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**1.8V 32M-BIT [x 1/x 2/x 4] CMOS MXSMIO® (SERIAL MULTI I/O)  
FLASH MEMORY****1. FEATURES****GENERAL**

- Supports Serial Peripheral Interface -- Mode 0 and Mode 3
- 33,554,432 x 1 bit structure  
or 16,777,216 x 2 bits (two I/O mode) structure  
or 8,388,608 x 4 bits (four I/O mode) structure
- Equal Sectors with 4K byte each,  
or Equal Blocks with 32K byte each  
or Equal Blocks with 64K byte each
  - Any Block can be erased individually
- Single Power Supply Operation
  - 1.65 to 2.0 volt for read, erase, and program operations
- Latch-up protected to 100mA from -1V to Vcc +1V
- Low Vcc write inhibit is from 1.0V to 1.4V

**PERFORMANCE**

- High Performance
  - Fast read for SPI mode
    - 1 I/O: 104MHz with 8 dummy cycles
    - 2 I/O: 84MHz with 4 dummy cycles, equivalent to 168MHz
    - 4 I/O: 104MHz with 2+4 dummy cycles, equivalent to 416MHz
  - Fast read for QPI mode
    - 4 I/O: 84MHz with 2+2 dummy cycles, equivalent to 336MHz
    - 4 I/O: 104MHz with 2+4 dummy cycles, equivalent to 416MHz
  - Fast program time:  
0.5ms(typ.) and 3ms(max.)/page (256-byte per page)
  - Byte program time: 12us (typical)
  - 8/16/32/64 byte Wrap-Around Burst Read Mode
  - Fast erase time:
    - 35ms (typ.)/sector (4K-byte per sector);
    - 200ms(typ.)/block (32K-byte per block),
    - 350ms(typ.)/block (64K-byte per block)
- Low Power Consumption
  - Low active read current:
    - 20mA(typ.) at 104MHz,
    - 15mA(typ.) at 84MHz
  - Low active erase current:
    - 18mA(typ.) at Sector Erase, Block Erase (32KB/64KB);
    - 20mA at Chip Erase
  - Low active programming current: 20mA (typ.)
  - Standby current: 10uA (typ.)
- Deep Power Down: 1.5uA(typ.)
- Typical 100,000 erase/program cycles
- 20 years data retention

**SOFTWARE FEATURES**

- Input Data Format
  - 1-byte Command code
- Advanced Security Features
  - Block lock protection  
The BP0-BP3 status bit defines the size of the area to be software protection against program and erase instructions
  - Additional 4k-bit secured OTP for unique identifier
- Auto Erase and Auto Program Algorithm
  - Automatically erases and verifies data at selected sector or block
  - Automatically programs and verifies data at selected page by an internal algorithm that automatically times the program pulse widths (Any page to be programmed should have page in the erased state first)
- Status Register Feature
- Command Reset
- Program/Erase Suspend
- Electronic Identification
  - JEDEC 1-byte manufacturer ID and 2-byte device ID
  - RES command for 1-byte Device ID
  - REMS command for 1-byte manufacturer ID and 1-byte device ID
- Support Serial Flash Discoverable Parameters (SFDP) mode

**HARDWARE FEATURES**

- SCLK Input
  - Serial clock input
- SI/SIO0
  - Serial Data Input or Serial Data Input/Output for 2 x I/O read mode and 4 x I/O read mode
- SO/SIO1
  - Serial Data Output or Serial Data Input/Output for 2 x I/O read mode and 4 x I/O read mode
- WP#/SIO2
  - Hardware write protection or Serial Data Input/Output for 4 x I/O read mode
- RESET#/SIO3
  - Hardware Reset pin or Serial input & Output for 4 x I/O read mode
- PACKAGE
  - 8-pin SOP (200mil)
  - 8-land WSON (6x5mm)
  - 8-land USON (4x3mm)
  - 8-land XSON(4x4mm)
  - 12-ball WLCSP
- **All devices are RoHS Compliant and Halogen-free**

## 2. GENERAL DESCRIPTION

MX25U3235F is 32Mb bits Serial NOR Flash memory, which is configured as 4,194,304 x 8 internally. When it is in two or four I/O mode, the structure becomes 16,777,216 bits x 2 or 8,388,608 bits x 4.

MX25U3235F features a serial peripheral interface and software protocol allowing operation on a simple 3-wire bus while it is in single I/O mode. The three bus signals are a clock input (SCLK), a serial data input (SI), and a serial data output (SO). Serial access to the device is enabled by CS# input.

When it is in two I/O read mode, the SI pin and SO pin become SIO0 pin and SIO1 pin for address/dummy bits input and data output. When it is in four I/O read mode, the SI pin, SO pin, WP# pin and RESET# pin become SIO0 pin, SIO1 pin, SIO2 pin and SIO3 pin for address/dummy bits input and data output.

The MX25U3235F MXSMIO® (Serial Multi I/O) provides sequential read operation on the whole chip.

After program/erase command is issued, auto program/erase algorithms which program/erase and verify the specified page or sector/block locations will be executed. Program command is executed on byte basis, or page (256 bytes) basis, or word basis. Erase command is executed on 4K-byte sector, 32K-byte block, or 64K-byte block, or whole chip basis.

To provide user with ease of interface, a status register is included to indicate the status of the chip. The status read command can be issued to detect completion status of a program or erase operation via WIP bit.

Advanced security features enhance the protection and security functions, please refer to the security features section for more details.

The MX25U3235F utilizes Macronix's proprietary memory cell, which reliably stores memory contents even after 100,000 program and erase cycles.

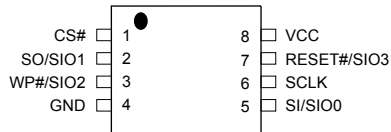
**Table 1. Additional Feature**

| Protection and Security             | MX25U3235F |
|-------------------------------------|------------|
| Flexible Block Protection (BP0-BP3) | V          |
| 4K-bit security OTP                 | V          |

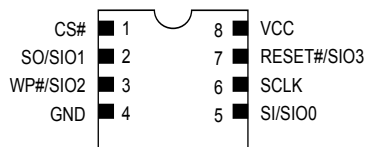
| Read Performance | MX25U3235F |        |        |        |        |        |        |        |
|------------------|------------|--------|--------|--------|--------|--------|--------|--------|
| I/O mode         | SPI        |        |        |        |        |        | QPI    |        |
| I/O              | 1 I/O      | 1I /2O | 2 I/O  | 1I/4O  | 4 I/O  | 4 I/O  | 4 I/O  | 4 I/O  |
| Dummy Cycle      | 8          | 8      | 4      | 8      | 4      | 6      | 4      | 6      |
| Frequency        | 104MHz     | 104MHz | 84 MHz | 104MHz | 84 MHz | 104MHz | 84 MHz | 104MHz |

### 3. PIN CONFIGURATIONS

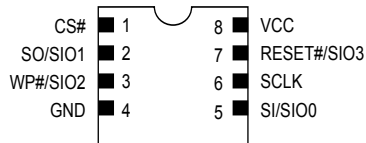
#### 8-PIN SOP (200mil)



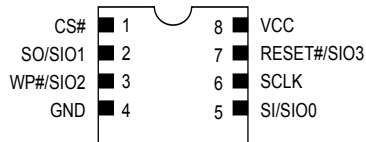
#### 8-LAND WSON (6x5mm)



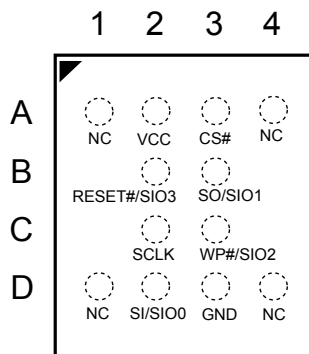
#### 8-LAND USON (4x3mm)



#### 8-LAND XSON(4x4mm)



#### 12-BALL BGA (WLCSP) TOP View

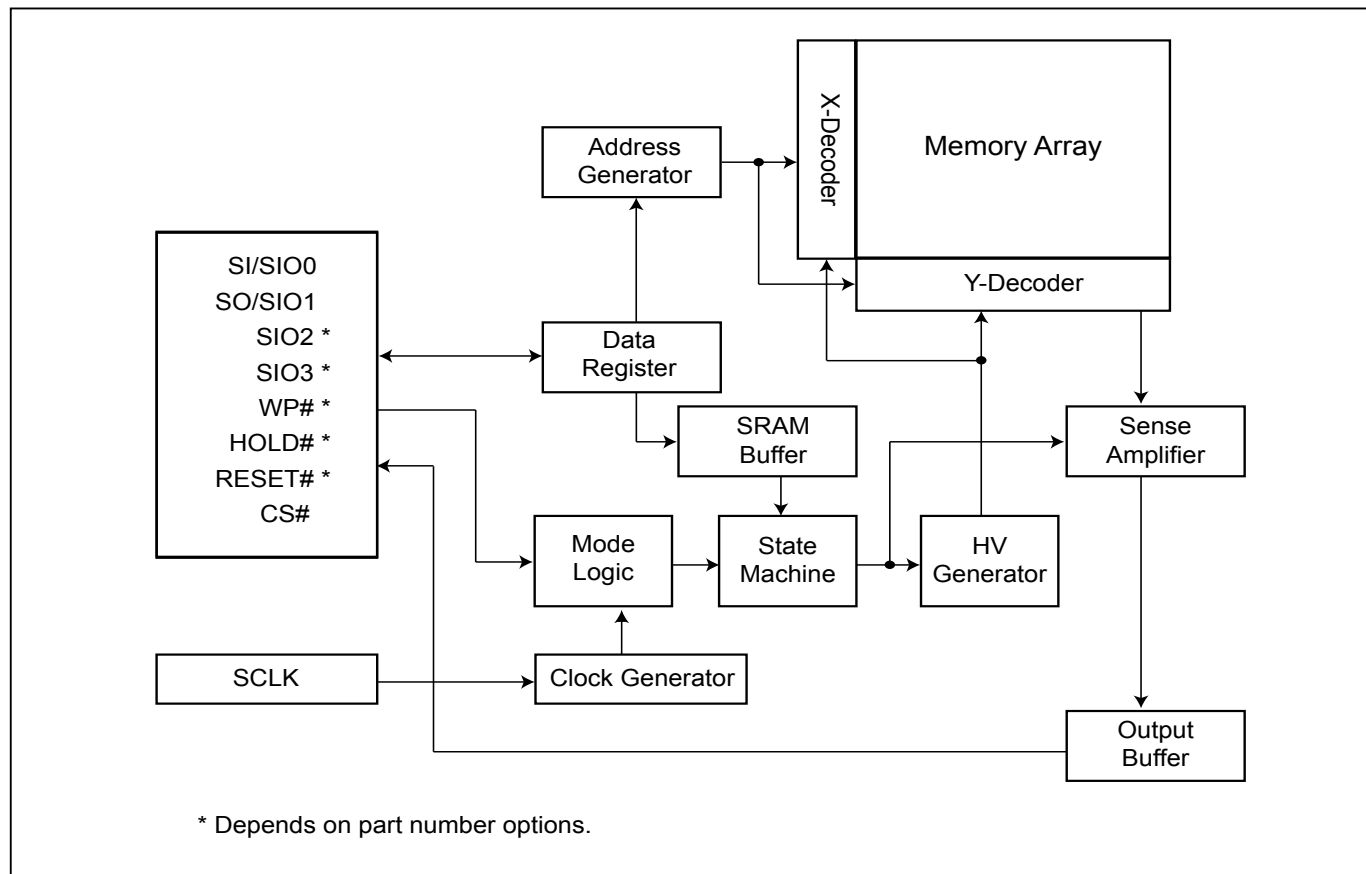


### 4. PIN DESCRIPTION

| SYMBOL      | DESCRIPTION                                                                                 |
|-------------|---------------------------------------------------------------------------------------------|
| CS#         | Chip Select                                                                                 |
| SI/SIO0     | Serial Data Input (for 1 x I/O)/ Serial Data Input & Output (for 2xI/O or 4xI/O read mode)  |
| SO/SIO1     | Serial Data Output (for 1 x I/O)/ Serial Data Input & Output (for 2xI/O or 4xI/O read mode) |
| SCLK        | Clock Input                                                                                 |
| WP#/SIO2    | Write Protection Active Low or Serial Data Input & Output (for 4xI/O read mode)             |
| RESET#/SIO3 | Hardware Reset Pin Active low or Serial Data Input & Output (for 4xI/O read mode)           |
| VCC         | + 1.8V Power Supply                                                                         |
| GND         | Ground                                                                                      |

**Note:** The pin of RESET#/SIO3 or WP#/SIO2 will remain internal pull up function while this pin is not physically connected in system configuration. However, the internal pull up function will be disabled if the system has physical connection to RESET#/SIO3 or WP#/SIO2 pin.

## 5. BLOCK DIAGRAM



## 6. DATA PROTECTION

During power transition, there may be some false system level signals which result in inadvertent erasure or programming. The device is designed to protect itself from these accidental write cycles.

The state machine will be reset as standby mode automatically during power up. In addition, the control register architecture of the device constrains that the memory contents can only be changed after specific command sequences have completed successfully.

In the following, there are several features to protect the system from the accidental write cycles during VCC power-up and power-down or from system noise.

- Power-on reset: to avoid sudden power switch by system power supply transition, the power-on reset (internal timer) may protect the Flash.
- Valid command length checking: The command length will be checked whether it is at byte base and completed on byte boundary.
- Write Enable (WREN) command: WREN command is required to set the Write Enable Latch bit (WEL) before issuing other commands to change data.
- Deep Power Down Mode: By entering deep power down mode, the flash device is under protected from writing all commands except the Release from deep power down mode command (RDP) and Read Electronic Signature command (RES) and softreset command.
- Advanced Security Features: there are some protection and security features which protect content from inadvertent write and hostile access.

### I. Block lock protection

- The Software Protected Mode (SPM) use (BP3, BP2, BP1, BP0) bits to allow part of memory to be protected as read only. The protected area definition is shown as "[Table 2. Protected Area Sizes](#)", the protected areas are more flexible which may protect various area by setting value of BP0-BP3 bits.
- The Hardware Protected Mode (HPM) use WP#/SIO2 to protect the (BP3, BP2, BP1, BP0) bits and Status Register Write Protect bit.
- In four I/O and QPI mode, the feature of HPM will be disabled.

**Table 2. Protected Area Sizes**

| Status bit |     |     |     | Protect Level                                                     |
|------------|-----|-----|-----|-------------------------------------------------------------------|
| BP3        | BP2 | BP1 | BP0 |                                                                   |
| 0          | 0   | 0   | 0   | 0 (none)                                                          |
| 0          | 0   | 0   | 1   | 1 (1block, protected block 63 <sup>rd</sup> )                     |
| 0          | 0   | 1   | 0   | 2 (2blocks, protected block 62 <sup>nd</sup> -63 <sup>rd</sup> )  |
| 0          | 0   | 1   | 1   | 3 (4blocks, protected block 60 <sup>th</sup> -63 <sup>rd</sup> )  |
| 0          | 1   | 0   | 0   | 4 (8blocks, protected block 56 <sup>th</sup> -63 <sup>rd</sup> )  |
| 0          | 1   | 0   | 1   | 5 (16blocks, protected block 48 <sup>th</sup> -63 <sup>rd</sup> ) |
| 0          | 1   | 1   | 0   | 6 (32blocks, protected block 32 <sup>nd</sup> -63 <sup>rd</sup> ) |
| 0          | 1   | 1   | 1   | 7 (64blocks, protected all)                                       |
| 1          | 0   | 0   | 0   | 8 (64blocks, protected all)                                       |
| 1          | 0   | 0   | 1   | 9 (32blocks, protected block 0 <sup>th</sup> -31 <sup>st</sup> )  |
| 1          | 0   | 1   | 0   | 10 (48blocks, protected block 0 <sup>th</sup> -47 <sup>th</sup> ) |
| 1          | 0   | 1   | 1   | 11 (56blocks, protected block 0 <sup>th</sup> -55 <sup>th</sup> ) |
| 1          | 1   | 0   | 0   | 12 (60blocks, protected block 0 <sup>th</sup> -59 <sup>th</sup> ) |
| 1          | 1   | 0   | 1   | 13 (62blocks, protected block 0 <sup>th</sup> -61 <sup>st</sup> ) |
| 1          | 1   | 1   | 0   | 14 (63blocks, protected block 0 <sup>th</sup> -62 <sup>nd</sup> ) |
| 1          | 1   | 1   | 1   | 15 (64blocks, protected all)                                      |

**II. Additional 4K-bit secured OTP** for unique identifier: to provide 4K-bit one-time program area for setting device unique serial number - Which may be set by factory or system customer.

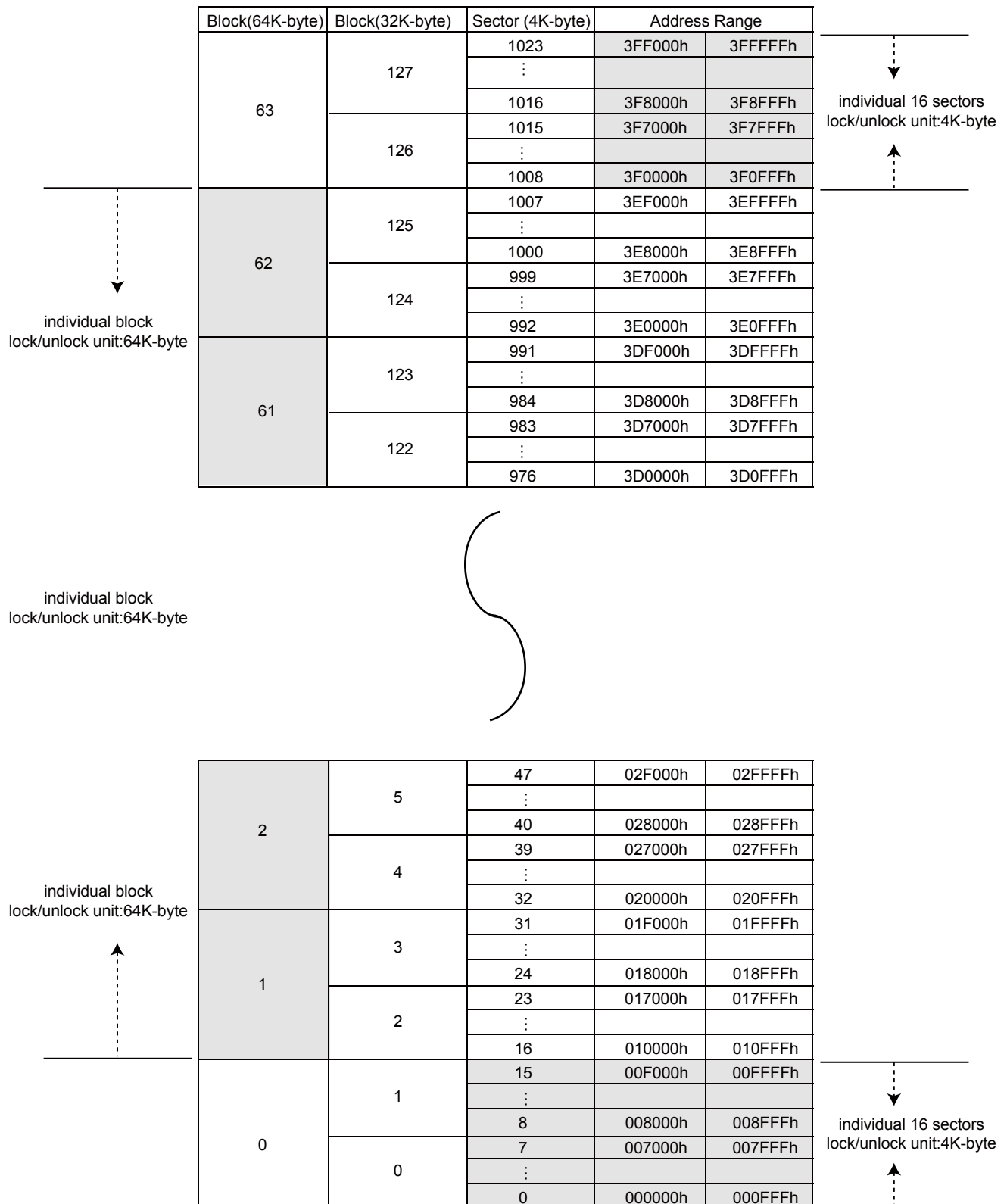
- Security register bit 0 indicates whether the secured OTP area is locked by factory or not.
- To program the 4K-bit secured OTP by entering 4K-bit secured OTP mode (with Enter Security OTP command), and going through normal program procedure, and then exiting 4K-bit secured OTP mode by writing Exit Security OTP command.
- Customer may lock-down the customer lockable secured OTP by writing WRSCUR(write security register) command to set customer lock-down bit1 as "1". Please refer to ["Table 9. Security Register Definition"](#) for security register bit definition and ["Table 3. 4K-bit Secured OTP Definition"](#) for address range definition.
- **Note:** Once lock-down whatever by factory or customer, it cannot be changed any more. While in 4K-bit secured OTP mode, array access is not allowed.

**Table 3. 4K-bit Secured OTP Definition**

| Address range | Size     | Standard Factory Lock          | Customer Lock          |
|---------------|----------|--------------------------------|------------------------|
| xxx000-xxx00F | 128-bit  | ESN (electrical serial number) | Determined by customer |
| xxx010-xxx1FF | 3968-bit | N/A                            |                        |

## 7. MEMORY ORGANIZATION

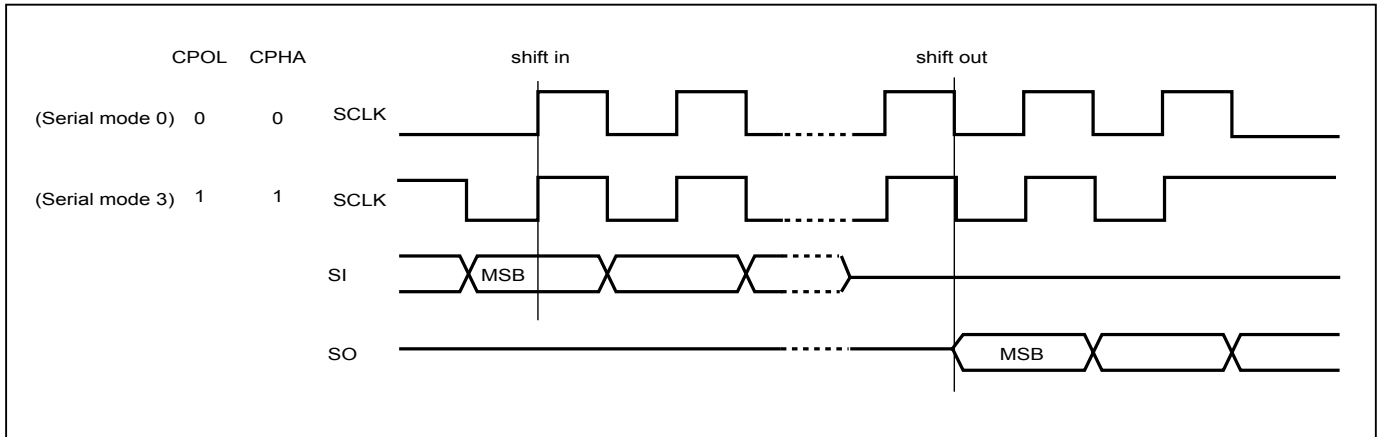
**Table 4. Memory Organization**



## 8. DEVICE OPERATION

1. Before a command is issued, status register should be checked to ensure device is ready for the intended operation.
2. When incorrect command is inputted to this device, it enters standby mode and remains in standby mode until next CS# falling edge. In standby mode, SO pin of the device is High-Z.
3. When correct command is inputted to this device, it enters active mode and remains in active mode until next CS# rising edge.
4. Input data is latched on the rising edge of Serial Clock (SCLK) and data shifts out on the falling edge of SCLK. The difference of Serial mode 0 and mode 3 is shown as *"Figure 1. Serial Modes Supported"*.
5. For the following instructions: RDID, RDSR, RDSCUR, READ, FAST\_READ, DREAD, 2READ, QREAD, 4READ, W4READ, RDSFDP, RES, REMS, QPIID, RDBLOCK, the shifted-in instruction sequence is followed by a data-out sequence. After any bit of data being shifted out, the CS# can be high. For the following instructions: WREN, WRDI, WRSR, SE, BE32K, BE, CE, PP, 4PP, DP, ENSO, EXSO, WRSCUR, WPSEL, SBLK, SBULK, GBULK, SUSPEND, RESUME, NOP, RSTEN, RST, EQIO, RSTQIO the CS# must go high exactly at the byte boundary; otherwise, the instruction will be rejected and not executed.
6. While a Write Status Register, Program or Erase operation is in progress, access to the memory array is neglected and will not affect the current operation of Write Status Register, Program, Erase.

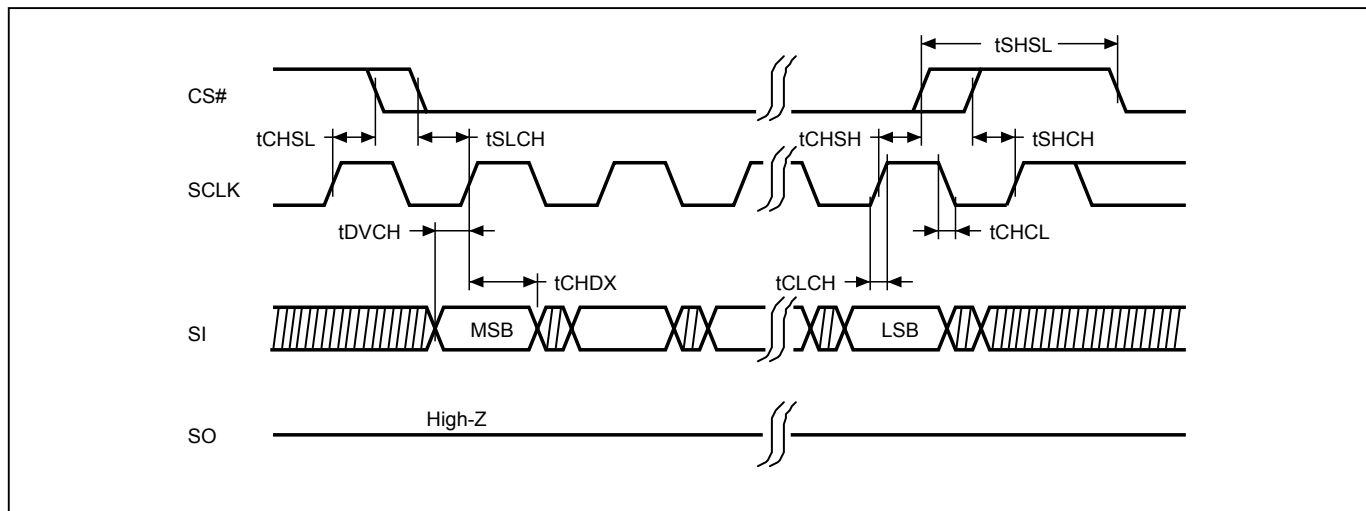
**Figure 1. Serial Modes Supported**



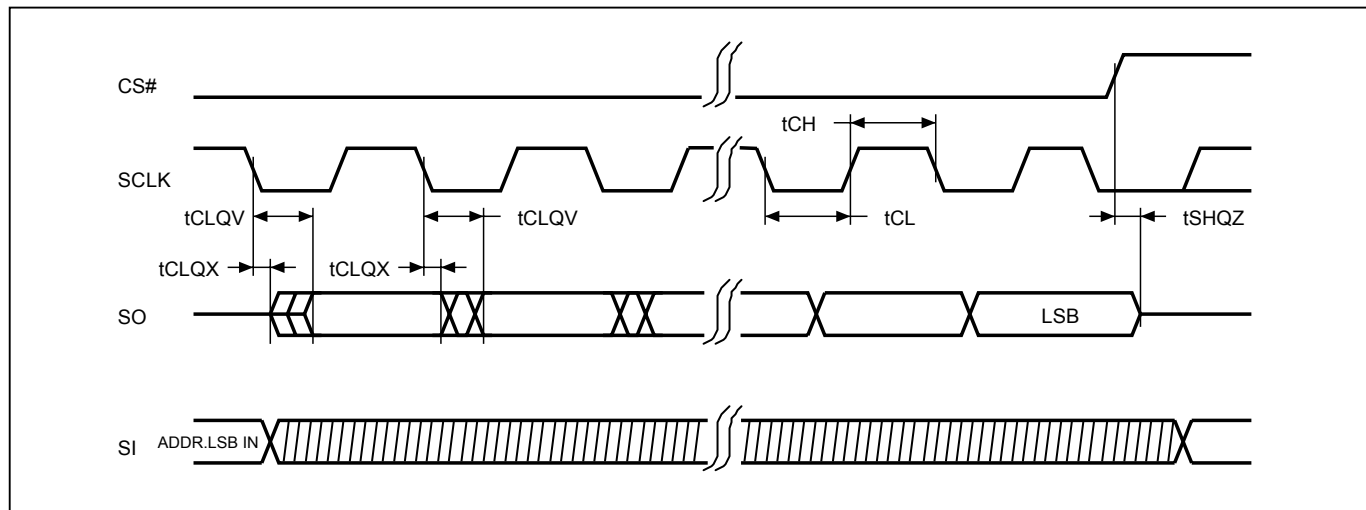
**Note:**

CPOL indicates clock polarity of Serial master, CPOL=1 for SCLK high while idle, CPOL=0 for SCLK low while not transmitting. CPHA indicates clock phase. The combination of CPOL bit and CPHA bit decides which Serial mode is supported.

**Figure 2. Serial Input Timing**



**Figure 3. Output Timing**



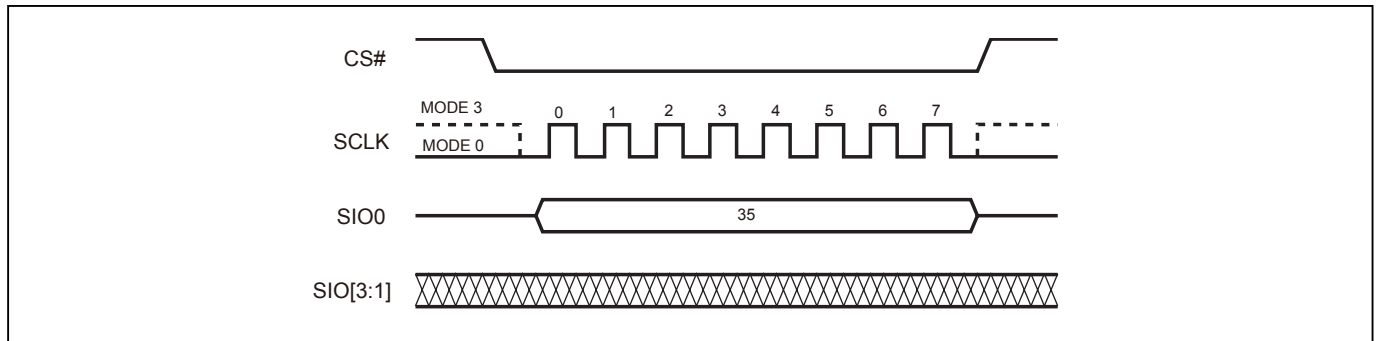
## 8-1. Quad Peripheral Interface (QPI) Read Mode

QPI protocol enables user to take full advantage of Quad I/O Serial Flash by providing the Quad I/O interface in command cycles, address cycles and as well as data output cycles.

### Enable QPI mode

By issuing EQIO command (35h), the QPI mode is enabled.

**Figure 4. Enable QPI Sequence (Command 35h)**

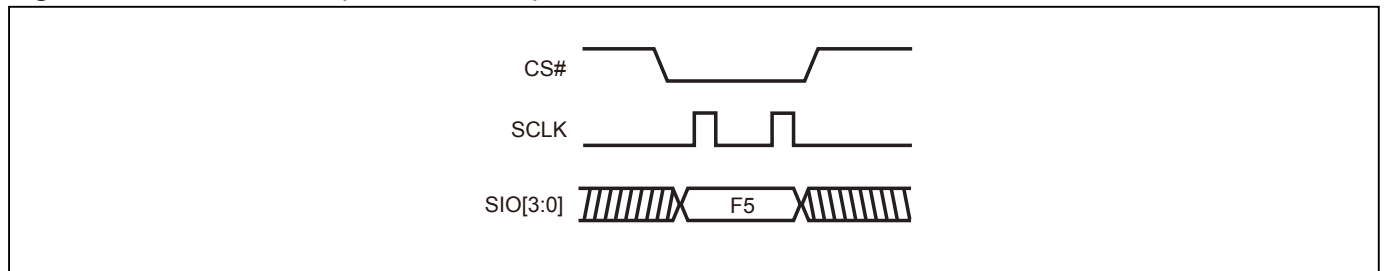


### Reset QPI (RSTQIO)

To reset the QPI mode, the RSTQIO (F5h) command is required. After the RSTQIO command is issued, the device returns from QPI mode (4 I/O interface in command cycles) to SPI mode (1 I/O interface in command cycles).

**Note:** For EQIO and RSTQIO commands, CS# high width has to follow "From Write/Erase/Program to Read Status Register" specification of tSHSL (as defined in ["Table 20. AC Characteristics"](#)) for next instruction.

**Figure 5. Reset QPI Mode (Command F5h)**



## 9. COMMAND DESCRIPTION

**Table 5. Command Set**

### Read/Write Array Commands

| Mode           | SPI                                  | SPI/QPI                              | SPI                                                 | SPI                                             | SPI/QPI                           | SPI                                   |
|----------------|--------------------------------------|--------------------------------------|-----------------------------------------------------|-------------------------------------------------|-----------------------------------|---------------------------------------|
| Command (byte) | READ (normal read)                   | FAST READ (fast read data)           | DREAD (1I / 2O read command)                        | 2READ (2 x I/O read command) <sup>Note 1</sup>  | 4READ (4 x I/O read)              | W4READ                                |
| 1st byte       | 03 (hex)                             | 0B (hex)                             | 3B (hex)                                            | BB (hex)                                        | EB (hex)                          | E7 (hex)                              |
| 2nd byte       | ADD1(8)                              | ADD1(8)                              | ADD1(8)                                             | ADD1(4)                                         | ADD1(2)                           | ADD1(2)                               |
| 3rd byte       | ADD2(8)                              | ADD2(8)                              | ADD2(8)                                             | ADD2(4)                                         | ADD2(2)                           | ADD2(2)                               |
| 4th byte       | ADD3(8)                              | ADD3(8)                              | ADD3(8)                                             | ADD3(4)                                         | ADD3(2)                           | ADD3(2)                               |
| 5th byte       |                                      | Dummy(8)/(4)*                        | Dummy(8)                                            | Dummy(4)                                        | Dummy(6)                          | Dummy(4)                              |
| Action         | n bytes read out until CS# goes high | n bytes read out until CS# goes high | n bytes read out by Dual Output until CS# goes high | n bytes read out by 2 x I/O until CS# goes high | Quad I/O read with 6 dummy cycles | Quad I/O read for with 4 dummy cycles |

| Mode           | SPI                                                 | SPI/QPI                      | SPI                                     | SPI/QPI                      | SPI/QPI                         | SPI/QPI                     |
|----------------|-----------------------------------------------------|------------------------------|-----------------------------------------|------------------------------|---------------------------------|-----------------------------|
| Command (byte) | QREAD (1I/4O read)                                  | PP (page program)            | 4PP (quad page program)                 | SE (sector erase)            | BE 32K (block erase 32KB)       | BE (block erase 64KB)       |
| 1st byte       | 6B (hex)                                            | 02 (hex)                     | 38 (hex)                                | 20 (hex)                     | 52 (hex)                        | D8 (hex)                    |
| 2nd byte       | ADD1(8)                                             | ADD1                         | ADD1                                    | ADD1                         | ADD1                            | ADD1                        |
| 3rd byte       | ADD2(8)                                             | ADD2                         | ADD2                                    | ADD2                         | ADD2                            | ADD2                        |
| 4th byte       | ADD3(8)                                             | ADD3                         | ADD3                                    | ADD3                         | ADD3                            | ADD3                        |
| 5th byte       | Dummy(8)                                            |                              |                                         |                              |                                 |                             |
| Action         | n bytes read out by Quad output until CS# goes high | to program the selected page | quad input to program the selected page | to erase the selected sector | to erase the selected 32K block | to erase the selected block |

| Mode           | SPI/QPI             |
|----------------|---------------------|
| Command (byte) | CE (chip erase)     |
| 1st byte       | 60 or C7 (hex)      |
| 2nd byte       |                     |
| 3rd byte       |                     |
| 4th byte       |                     |
| 5th byte       |                     |
| Action         | to erase whole chip |

Note: The number in parentheses after "ADD" or "Data" stands for how many clock cycles it has. For example, "Data(8)" represents there are 8 clock cycles for the data in.

\* The fast read command (0Bh) when under QPI mode, the dummy cycle is 4 clocks.

### Register/Setting Commands

| Command (byte) | WREN (write enable)                   | WRDI (write disable)                    | RDSR (read status register)                   | WRSR (write status register)               | WPSEL (Write Protect Selection)                   | EQIO (Enable QPI)     |
|----------------|---------------------------------------|-----------------------------------------|-----------------------------------------------|--------------------------------------------|---------------------------------------------------|-----------------------|
| Mode           | SPI/QPI                               | SPI/QPI                                 | SPI/QPI                                       | SPI/QPI                                    | SPI/QPI                                           | SPI                   |
| 1st byte       | 06 (hex)                              | 04 (hex)                                | 05 (hex)                                      | 01 (hex)                                   | 68 (hex)                                          | 35 (hex)              |
| 2nd byte       |                                       |                                         |                                               | Values                                     |                                                   |                       |
| 3rd byte       |                                       |                                         |                                               |                                            |                                                   |                       |
| 4th byte       |                                       |                                         |                                               |                                            |                                                   |                       |
| 5th byte       |                                       |                                         |                                               |                                            |                                                   |                       |
| Action         | sets the (WEL) write enable latch bit | resets the (WEL) write enable latch bit | to read out the values of the status register | to write new values of the status register | to enter and enable individual block protect mode | Entering the QPI mode |

| Command (byte) | RSTQIO (Reset QPI)   | PGM/ERS Suspend (Suspends Program/Erase) | PGM/ERS Resume (Resumes Program/Erase) | DP (Deep power down)        | RDP (Release from deep power down) | SBL (Set Burst Length) |
|----------------|----------------------|------------------------------------------|----------------------------------------|-----------------------------|------------------------------------|------------------------|
| Mode           | QPI                  | SPI/QPI                                  | SPI/QPI                                | SPI/QPI                     | SPI/QPI                            | SPI/QPI                |
| 1st byte       | F5 (hex)             | B0 (hex)                                 | 30 (hex)                               | B9 (hex)                    | AB (hex)                           | C0 (hex)               |
| 2nd byte       |                      |                                          |                                        |                             |                                    | Value                  |
| 3rd byte       |                      |                                          |                                        |                             |                                    |                        |
| 4th byte       |                      |                                          |                                        |                             |                                    |                        |
| 5th byte       |                      |                                          |                                        |                             |                                    |                        |
| Action         | Exiting the QPI mode |                                          |                                        | enters deep power down mode | release from deep power down mode  | to set Burst length    |

### ID/Security Commands

| Command (byte) | RDID (read identification)                                  | RES (read electronic ID)     | REMS (read electronic manufacturer & device ID) | QPIID (QPI ID Read) | RDSFDP         | ENSO (enter secured OTP)             | EXSO (exit secured OTP)             |
|----------------|-------------------------------------------------------------|------------------------------|-------------------------------------------------|---------------------|----------------|--------------------------------------|-------------------------------------|
| Mode           | SPI                                                         | SPI/QPI                      | SPI                                             | QPI                 | SPI/QPI        | SPI/QPI                              | SPI/QPI                             |
| 1st byte       | 9F (hex)                                                    | AB (hex)                     | 90 (hex)                                        | AF (hex)            | 5A (hex)       | B1 (hex)                             | C1 (hex)                            |
| 2nd byte       |                                                             | x                            | x                                               |                     | ADD1(8)        |                                      |                                     |
| 3rd byte       |                                                             | x                            | x                                               |                     | ADD2(8)        |                                      |                                     |
| 4th byte       |                                                             | x                            | ADD (Note 2)                                    |                     | ADD3(8)        |                                      |                                     |
| 5th byte       |                                                             |                              |                                                 |                     | Dummy(8)       |                                      |                                     |
| Action         | outputs JEDEC ID: 1-byte Manufacturer ID & 2-byte Device ID | to read out 1-byte Device ID | output the Manufacturer ID & Device ID          | ID in QPI interface | Read SFDP mode | to enter the 4K-bit secured OTP mode | to exit the 4K-bit secured OTP mode |

| COMMAND (byte) | RDSCUR (read security register)    | WRSCUR (write security register)                                   | SBLK (single block lock)                                      | SBULK (single block unlock)                               | RDBLOCK (block protect read)                         | GBLK (gang block lock)   | GBULK (gang block unlock) |
|----------------|------------------------------------|--------------------------------------------------------------------|---------------------------------------------------------------|-----------------------------------------------------------|------------------------------------------------------|--------------------------|---------------------------|
| Mode           | SPI/QPI                            | SPI/QPI                                                            | SPI/QPI                                                       | SPI/QPI                                                   | SPI/QPI                                              | SPI/QPI                  | SPI/QPI                   |
| 1st byte       | 2B (hex)                           | 2F (hex)                                                           | 36 (hex)                                                      | 39 (hex)                                                  | 3C (hex)                                             | 7E (hex)                 | 98 (hex)                  |
| 2nd byte       |                                    |                                                                    | ADD1                                                          | ADD1                                                      | ADD1                                                 |                          |                           |
| 3rd byte       |                                    |                                                                    | ADD2                                                          | ADD2                                                      | ADD2                                                 |                          |                           |
| 4th byte       |                                    |                                                                    | ADD3                                                          | ADD3                                                      | ADD3                                                 |                          |                           |
| 5th byte       |                                    |                                                                    |                                                               |                                                           |                                                      |                          |                           |
| Action         | to read value of security register | to set the lock-down bit as "1" (once lock-down, cannot be update) | individual block (64K-byte) or sector (4K-byte) write protect | individual block (64K-byte) or sector (4K-byte) unprotect | read individual block or sector write protect status | whole chip write protect | whole chip unprotect      |

**Reset Commands**

| COMMAND<br>(byte) | NOP<br>(No Operation) | RSTEN<br>(Reset Enable) | RST<br>(Reset<br>Memory) |
|-------------------|-----------------------|-------------------------|--------------------------|
| Mode              | SPI/QPI               | SPI/QPI                 | SPI/QPI                  |
| 1st byte          | 00 (hex)              | 66 (hex)                | 99 (hex)                 |
| 2nd byte          |                       |                         |                          |
| 3rd byte          |                       |                         |                          |
| 4th byte          |                       |                         |                          |
| 5th byte          |                       |                         |                          |
| Action            |                       |                         | (Note 4)                 |

Note 1: The count base is 4-bit for ADD(2) and Dummy(2) because of 2 x I/O. And the MSB is on SO/SIO1 which is different from 1 x I/O condition.

Note 2: ADD=00H will output the manufacturer ID first and ADD=01H will output device ID first.

Note 3: It is not recommended to adopt any other code not in the command definition table, which will potentially enter the hidden mode.

Note 4: The RSTEN command must be executed before executing the RST command. If any other command is issued in-between RSTEN and RST, the RST command will be ignored.

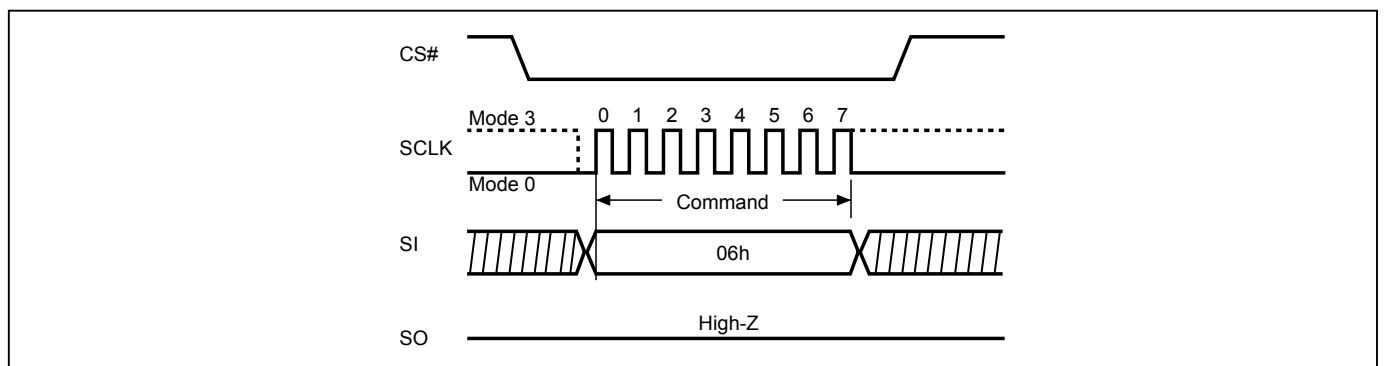
### 9-1. Write Enable (WREN)

The Write Enable (WREN) instruction is for setting Write Enable Latch (WEL) bit. For those instructions like PP, 4PP, SE, BE32K, BE, CE, and WRSR, which are intended to change the device content WEL bit should be set every time after the WREN instruction setting the WEL bit.

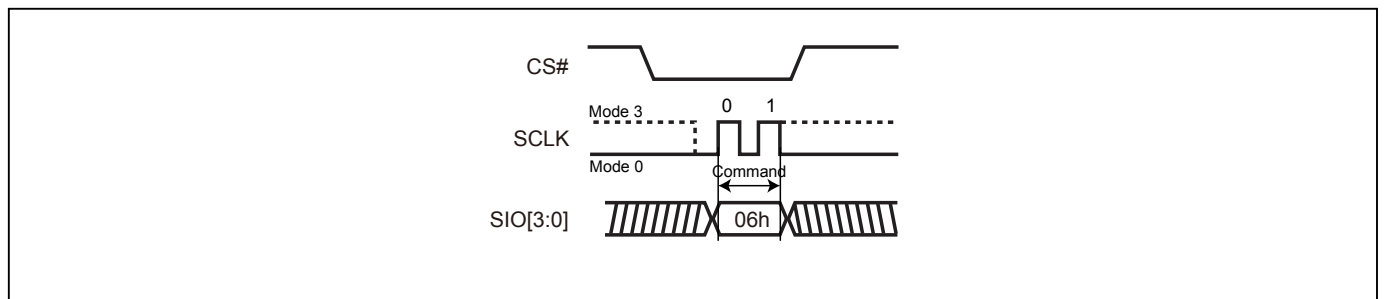
The sequence of issuing WREN instruction is: CS# goes low→sending WREN instruction code→ CS# goes high.

Both SPI (8 clocks) and QPI (2 clocks) command cycle can accept by this instruction. The SIO[3:1] are "don't care" in SPI mode.

**Figure 6. Write Enable (WREN) Sequence (SPI Mode)**



**Figure 7. Write Enable (WREN) Sequence (QPI Mode)**



## 9-2. Write Disable (WRDI)

The Write Disable (WRDI) instruction is to reset Write Enable Latch (WEL) bit.

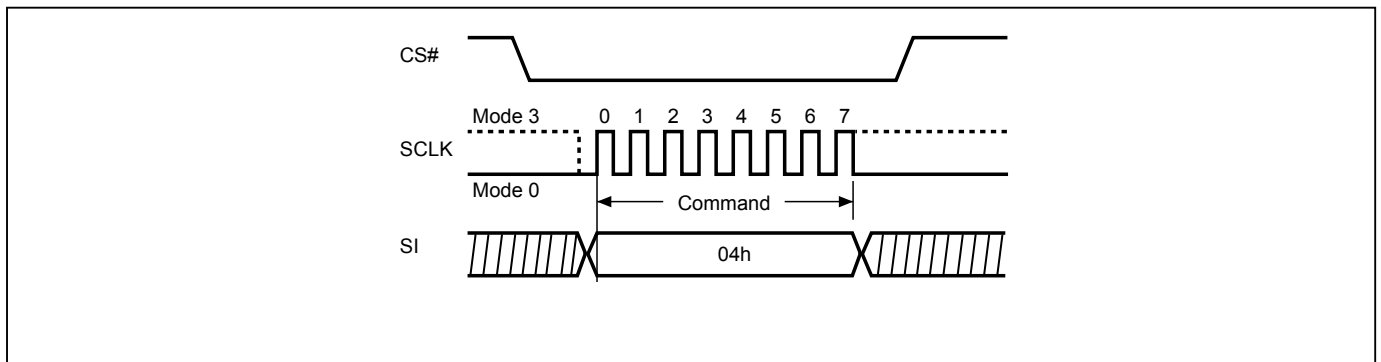
The sequence of issuing WRDI instruction is: CS# goes low→sending WRDI instruction code→CS# goes high.

Both SPI (8 clocks) and QPI (2 clocks) command cycle can accept by this instruction. The SIO[3:1] are "don't care" in SPI mode.

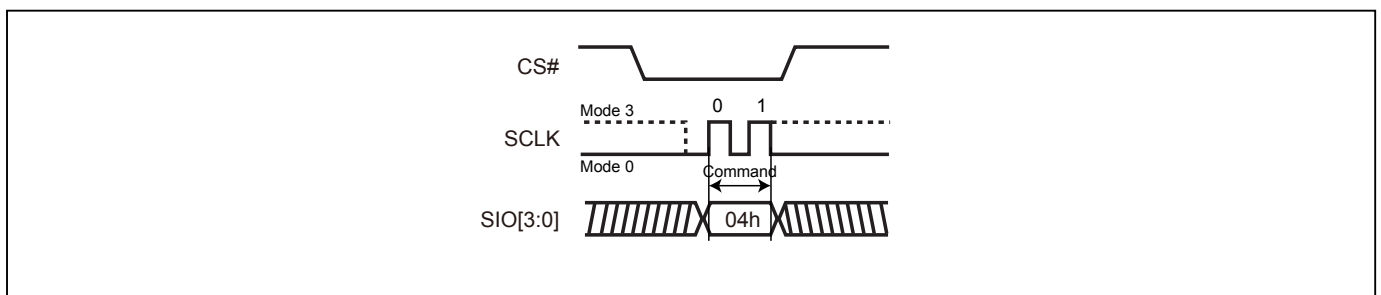
The WEL bit is reset by following situations:

- Power-up
- Reset# pin driven low
- Completion of Write Disable (WRDI) instruction
- Completion of Write Status Register (WRSR) instruction
- Completion of Page Program (PP) instruction
- Completion of Quad Page Program (4PP) instruction
- Completion of Sector Erase (SE) instruction
- Completion of Block Erase 32KB (BE32K) instruction
- Completion of Block Erase (BE) instruction
- Completion of Chip Erase (CE) instruction
- Program/Erase Suspend
- Completion of Softreset command
- Completion of Write Security Register (WRSCUR) command
- Completion of Write Protection Selection (WPSEL) command

**Figure 8. Write Disable (WRDI) Sequence (SPI Mode)**



**Figure 9. Write Disable (WRDI) Sequence (QPI Mode)**



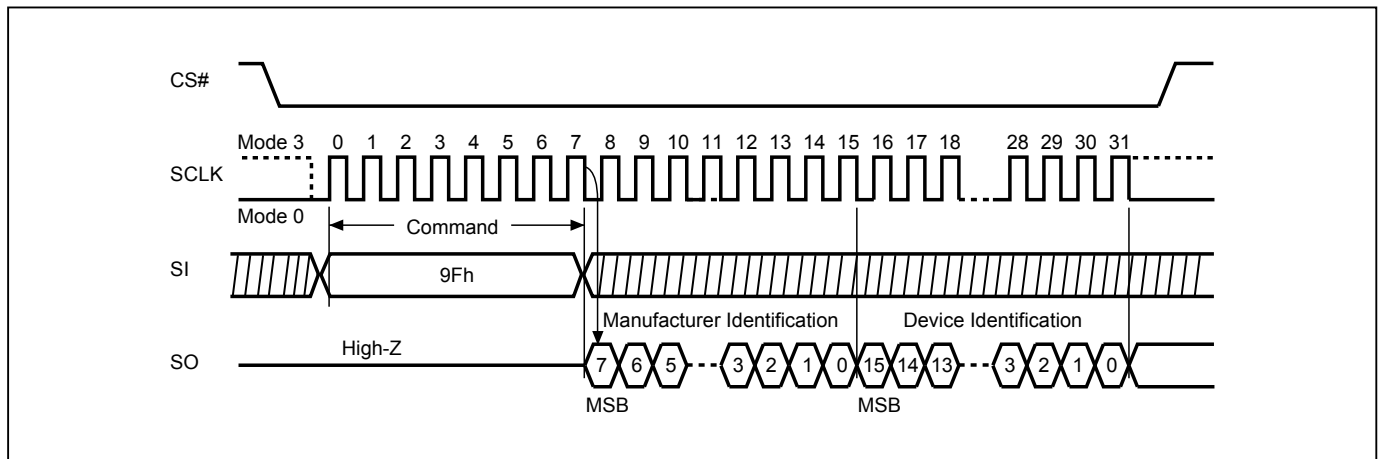
### 9-3. Read Identification (RDID)

The RDID instruction is for reading the manufacturer ID of 1-byte and followed by Device ID of 2-byte. The Macronix Manufacturer ID and Device ID are listed as "[Table 6. ID Definitions](#)".

The sequence of issuing RDID instruction is: CS# goes low→ sending RDID instruction code→24-bits ID data out on SO→ to end RDID operation can drive CS# to high at any time during data out.

While Program/Erase operation is in progress, it will not decode the RDID instruction, therefore there's no effect on the cycle of program/erase operation which is currently in progress. When CS# goes high, the device is at standby stage.

**Figure 10. Read Identification (RDID) Sequence (SPI mode only)**



#### 9-4. Release from Deep Power-down (RDP), Read Electronic Signature (RES)

The Release from Deep Power-down (RDP) instruction is terminated by driving Chip Select (CS#) High. When Chip Select (CS#) is driven High, the device is put in the Stand-by Power mode. If the device was not previously in the Deep Power-down mode, the transition to the Stand-by Power mode is immediate. If the device was previously in the Deep Power-down mode, the transition to the Stand-by Power mode is delayed by  $t_{RES1}$ , and Chip Select (CS#) must remain High for at least  $t_{RES1(max)}$ , as specified in "Table 20. AC Characteristics". Once in the Stand-by Power mode, the device waits to be selected, so that it can receive, decode and execute instructions. The RDP instruction is only for releasing from Deep Power Down Mode. RESET# pin goes low will release the Flash from deep power down mode.

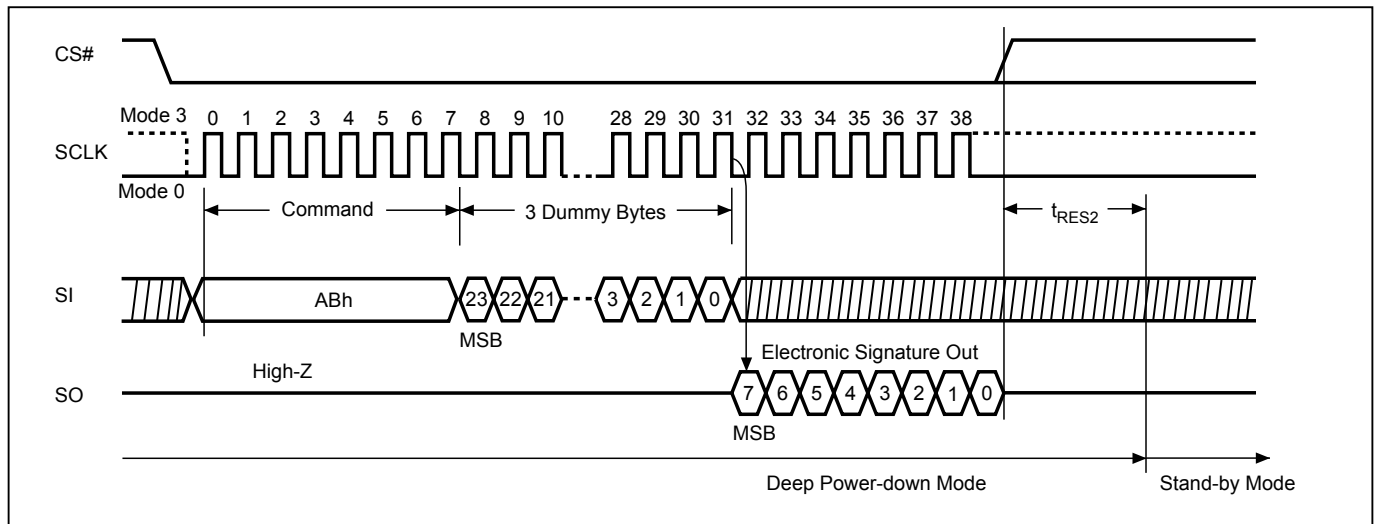
RES instruction is for reading out the old style of 8-bit Electronic Signature, whose values are shown as "Table 6. ID Definitions". This is not the same as RDID instruction. It is not recommended to use for new design. For new design, please use RDID instruction.

Even in Deep power-down mode, the RDP and RES are also allowed to be executed, only except the device is in progress of program/erase/write cycle; there's no effect on the current program/erase/write cycle in progress.

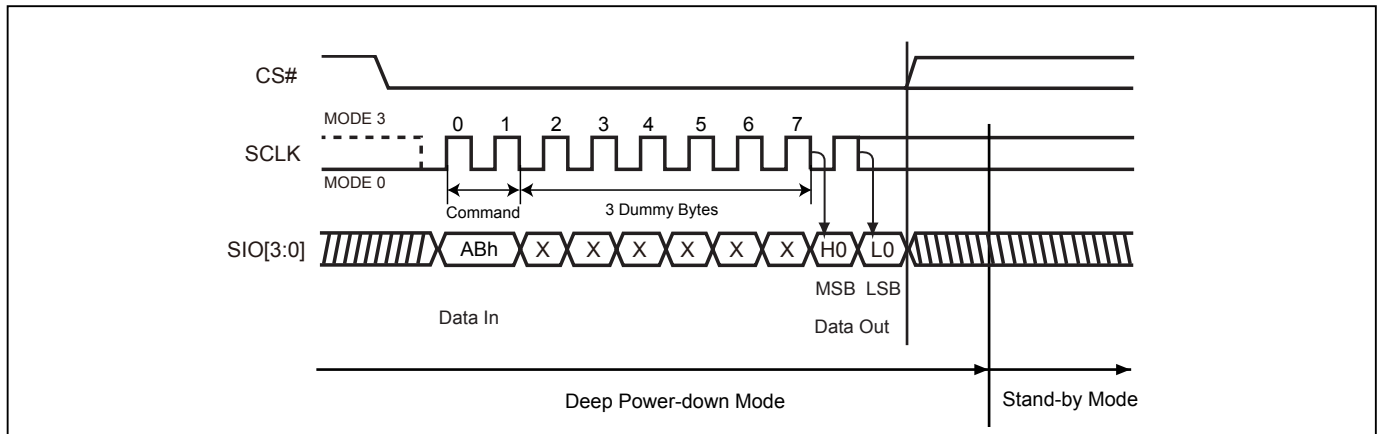
Both SPI (8 clocks) and QPI (2 clocks) command cycle can accept by this instruction. The SIO[3:1] are "don't care" in SPI mode.

The RES instruction is ended by CS# goes high after the ID been read out at least once. The ID outputs repeatedly if continuously send the additional clock cycles on SCLK while CS# is at low. If the device was not previously in Deep Power-down mode, the device transition to standby mode is immediate. If the device was previously in Deep Power-down mode, there's a delay of  $t_{RES2}$  to transit to standby mode, and CS# must remain to high at least  $t_{RES2(max)}$ . Once in the standby mode, the device waits to be selected, so it can be receive, decode, and execute instruction.

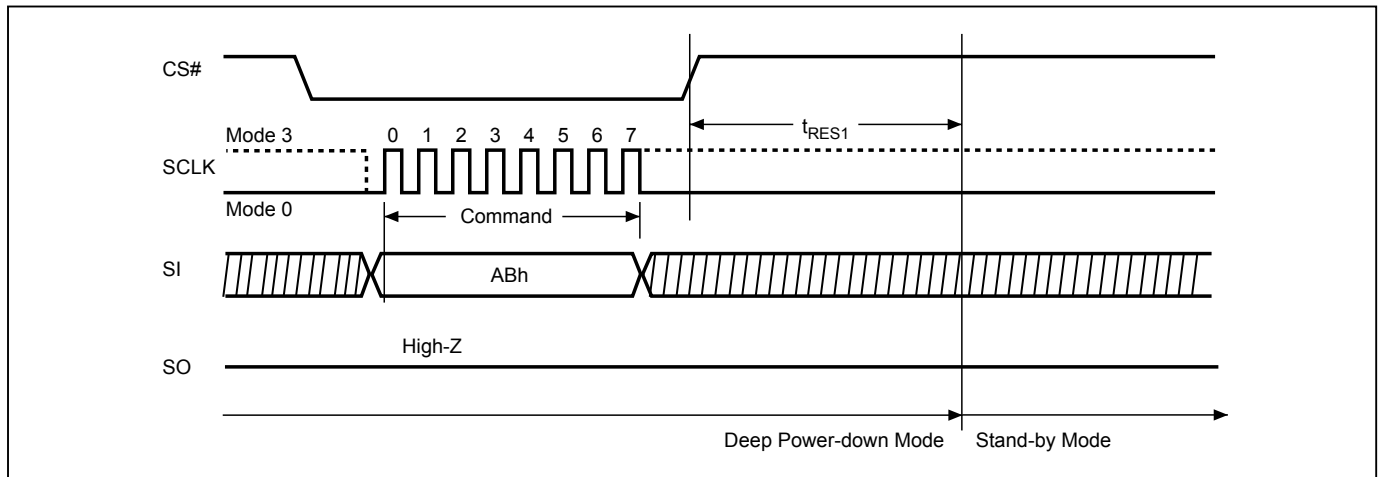
Figure 11. Read Electronic Signature (RES) Sequence (SPI Mode)



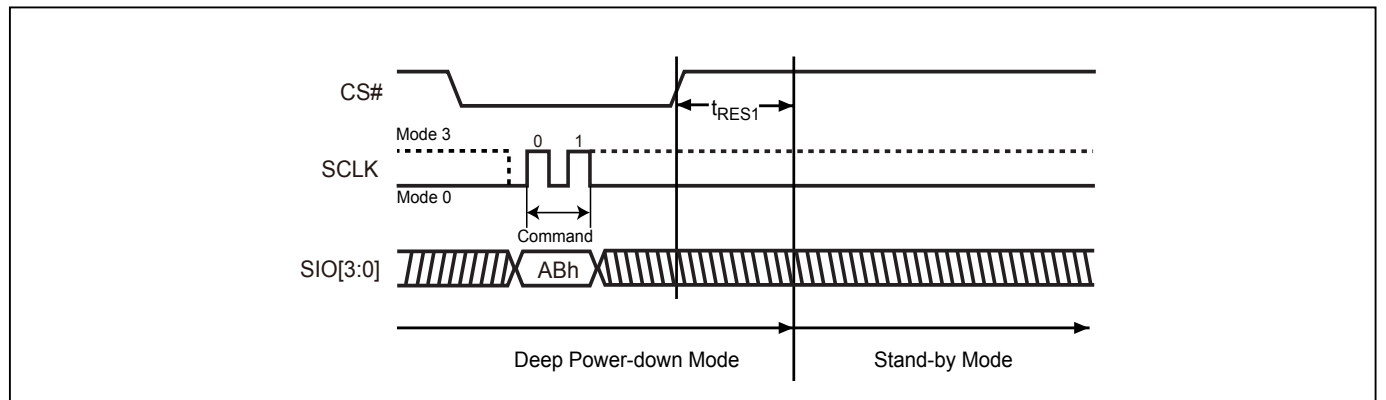
**Figure 12. Read Electronic Signature (RES) Sequence (QPI Mode)**



**Figure 13. Release from Deep Power-down (RDP) Sequence (SPI Mode)**



**Figure 14. Release from Deep Power-down (RDP) Sequence (QPI Mode)**

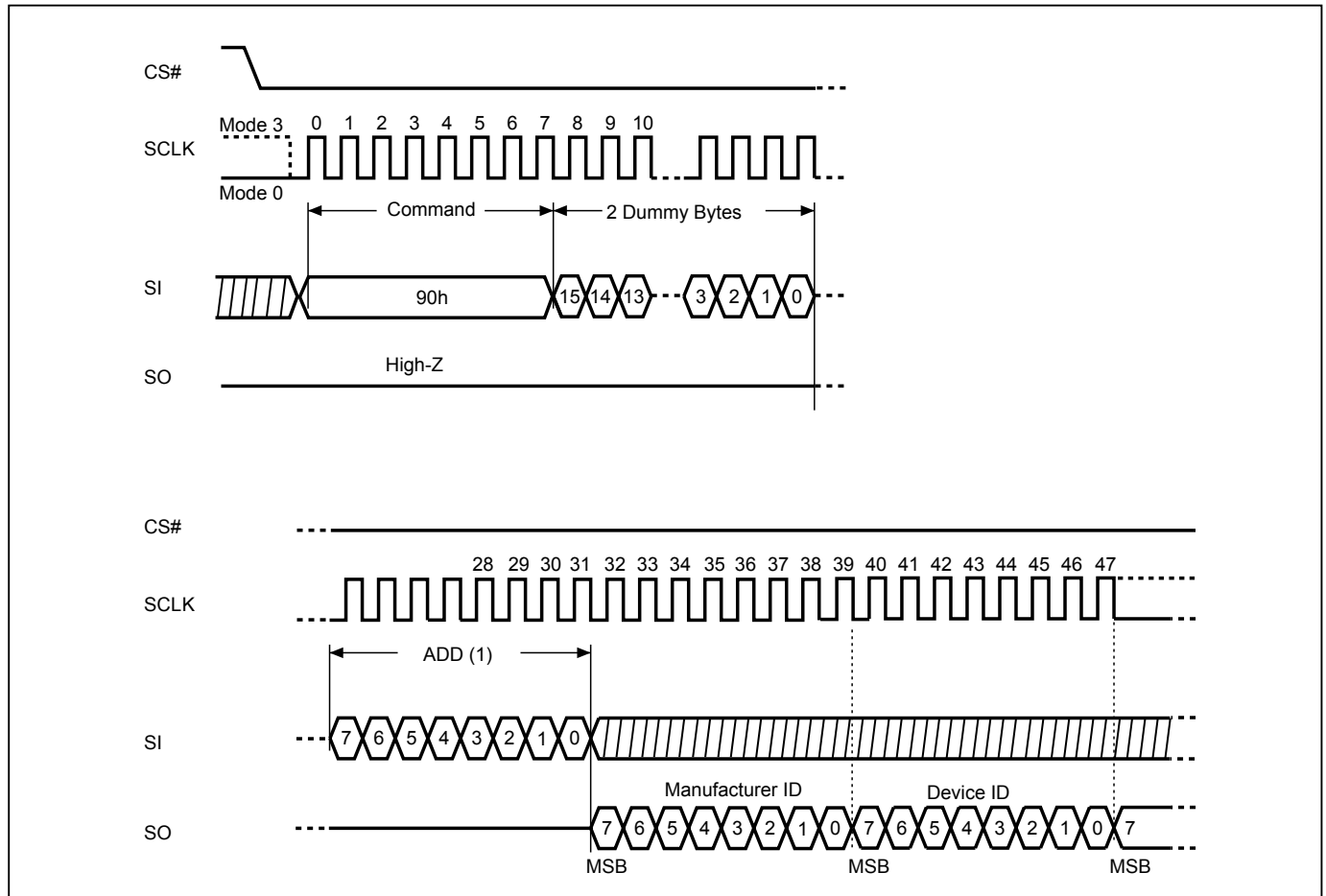


## 9-5. Read Electronic Manufacturer ID & Device ID (REMS)

The REMS instruction returns both the JEDEC assigned manufacturer ID and the device ID. The Device ID values are listed in "Table 6. ID Definitions".

The REMS instruction is initiated by driving the CS# pin low and sending the instruction code "90h" followed by two dummy bytes and one address byte (A7~A0). After which the manufacturer ID for Macronix (C2h) and the device ID are shifted out on the falling edge of SCLK with the most significant bit (MSB) first. If the address byte is 00h, the manufacturer ID will be output first, followed by the device ID. If the address byte is 01h, then the device ID will be output first, followed by the manufacturer ID. While CS# is low, the manufacturer and device IDs can be read continuously, alternating from one to the other. The instruction is completed by driving CS# high.

**Figure 15. Read Electronic Manufacturer & Device ID (REMS) Sequence (SPI Mode only)**



### Notes:

- (1) ADD=00H will output the manufacturer's ID first and ADD=01H will output device ID first.
- (2) Instruction is 90(hex).

**9-6. QPI ID Read (QPIID)**

User can execute this ID Read instruction to identify the Device ID and Manufacturer ID. The sequence of issue QPIID instruction is CS# goes low→sending QPI ID instruction→Data out on SO→CS# goes high. Most significant bit (MSB) first.

After the command cycle, the device will immediately output data on the falling edge of SCLK. The manufacturer ID, memory type, and device ID data byte will be output continuously, until the CS# goes high.

**Table 6. ID Definitions**

| Command Type | Command   | MX25U3235F      |             |                |
|--------------|-----------|-----------------|-------------|----------------|
|              |           | Manufacturer ID | Memory Type | Memory Density |
| RDID / QPIID | 9Fh / AFh | C2              | 25          | 36             |
| RES          | ABh       | Electronic ID   |             |                |
|              |           | 36              |             |                |
| REMS         | 90h       | Manufacturer ID | Device ID   |                |
|              |           | C2              | 36          |                |

## 9-7. Read Status Register (RDSR)

The RDSR instruction is for reading Status Register Bits. The Read Status Register can be read at any time (even in program/erase/write status register condition). It is recommended to check the Write in Progress (WIP) bit before sending a new instruction when a program, erase, or write status register operation is in progress.

The sequence of issuing RDSR instruction is: CS# goes low→ sending RDSR instruction code→ Status Register data out on SO.

Both SPI (8 clocks) and QPI (2 clocks) command cycle can accept by this instruction. The SIO[3:1] are "don't care" in SPI mode.

Figure 16. Read Status Register (RDSR) Sequence (SPI Mode)

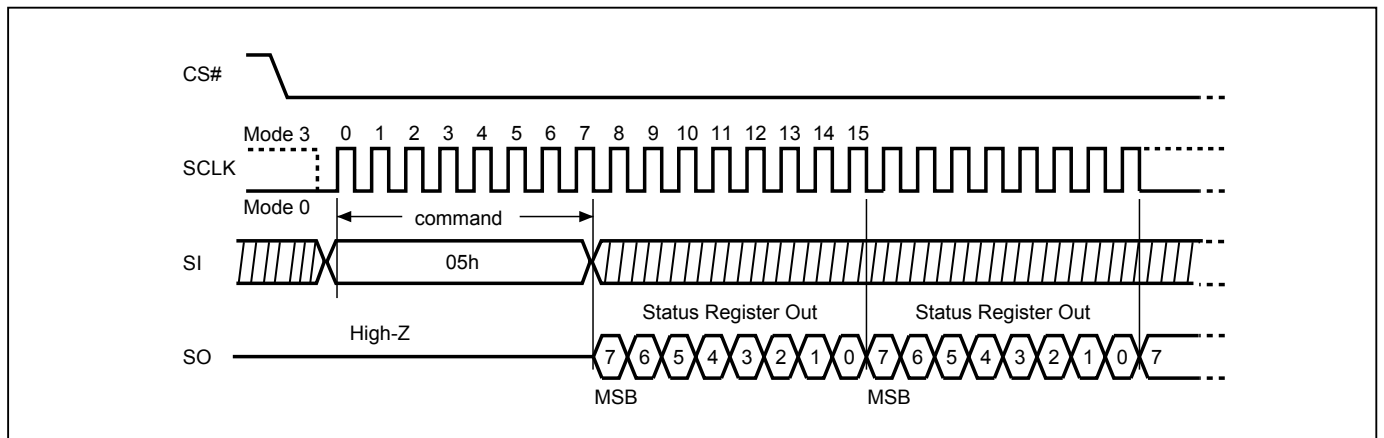
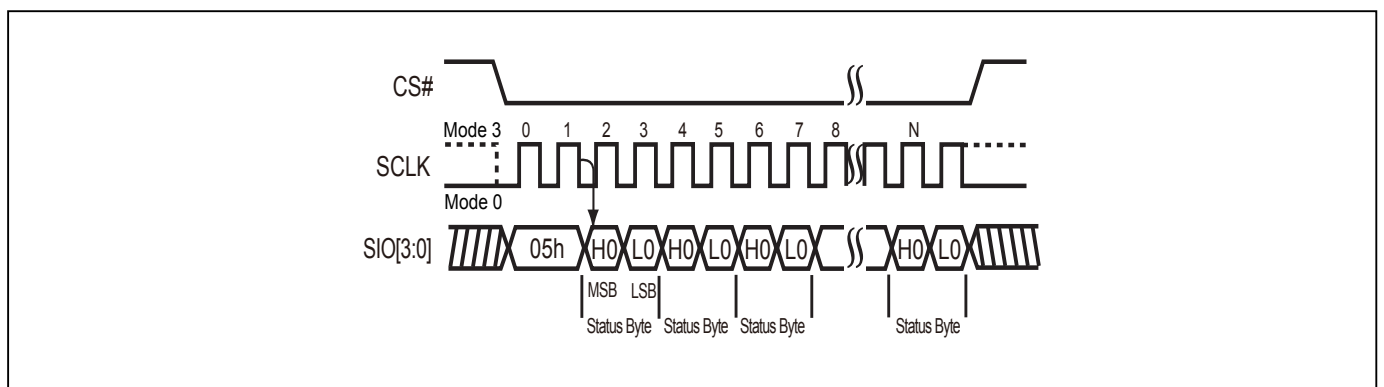
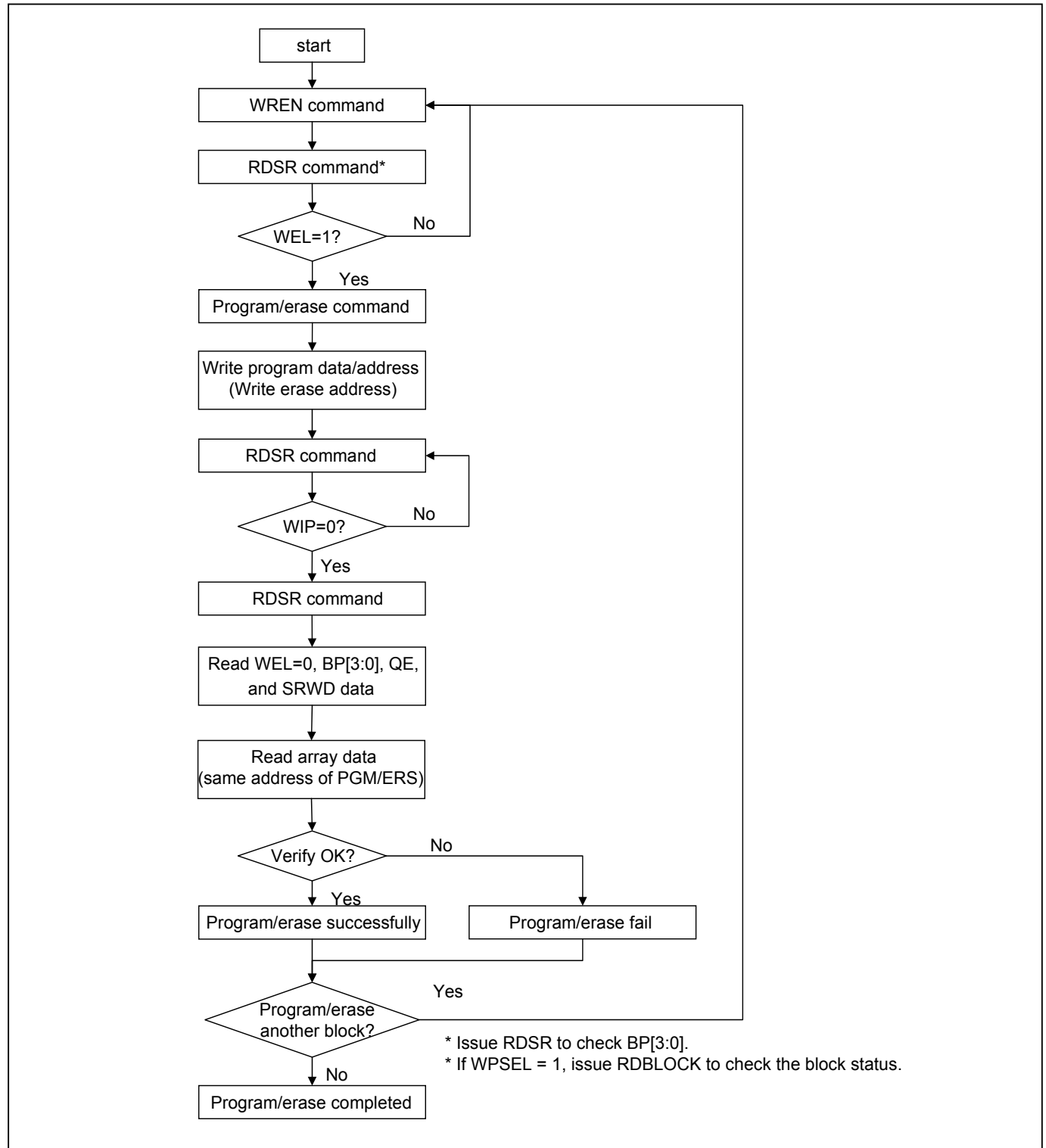


Figure 17. Read Status Register (RDSR) Sequence (QPI Mode)

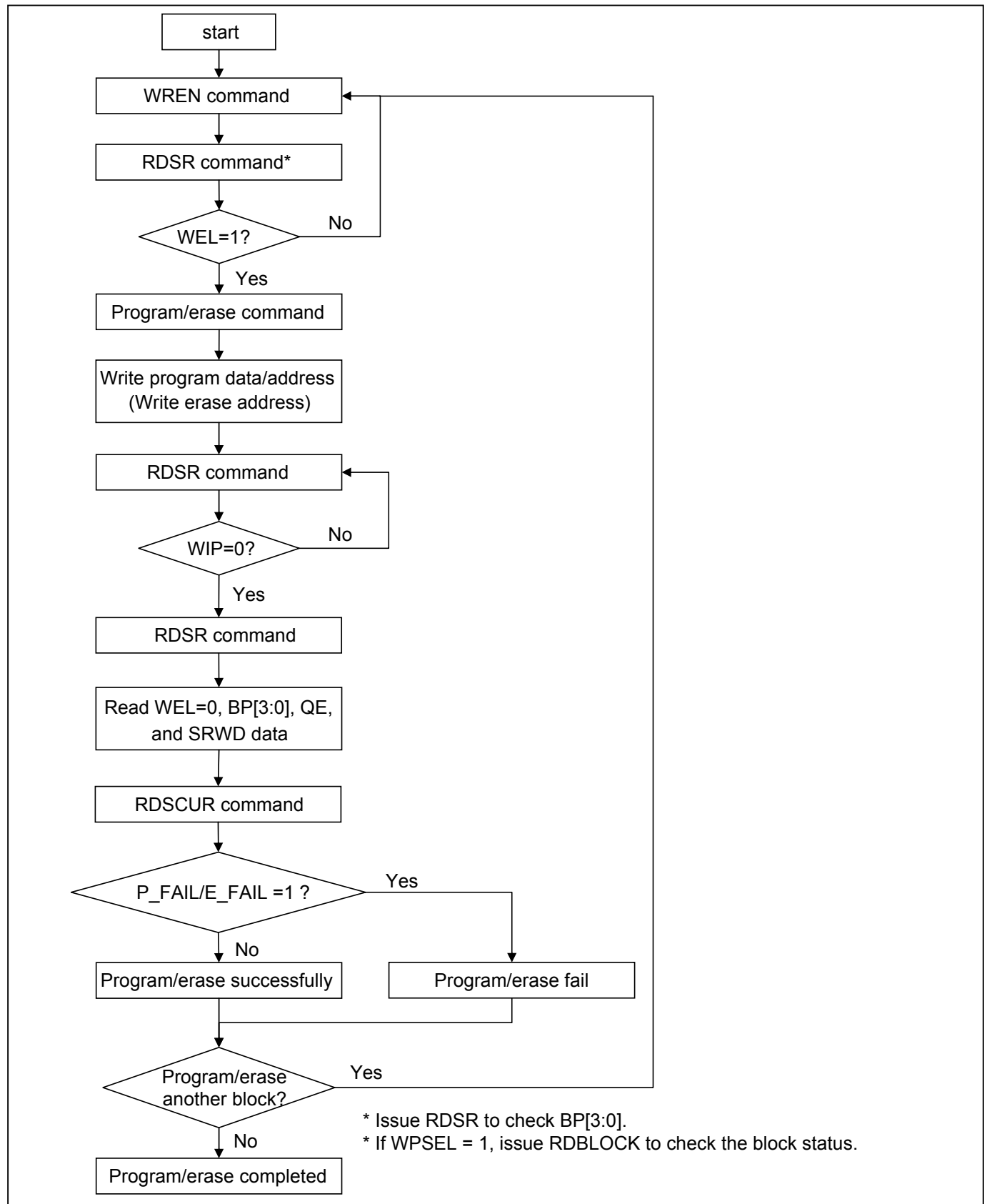


For user to check if Program/Erase operation is finished or not, RDSR instruction flow are shown as follows:

**Figure 18. Program/Erase flow with read array data**



**Figure 19. Program/Erase flow without read array data (read P\_FAIL/E\_FAIL flag)**



## Status Register

The definition of the status register bits is as below:

**WIP bit.** The Write in Progress (WIP) bit, a volatile bit, indicates whether the device is busy in program/erase/write status register progress. When WIP bit sets to 1, which means the device is busy in program/erase/write status register progress. When WIP bit sets to 0, which means the device is not in progress of program/erase/write status register cycle.

**WEL bit.** The Write Enable Latch (WEL) bit is a volatile bit that is set to "1" by the WREN instruction. WEL needs to be set to "1" before the device can accept program and erase instructions, otherwise the program and erase instructions are ignored. WEL automatically clears to "0" when a program or erase operation completes. To ensure that both WIP and WEL are "0" and the device is ready for the next program or erase operation, it is recommended that WIP be confirmed to be "0" before checking that WEL is also "0". If a program or erase instruction is applied to a protected memory area, the instruction will be ignored and WEL will clear to "0".

**BP3, BP2, BP1, BP0 bits.** The Block Protect (BP3, BP2, BP1, BP0) bits, non-volatile bits, indicate the protected area (as defined in ["Table 2. Protected Area Sizes"](#)) of the device to against the program/erase instruction without hardware protection mode being set. To write the Block Protect (BP3, BP2, BP1, BP0) bits requires the Write Status Register (WRSR) instruction to be executed. Those bits define the protected area of the memory to against Page Program (PP), Sector Erase (SE), Block Erase 32KB (BE32K), Block Erase (BE) and Chip Erase (CE) instructions (only if Block Protect bits (BP3:BP0) set to 0, the CE instruction can be executed). The BP3, BP2, BP1, BP0 bits are "0" as default, which is unprotected.

**QE bit.** The Quad Enable (QE) bit is a non-volatile bit with a factory default of "0". When QE is "0", Quad mode commands are ignored; pins WP#/SIO2 and RESET#/SIO3 function as WP# and RESET#, respectively. When QE is "1", Quad mode is enabled and Quad mode commands are supported along with Single and Dual mode commands. Pins WP#/SIO2 and RESET#/SIO3 function as SIO2 and SIO3, respectively, and their alternate pin functions are disabled. Enabling Quad mode also disables the HPM and RESET feature

**SRWD bit.** The Status Register Write Disable (SRWD) bit, non-volatile bit, is operated together with Write Protection (WP#/SIO2) pin for providing hardware protection mode. The hardware protection mode requires SRWD sets to 1 and WP#/SIO2 pin signal is low stage. In the hardware protection mode, the Write Status Register (WRSR) instruction is no longer accepted for execution and the SRWD bit and Block Protect bits (BP3, BP2, BP1, BP0) are read only. The SRWD bit defaults to be "0".

**Table 7. Status Register**

| bit7                                                                | bit6                               | bit5                           | bit4                           | bit3                           | bit2                           | bit1                                 | bit0                                          |
|---------------------------------------------------------------------|------------------------------------|--------------------------------|--------------------------------|--------------------------------|--------------------------------|--------------------------------------|-----------------------------------------------|
| SRWD (status register write protect)                                | QE (Quad Enable)                   | BP3 (level of protected block) | BP2 (level of protected block) | BP1 (level of protected block) | BP0 (level of protected block) | WEL (write enable latch)             | WIP (write in progress bit)                   |
| 1=status register write disabled<br>0=status register write enabled | 1=Quad Enable<br>0=not Quad Enable | (note 1)                       | (note 1)                       | (note 1)                       | (note 1)                       | 1=write enable<br>0=not write enable | 1=write operation<br>0=not in write operation |
| Non-volatile bit                                                    | Non-volatile bit                   | Non-volatile bit               | Non-volatile bit               | Non-volatile bit               | Non-volatile bit               | volatile bit                         | volatile bit                                  |

**Note 1:** Please refer to the ["Table 2. Protected Area Sizes"](#).

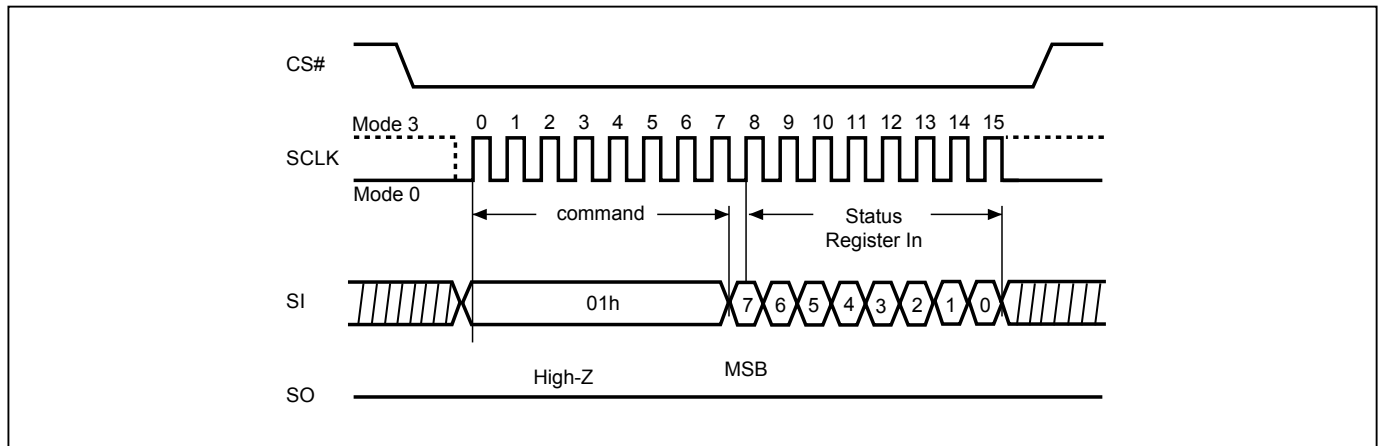
## 9-8. Write Status Register (WRSR)

The WRSR instruction is for changing the values of Status Register Bits. Before sending WRSR instruction, the Write Enable (WREN) instruction must be decoded and executed to set the Write Enable Latch (WEL) bit in advance. The WRSR instruction can change the value of Block Protect (BP3, BP2, BP1, BP0) bits to define the protected area of memory (as shown in "Table 2. Protected Area Sizes"). The WRSR also can set or reset the Quad enable (QE) bit and set or reset the Status Register Write Disable (SRWD) bit in accordance with Write Protection (WP#/SIO2) pin signal, but has no effect on bit1(WEL) and bit0 (WIP) of the status register. The WRSR instruction cannot be executed once the Hardware Protected Mode (HPM) is entered.

The sequence of issuing WRSR instruction is: CS# goes low→ sending WRSR instruction code→ Status Register data on SI→CS# goes high.

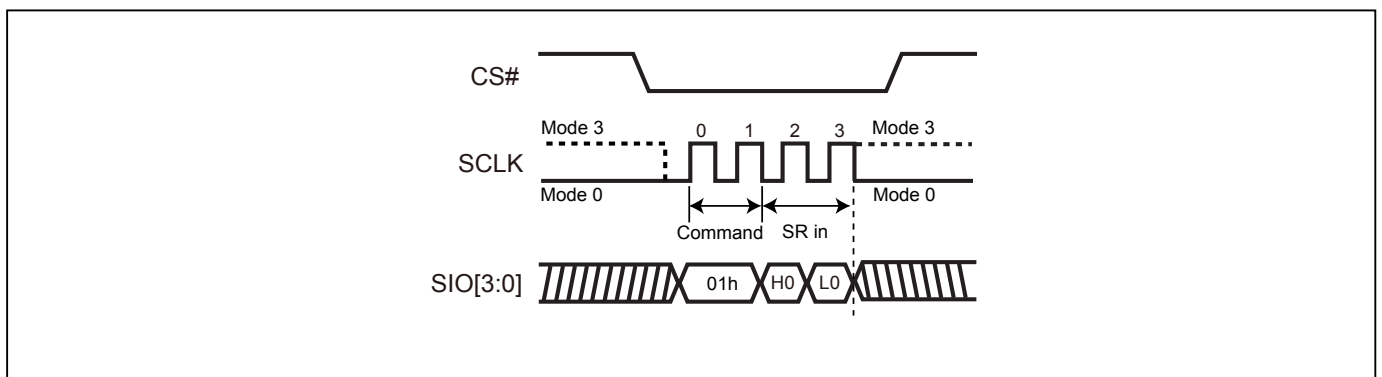
The CS# must go high exactly at the 8 bites or 16 bits data boundary; otherwise, the instruction will be rejected and not executed. The self-timed Write Status Register cycle time (tW) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be checked during the Write Status Register cycle is in progress. The WIP sets 1 during the tW timing, and sets 0 when Write Status Register Cycle is completed, and the Write Enable Latch (WEL) bit is reset.

**Figure 20. Write Status Register (WRSR) Sequence (SPI Mode)**



**Note :** The CS# must go high exactly at 8 bits or 16 bits data boundary to completed the write register command.

**Figure 21. Write Status Register (WRSR) Sequence (QPI Mode)**



**Software Protected Mode (SPM):**

- When SRWD bit=0, no matter WP#/SIO2 is low or high, the WREN instruction may set the WEL bit and can change the values of SRWD, BP3, BP2, BP1, BP0. The protected area, which is defined by BP3, BP2, BP1, BP0, is at software protected mode (SPM).
- When SRWD bit=1 and WP#/SIO2 is high, the WREN instruction may set the WEL bit can change the values of SRWD, BP3, BP2, BP1, BP0. The protected area, which is defined by BP3, BP2, BP1, BP0, is at software protected mode (SPM)

**Note:**

If SRWD bit=1 but WP#/SIO2 is low, it is impossible to write the Status Register even if the WEL bit has previously been set. It is rejected to write the Status Register and not be executed.

**Hardware Protected Mode (HPM):**

- When SRWD bit=1, and then WP#/SIO2 is low (or WP#/SIO2 is low before SRWD bit=1), it enters the hardware protected mode (HPM). The data of the protected area is protected by software protected mode by BP3, BP2, BP1, BP0 and hardware protected mode by the WP#/SIO2 to against data modification.

**Note:**

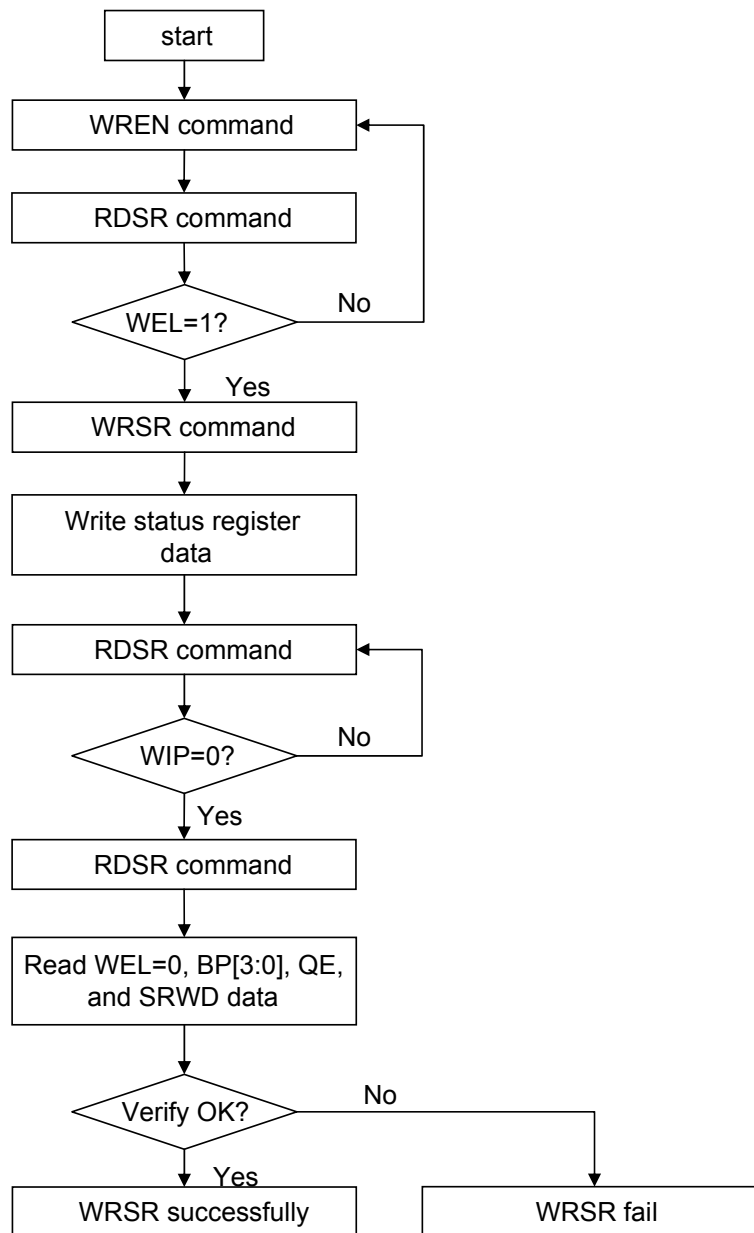
To exit the hardware protected mode requires WP#/SIO2 driving high once the hardware protected mode is entered. If the WP#/SIO2 pin is permanently connected to high, the hardware protected mode can never be entered; only can use software protected mode via BP3, BP2, BP1, BP0.

If the system enter QPI or set QE=1, the feature of HPM will be disabled.

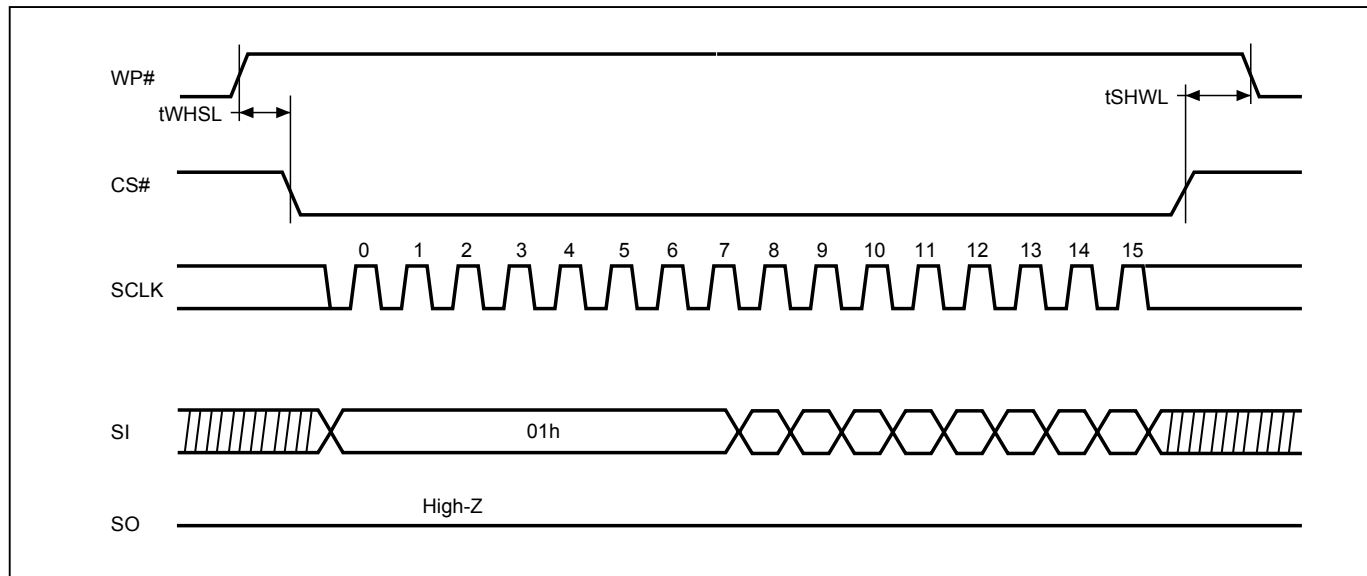
**Table 8. Protection Modes**

| Mode                           | Status register condition                                                                           | WP# and SRWD bit status                                                  | Memory                                         |
|--------------------------------|-----------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------|------------------------------------------------|
| Software protection mode (SPM) | Status register can be written in (WEL bit is set to "1") and the SRWD, BP0-BP3 bits can be changed | WP#=1 and SRWD bit=0, or<br>WP#=0 and SRWD bit=0, or<br>WP#=1 and SRWD=1 | The protected area cannot be program or erase. |
| Hardware protection mode (HPM) | The SRWD, BP0-BP3 of status register bits cannot be changed                                         | WP#=0, SRWD bit=1                                                        | The protected area cannot be program or erase. |

**Note:** As defined by the values in the Block Protect (BP3, BP2, BP1, BP0) bits of the Status Register, as shown in ["Table 2. Protected Area Sizes"](#).

**Figure 22. WRSR flow**

**Figure 23. WP# Setup Timing and Hold Timing during WRSR when SRWD=1**

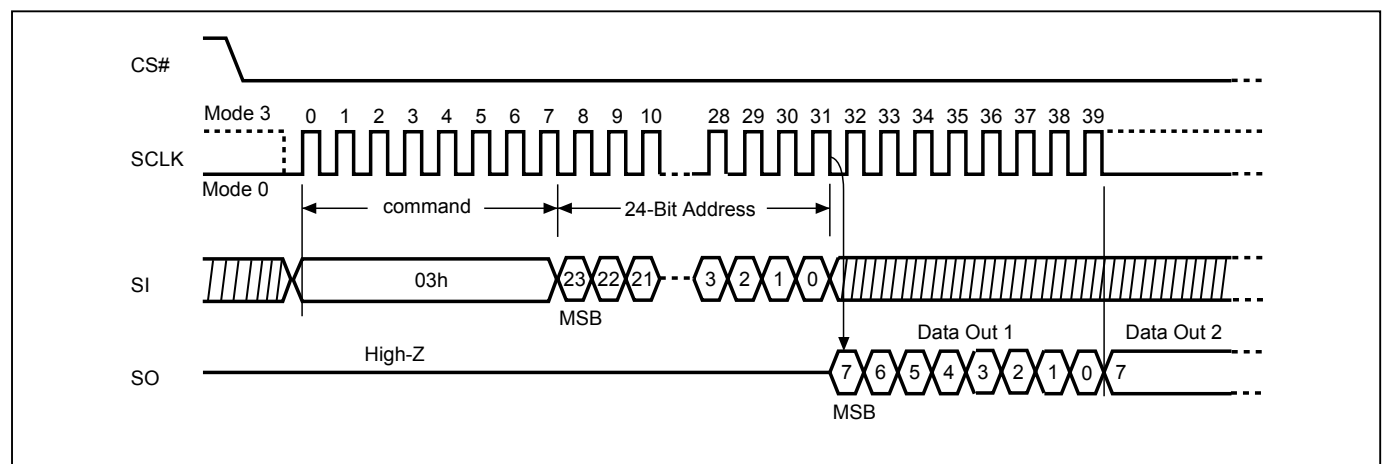


### 9-9. Read Data Bytes (READ)

The read instruction is for reading data out. The address is latched on rising edge of SCLK, and data shifts out on the falling edge of SCLK at a maximum frequency  $f_R$ . The first address byte can be at any location. The address is automatically increased to the next higher address after each byte data is shifted out, so the whole memory can be read out at a single READ instruction. The address counter rolls over to 0 when the highest address has been reached.

The sequence of issuing READ instruction is: CS# goes low→sending READ instruction code→ 3-byte address on SI→ data out on SO→to end READ operation can use CS# to high at any time during data out.

**Figure 24. Read Data Bytes (READ) Sequence (SPI Mode only)**



**9-10. Read Data Bytes at Higher Speed (FAST\_READ)**

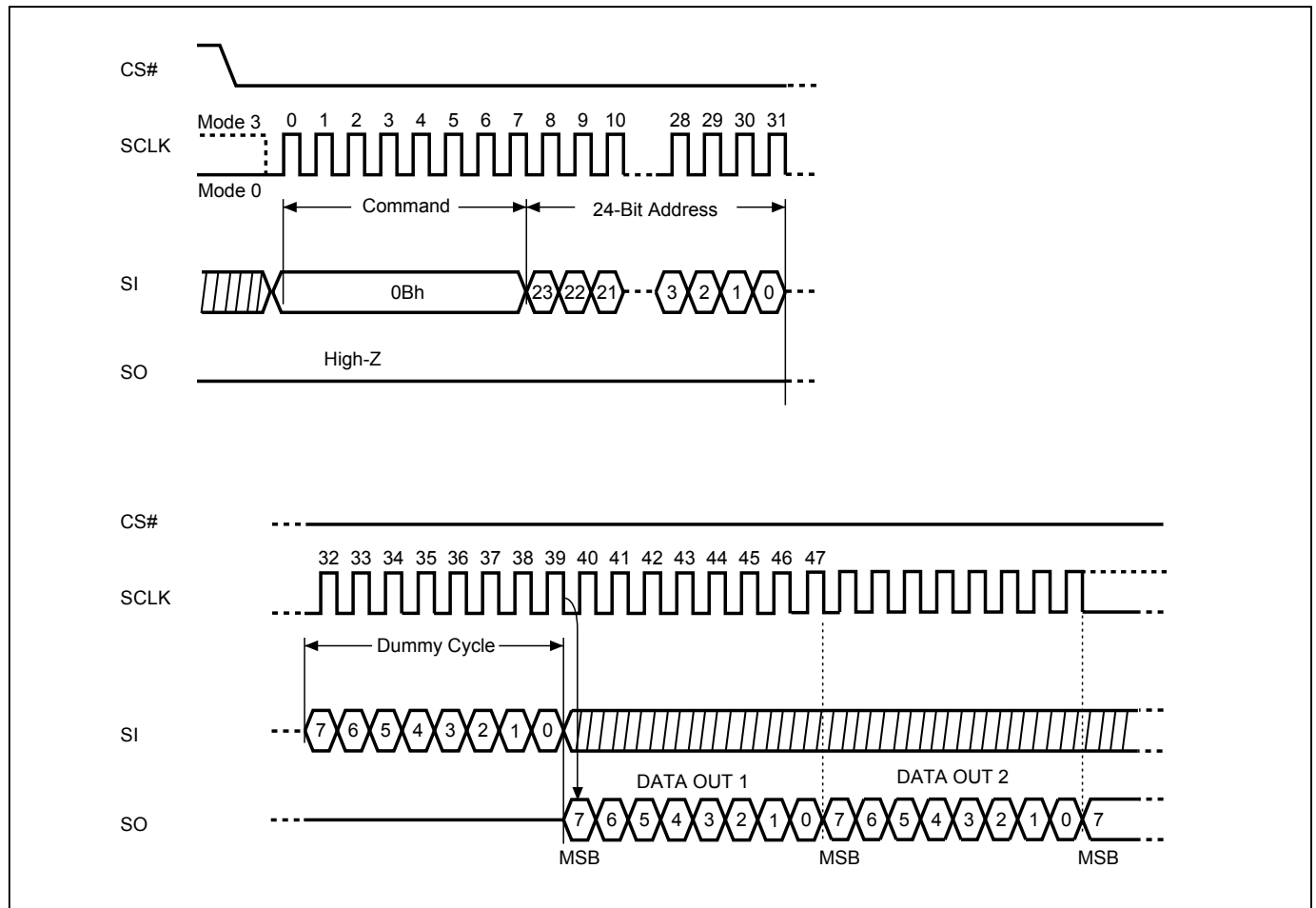
The FAST\_READ instruction is for quickly reading data out. The address is latched on rising edge of SCLK, and data of each bit shifts out on the falling edge of SCLK at a maximum frequency fC. The first address byte can be at any location. The address is automatically increased to the next higher address after each byte data is shifted out, so the whole memory can be read out at a single FAST\_READ instruction. The address counter rolls over to 0 when the highest address has been reached.

**Read on SPI Mode** The sequence of issuing FAST\_READ instruction is: CS# goes low→ sending FAST\_READ instruction code→ 3-byte address on SI→1-dummy byte (default) address on SI→ data out on SO→ to end FAST\_READ operation can use CS# to high at any time during data out.

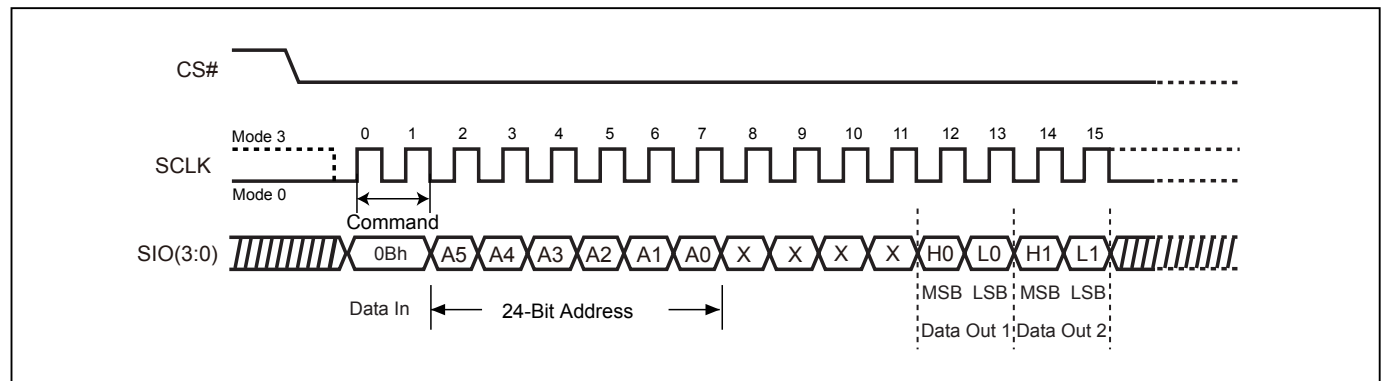
**Read on QPI Mode** The sequence of issuing FAST\_READ instruction in QPI mode is: CS# goes low→ sending FAST\_READ instruction, 2 cycles→ 24-bit address interleave on SIO3, SIO2, SIO1 & SIO0→4 dummy cycles→data out interleave on SIO3, SIO2, SIO1 & SIO0→ to end QPI FAST\_READ operation can use CS# to high at any time during data out.

While Program/Erase/Write Status Register cycle is in progress, FAST\_READ instruction is rejected without any impact on the Program/Erase/Write Status Register current cycle.

**Figure 25. Read at Higher Speed (FAST\_READ) Sequence (SPI Mode)**



**Figure 26. Read at Higher Speed (FAST\_READ) Sequence (QPI Mode)**



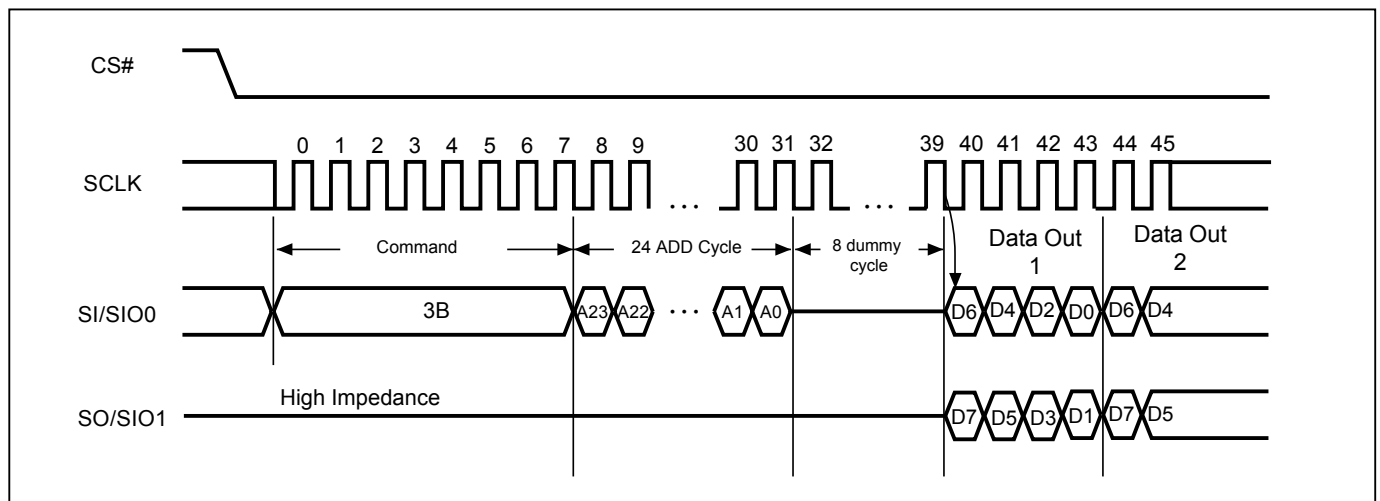
### 9-11. Dual Read Mode (DREAD)

The DREAD instruction enable double throughput of Serial NOR Flash in read mode. The address is latched on rising edge of SCLK, and data of every two bits (interleave on 2 I/O pins) shift out on the falling edge of SCLK at a maximum frequency fT. The first address byte can be at any location. The address is automatically increased to the next higher address after each byte data is shifted out, so the whole memory can be read out at a single DREAD instruction. The address counter rolls over to 0 when the highest address has been reached. Once writing DREAD instruction, the following data out will perform as 2-bit instead of previous 1-bit.

The sequence of issuing DREAD instruction is: CS# goes low → sending DREAD instruction → 3-byte address on SI → 8-bit dummy cycle → data out interleave on SIO1 & SIO0 → to end DREAD operation can use CS# to high at any time during data out.

While Program/Erase/Write Status Register cycle is in progress, DREAD instruction is rejected without any impact on the Program/Erase/Write Status Register current cycle.

**Figure 27. Dual Read Mode Sequence (Command 3Bh)**



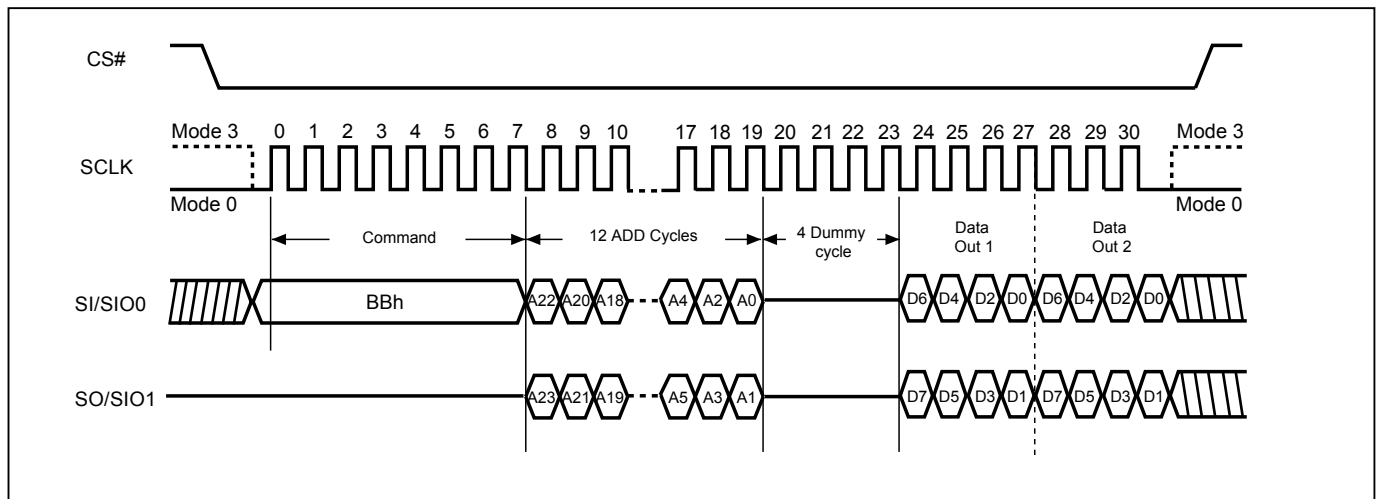
## 9-12. 2 x I/O Read Mode (2READ)

The 2READ instruction enable double throughput of Serial NOR Flash in read mode. The address is latched on rising edge of SCLK, and data of every two bits (interleave on 2 I/O pins) shift out on the falling edge of SCLK at a maximum frequency  $f_T$ . The first address byte can be at any location. The address is automatically increased to the next higher address after each byte data is shifted out, so the whole memory can be read out at a single 2READ instruction. The address counter rolls over to 0 when the highest address has been reached. Once writing 2READ instruction, the following address/dummy/data out will perform as 2-bit instead of previous 1-bit.

The sequence of issuing 2READ instruction is: CS# goes low → sending 2READ instruction → 24-bit address interleave on SIO1 & SIO0 → 4 dummy cycles on SIO1 & SIO0 → data out interleave on SIO1 & SIO0 → to end 2READ operation can use CS# to high at any time during data out.

While Program/Erase/Write Status Register cycle is in progress, 2READ instruction is rejected without any impact on the Program/Erase/Write Status Register current cycle.

**Figure 28. 2 x I/O Read Mode Sequence (SPI Mode only)**



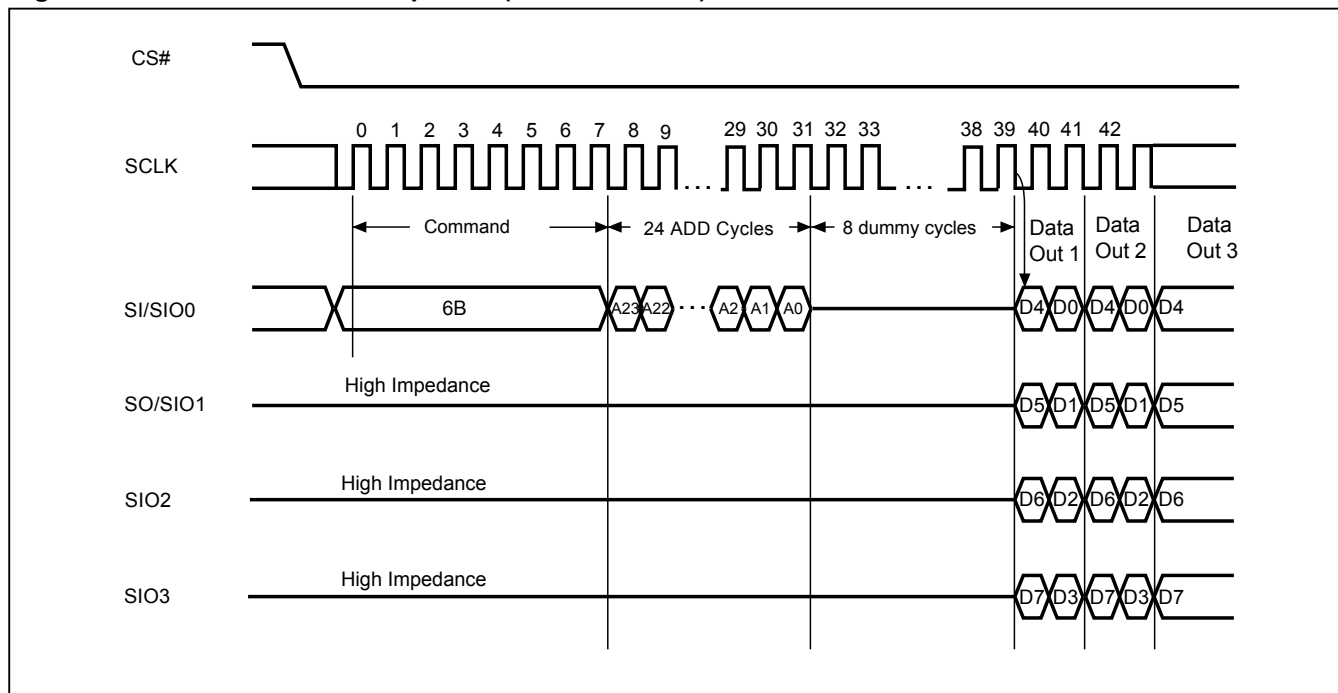
### 9-13. Quad Read Mode (QREAD)

The QREAD instruction enable quad throughput of Serial NOR Flash in read mode. A Quad Enable (QE) bit of status Register must be set to "1" before sending the QREAD instruction. The address is latched on rising edge of SCLK, and data of every four bits (interleave on 4 I/O pins) shift out on the falling edge of SCLK at a maximum frequency fQ. The first address byte can be at any location. The address is automatically increased to the next higher address after each byte data is shifted out, so the whole memory can be read out at a single QREAD instruction. The address counter rolls over to 0 when the highest address has been reached. Once writing QREAD instruction, the following data out will perform as 4-bit instead of previous 1-bit.

The sequence of issuing QREAD instruction is: CS# goes low → sending QREAD instruction → 3-byte address on SI → 8-bit dummy cycle → data out interleave on SIO3, SIO2, SIO1 & SIO0 → to end QREAD operation can use CS# to high at any time during data out.

While Program/Erase/Write Status Register cycle is in progress, QREAD instruction is rejected without any impact on the Program/Erase/Write Status Register current cycle.

**Figure 29. Quad Read Mode Sequence (Command 6Bh)**



**9-14. 4 x I/O Read Mode (4READ)**

The 4READ instruction enable quad throughput of Serial NOR Flash in read mode. A Quad Enable (QE) bit of status Register must be set to "1" before sending the 4READ instruction. The address is latched on rising edge of SCLK, and data of every four bits (interleave on 4 I/O pins) shift out on the falling edge of SCLK at a maximum frequency fQ. The first address byte can be at any location. The address is automatically increased to the next higher address after each byte data is shifted out, so the whole memory can be read out at a single 4READ instruction. The address counter rolls over to 0 when the highest address has been reached. Once writing 4READ instruction, the following address/dummy/data out will perform as 4-bit instead of previous 1-bit.

**4 x I/O Read on SPI Mode (4READ)** The sequence of issuing 4READ instruction is: CS# goes low→ sending 4READ instruction→ 24-bit address interleave on SIO3, SIO2, SIO1 & SIO0→2+4 dummy cycles→data out interleave on SIO3, SIO2, SIO1 & SIO0→ to end 4READ operation can use CS# to high at any time during data out.

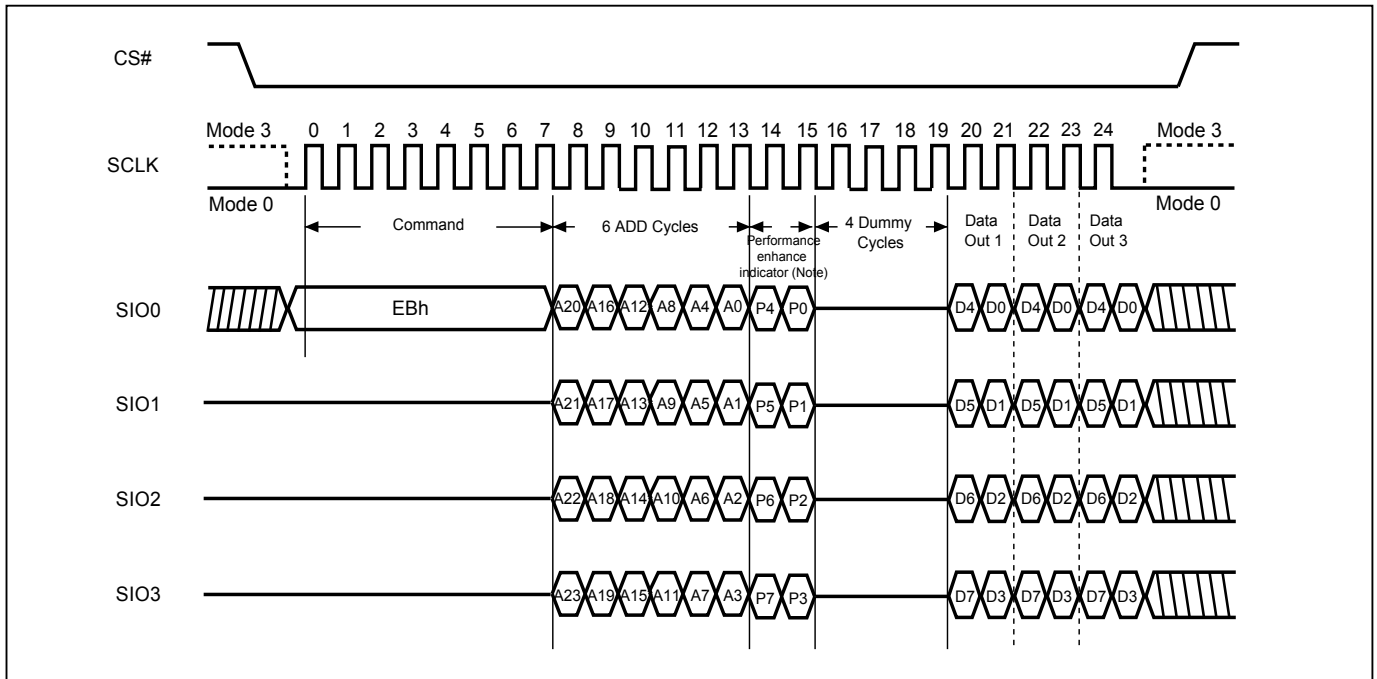
**4 x I/O Read on QPI Mode (4READ)** The 4READ instruction also support on QPI command mode. The sequence of issuing 4READ instruction QPI mode is: CS# goes low→ sending 4READ instruction→ 24-bit address interleave on SIO3, SIO2, SIO1 & SIO0→2+4 dummy cycles→data out interleave on SIO3, SIO2, SIO1 & SIO0→ to end 4READ operation can use CS# to high at any time during data out.

Another sequence of issuing 4READ instruction especially useful in random access is: CS# goes low→send 4READ instruction→3-bytes address interleave on SIO3, SIO2, SIO1 & SIO0 →performance enhance toggling bit P[7:0]→ 4 dummy cycles →data out until CS# goes high→ CS# goes low (The following 4READ instruction is not allowed, hence 8 cycles of 4READ can be saved comparing to normal 4READ mode) →24-bit random access address.

In the performance-enhancing mode, P[7:4] must be toggling with P[3:0] ; likewise P[7:0]=A5h, 5Ah, F0h or 0Fh can make this mode continue and reduce the next 4READ instruction. Once P[7:4] is no longer toggling with P[3:0]; likewise P[7:0]=FFh,00h,AAh or 55h and afterwards CS# is raised and then lowered, the system then will escape from performance enhance mode and return to normal operation.

While Program/Erase/Write Status Register cycle is in progress, 4READ instruction is rejected without any impact on the Program/Erase/Write Status Register current cycle.

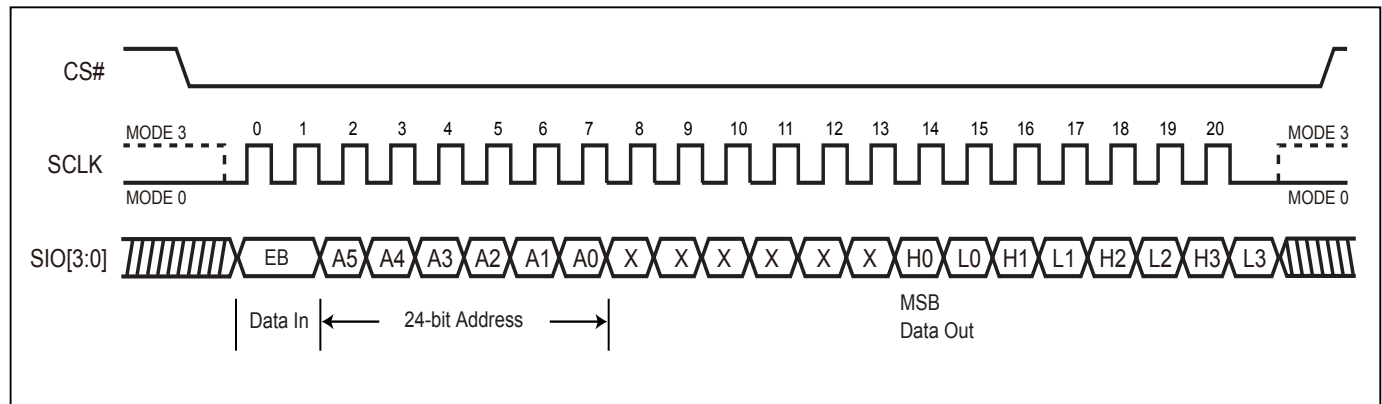
**Figure 30. 4 x I/O Read Mode Sequence (SPI Mode)**



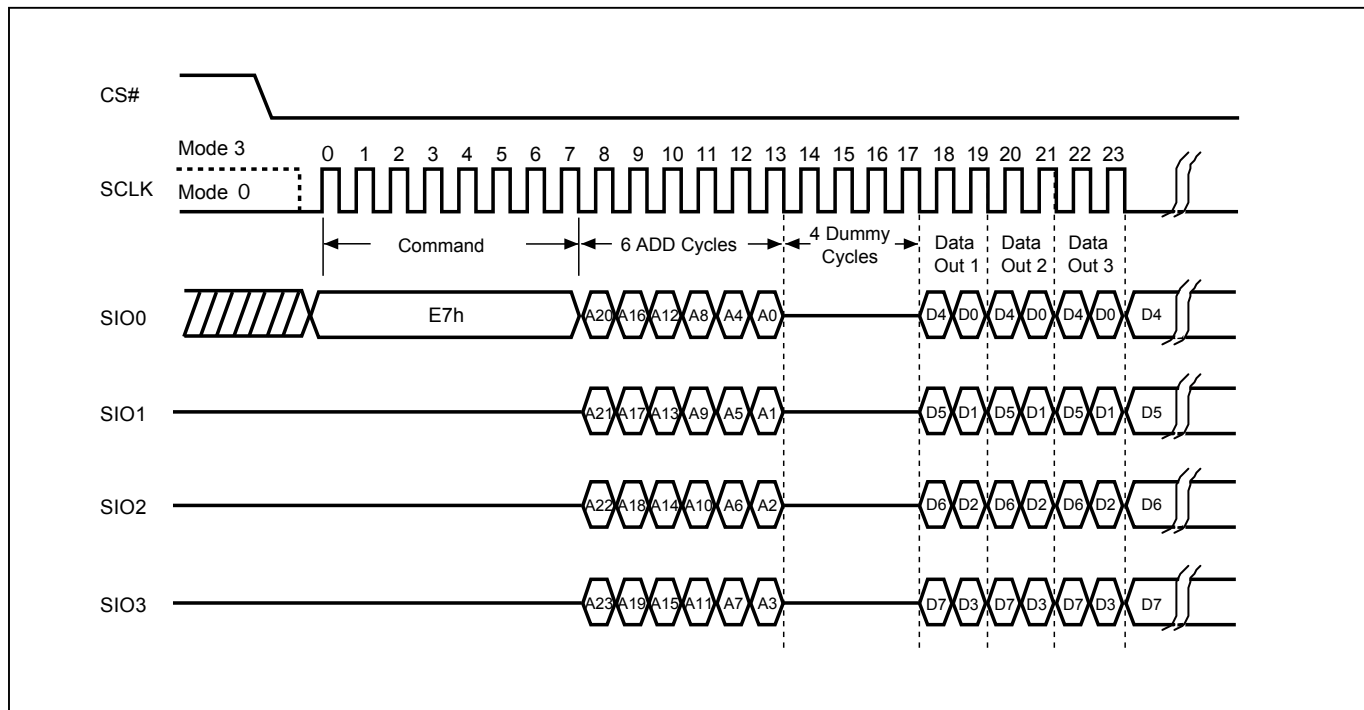
**Note:**

1. Hi-impedance is inhibited for the two clock cycles.
2. P7#P3, P6#P2, P5#P1 & P4#P0 (Toggling) is inhibited.

**Figure 31. 4 x I/O Read Mode Sequence (QPI Mode)**



**Figure 32. W4READ (Quad Read with 4 dummy cycles) Sequence**



## 9-15. Burst Read

This device supports Burst Read in both SPI and QPI mode.

To set the Burst length, following command operation is required

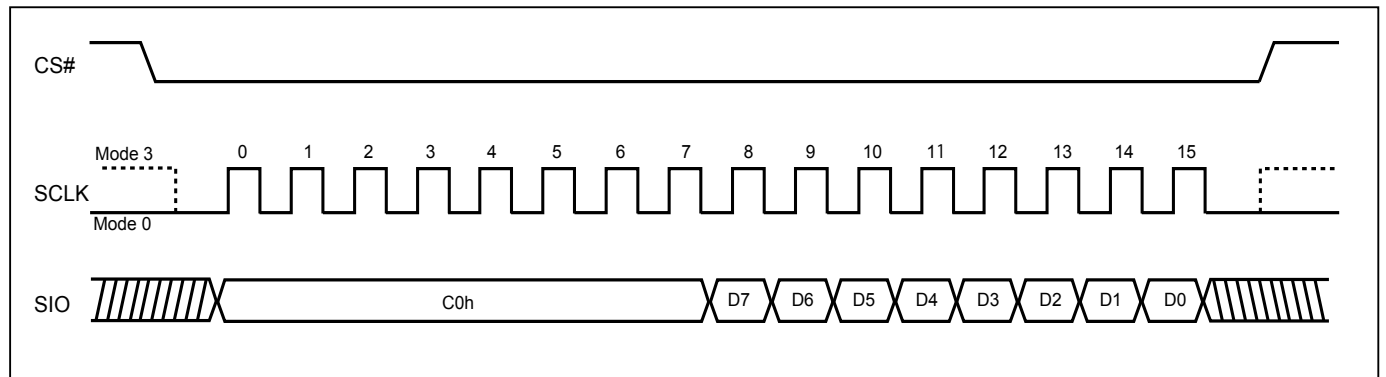
Issuing command: “C0h” in the first Byte (8-clocks), following 4 clocks defining wrap around enable with “0h” and disable with “1h”.

Next 4 clocks is to define wrap around depth. Definition as following table:

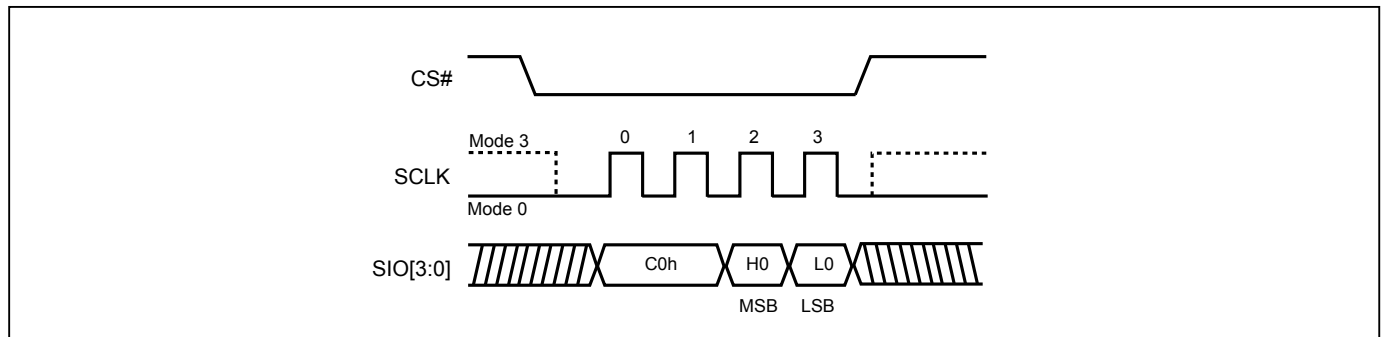
| Data | Wrap Around | Wrap Depth |
|------|-------------|------------|
| 00h  | Yes         | 8-byte     |
| 01h  | Yes         | 16-byte    |
| 02h  | Yes         | 32-byte    |
| 03h  | Yes         | 64-byte    |
| 1xh  | No          | X          |

The wrap around unit is defined within the 256Byte page, with random initial address. It's defined as “wrap-around mode disable” for the default state of the device. To exit wrap around, it is required to issue another “C0h” command in which data=‘1xh’. Otherwise, wrap around status will be retained until power down or reset command. To change wrap around depth, it is required to issue another “C0h” command in which data=“0xh”. QPI “0Bh” “EBh” and SPI “EBh” “E7h” support wrap around feature after wrap around enable. Burst read is supported in both SPI and QPI mode. The device is default without Burst read.

**Figure 33. Burst Read - SPI Mode**



**Figure 34. Burst Read - QPI Mode**



**Note:** MSB=Most Significant Bit  
LSB=Least Significant Bit

#### **9-16. Performance Enhance Mode**

The device could waive the command cycle bits if the two cycle bits after address cycle toggles.

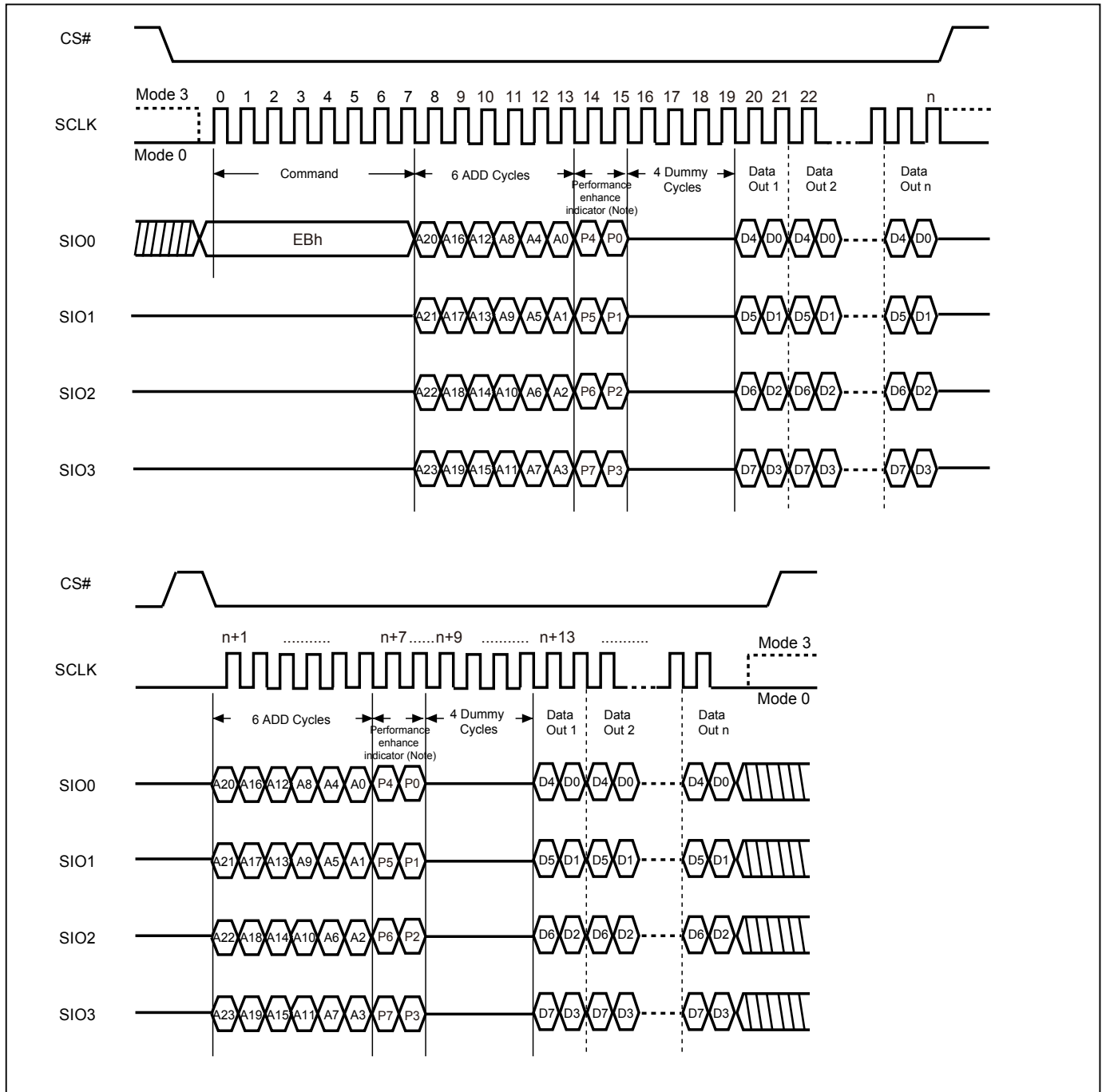
Performance enhance mode is supported in both SPI and QPI mode.

In QPI mode, “EBh” “0Bh” and SPI “EBh” “E7h” commands support enhance mode. The performance enhance mode is not supported in dual I/O mode.

After entering enhance mode, following CS# go high, the device will stay in the read mode and treat CS# go low of the first clock as address instead of command cycle.

To exit enhance mode, a new fast read command whose first two dummy cycles is not toggle then exit. Or issue “FFh” data cycle to exit enhance mode.

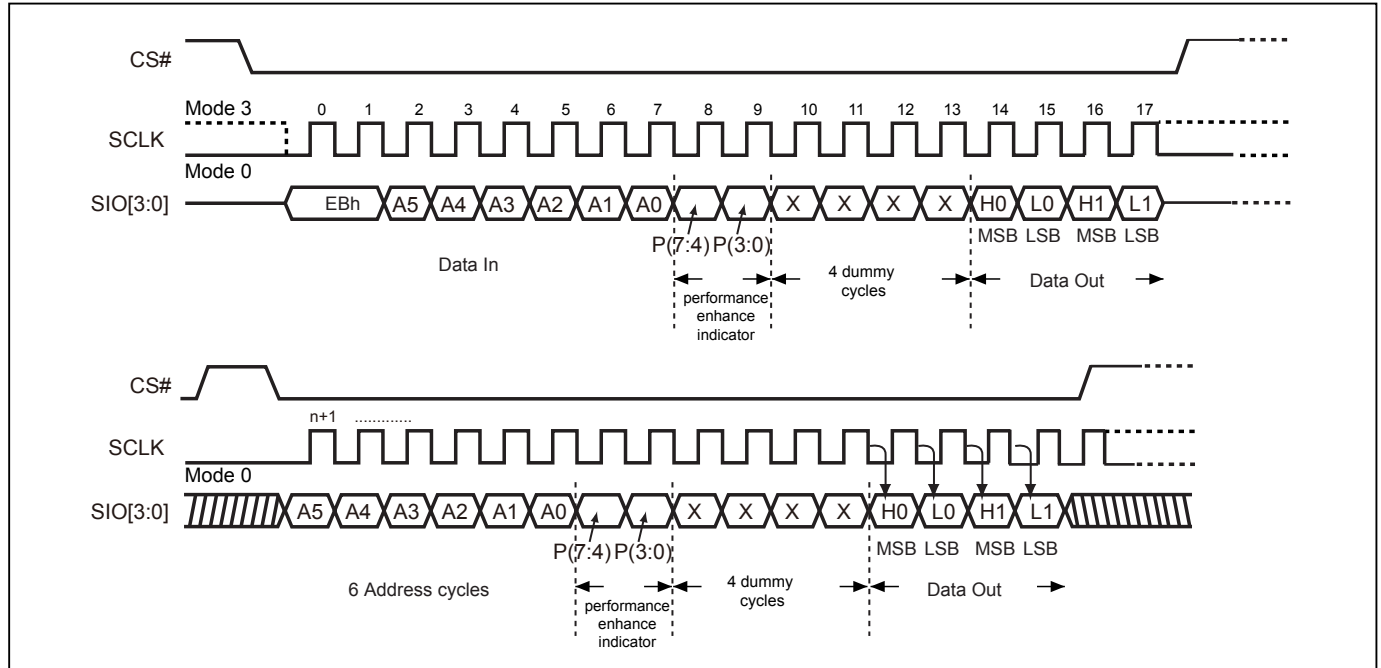
**Figure 35. 4 x I/O Read Performance Enhance Mode Sequence (SPI Mode)**



**Note:**

1. Performance enhance mode, if  $P7 \neq P3$  &  $P6 \neq P2$  &  $P5 \neq P1$  &  $P4 \neq P0$  (Toggling), ex: A5, 5A, 0F, if not using performance enhance recommend to keep 1 or 0 in performance enhance indicator.
2. Reset the performance enhance mode, if  $P7 = P3$  or  $P6 = P2$  or  $P5 = P1$  or  $P4 = P0$ , ex: AA, 00, FF.

**Figure 36. 4 x I/O Read Performance Enhance Mode Sequence (QPI Mode)**



**Note:**

1. Performance enhance mode, if  $P7 \neq P3$  &  $P6 \neq P2$  &  $P5 \neq P1$  &  $P4 \neq P0$  (Toggling), ex: A5, 5A, 0F, if not using performance enhance recommend to keep 1 or 0 in performance enhance indicator.
2. Reset the performance enhance mode, if  $P7 = P3$  or  $P6 = P2$  or  $P5 = P1$  or  $P4 = P0$ , ex: AA, 00, FF.

## 9-17. Sector Erase (SE)

The Sector Erase (SE) instruction is for erasing the data of the chosen sector to be "1". The instruction is used for any 4K-byte sector. A Write Enable (WREN) instruction must execute to set the Write Enable Latch (WEL) bit before sending the Sector Erase (SE). Any address of the sector (as shown in "Table 4. Memory Organization") is a valid address for Sector Erase (SE) instruction. The CS# must go high exactly at the byte boundary (the latest eighth of address byte been latched-in); otherwise, the instruction will be rejected and not executed.

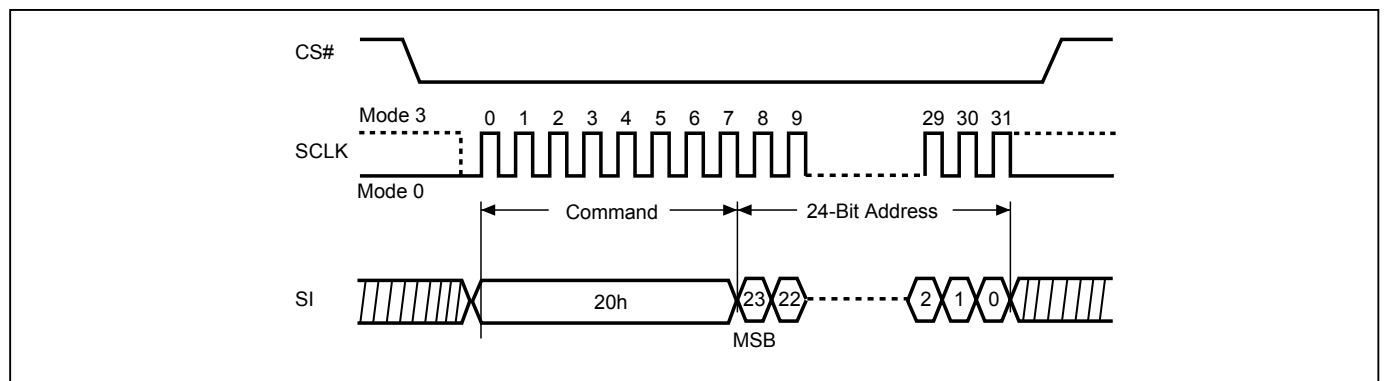
Address bits [Am-A12] (Am is the most significant address) select the sector address.

The sequence of issuing SE instruction is: CS# goes low→ sending SE instruction code→ 3-byte address on SI→ CS# goes high.

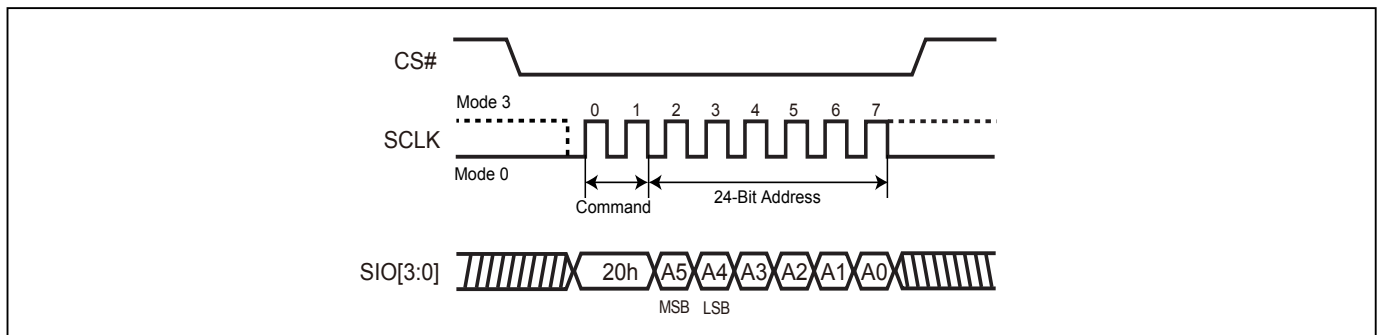
Both SPI (8 clocks) and QPI (2 clocks) command cycle can accept by this instruction. The SIO[3:1] are "don't care" in SPI mode.

The self-timed Sector Erase Cycle time (tSE) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be checked during the Sector Erase cycle is in progress. The WIP sets 1 during the tSE timing, and sets 0 when Sector Erase Cycle is completed, and the Write Enable Latch (WEL) bit is reset. If the sector is protected by BP3, BP2, BP1, BP0 bits, the Sector Erase (SE) instruction will not be executed on the sector.

**Figure 37. Sector Erase (SE) Sequence (SPI Mode)**



**Figure 38. Sector Erase (SE) Sequence (QPI Mode)**



### 9-18. Block Erase (BE32K)

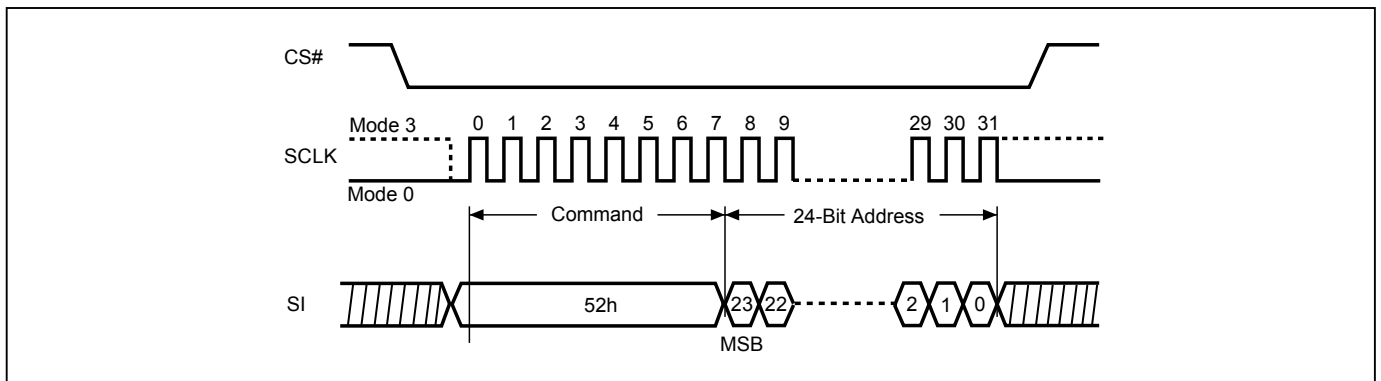
The Block Erase (BE32K) instruction is for erasing the data of the chosen block to be "1". The instruction is used for 32K-byte block erase operation. A Write Enable (WREN) instruction must execute to set the Write Enable Latch (WEL) bit before sending the Block Erase (BE32K). Any address of the block (as shown in ["Table 4. Memory Organization"](#)) is a valid address for Block Erase (BE32K) instruction. The CS# must go high exactly at the byte boundary (the latest eighth of address byte been latched-in); otherwise, the instruction will be rejected and not executed.

The sequence of issuing BE32K instruction is: CS# goes low→ sending BE32K instruction code→ 3-byte address on SI→CS# goes high.

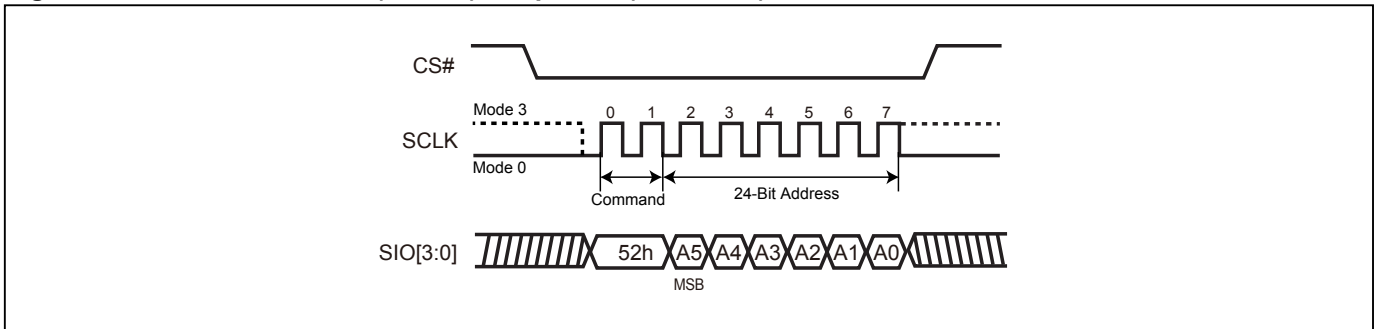
Both SPI (8 clocks) and QPI (2 clocks) command cycle can accept by this instruction. The SIO[3:1] are "don't care" in SPI mode.

The self-timed Block Erase Cycle time (tBE32K) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be checked during the Block Erase cycle is in progress. The WIP sets 1 during the tBE32K timing, and sets 0 when Block Erase Cycle is completed, and the Write Enable Latch (WEL) bit is reset. If the block is protected by BP3, BP2, BP1, BP0 bits, the Block Erase (BE32K) instruction will not be executed on the block.

**Figure 39. Block Erase 32KB (BE32K) Sequence (SPI Mode)**



**Figure 40. Block Erase 32KB (BE32K) Sequence (QPI Mode)**



### 9-19. Block Erase (BE)

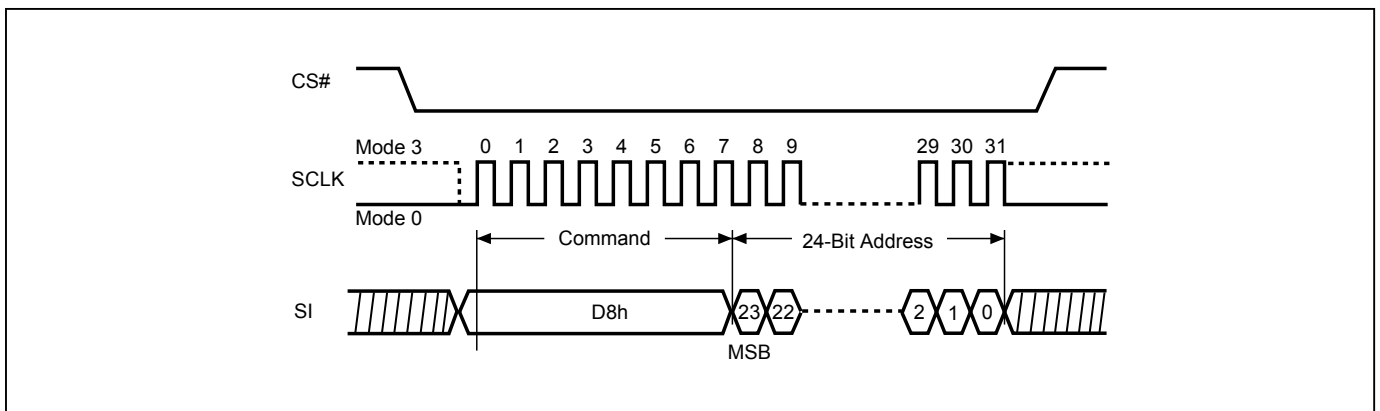
The Block Erase (BE) instruction is for erasing the data of the chosen block to be "1". The instruction is used for 64K-byte block erase operation. A Write Enable (WREN) instruction must execute to set the Write Enable Latch (WEL) bit before sending the Block Erase (BE). Any address of the block (Please refer to ["Table 4. Memory Organization"](#)) is a valid address for Block Erase (BE) instruction. The CS# must go high exactly at the byte boundary (the latest eighth of address byte been latched-in); otherwise, the instruction will be rejected and not executed.

The sequence of issuing BE instruction is: CS# goes low→ sending BE instruction code→ 3-byte address on SI→ CS# goes high.

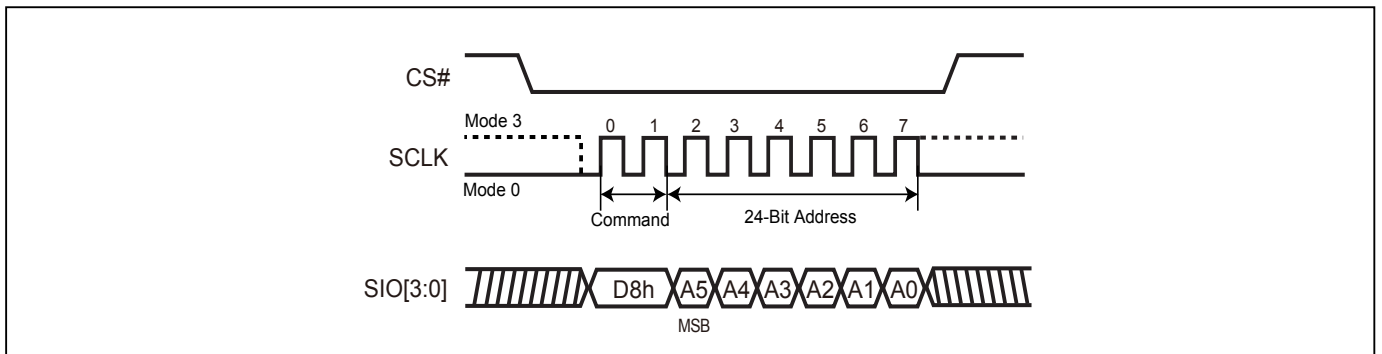
Both SPI (8 clocks) and QPI (2 clocks) command cycle can accept by this instruction. The SIO[3:1] are "don't care" in SPI mode.

The self-timed Block Erase Cycle time (tBE) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be checked during the Block Erase cycle is in progress. The WIP sets 1 during the tBE timing, and sets 0 when Block Erase Cycle is completed, and the Write Enable Latch (WEL) bit is reset. If the block is protected by BP3, BP2, BP1, BP0 bits, the Block Erase (BE) instruction will not be executed on the block.

**Figure 41. Block Erase (BE) Sequence (SPI Mode)**



**Figure 42. Block Erase (BE) Sequence (QPI Mode)**



## 9-20. Chip Erase (CE)

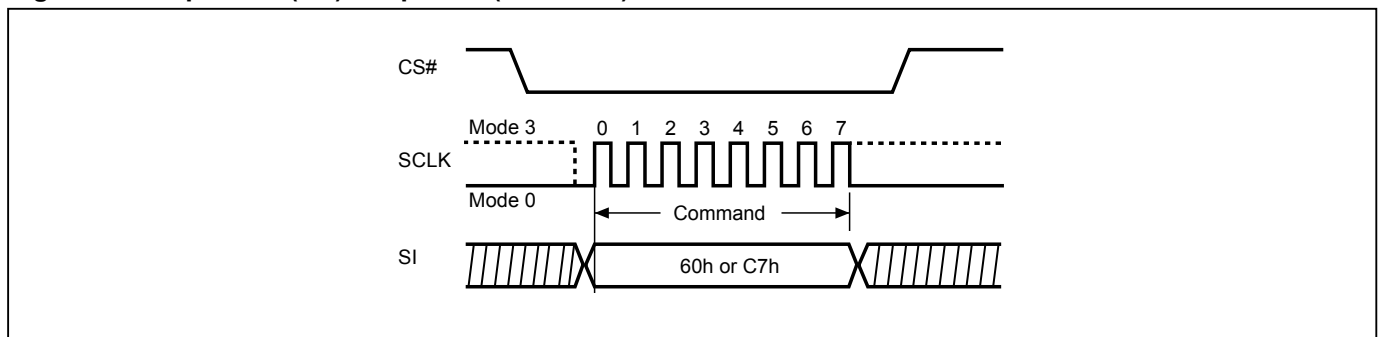
The Chip Erase (CE) instruction is for erasing the data of the whole chip to be "1". A Write Enable (WREN) instruction must execute to set the Write Enable Latch (WEL) bit before sending the Chip Erase (CE). The CS# must go high exactly at the byte boundary, otherwise the instruction will be rejected and not executed.

The sequence of issuing CE instruction is: CS# goes low→sending CE instruction code→CS# goes high.

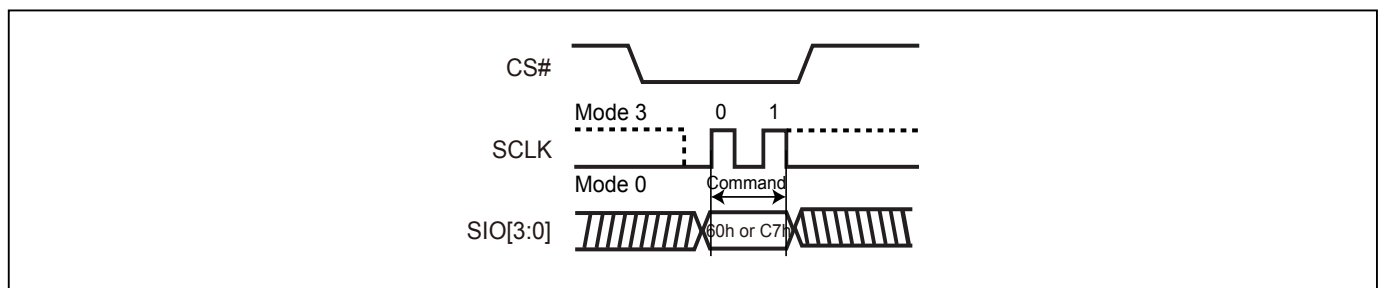
Both SPI (8 clocks) and QPI (2 clocks) command cycle can accept by this instruction. The SIO[3:1] are "don't care" in SPI mode.

The self-timed Chip Erase Cycle time ( $t_{CE}$ ) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be checked during the Chip Erase cycle is in progress. The WIP sets 1 during the  $t_{CE}$  timing, and sets 0 when Chip Erase Cycle is completed, and the Write Enable Latch (WEL) bit is reset. If the chip is protected by BP3, BP2, BP1, BP0 bits, the Chip Erase (CE) instruction will not be executed. It will be only executed when BP3, BP2, BP1, BP0 all set to "0".

**Figure 43. Chip Erase (CE) Sequence (SPI Mode)**



**Figure 44. Chip Erase (CE) Sequence (QPI Mode)**



**9-21. Page Program (PP)**

The Page Program (PP) instruction is for programming memory bits to "0". One to 256 bytes can be sent to the device to be programmed. A Write Enable (WREN) instruction must be executed to set the Write Enable Latch (WEL) bit before sending the Page Program (PP). If more than 256 data bytes are sent to the device, only the last 256 data bytes will be accepted and the previous data bytes will be disregarded. The Page Program instruction requires that all the data bytes fall within the same 256-byte page. The low order address byte A[7:0] specifies the starting address within the selected page. Bytes that will cross a page boundary will wrap to the beginning of the selected page. The device can accept (256 minus A[7:0]) data bytes without wrapping. If 256 data bytes are going to be programmed, A[7:0] should be set to 0.

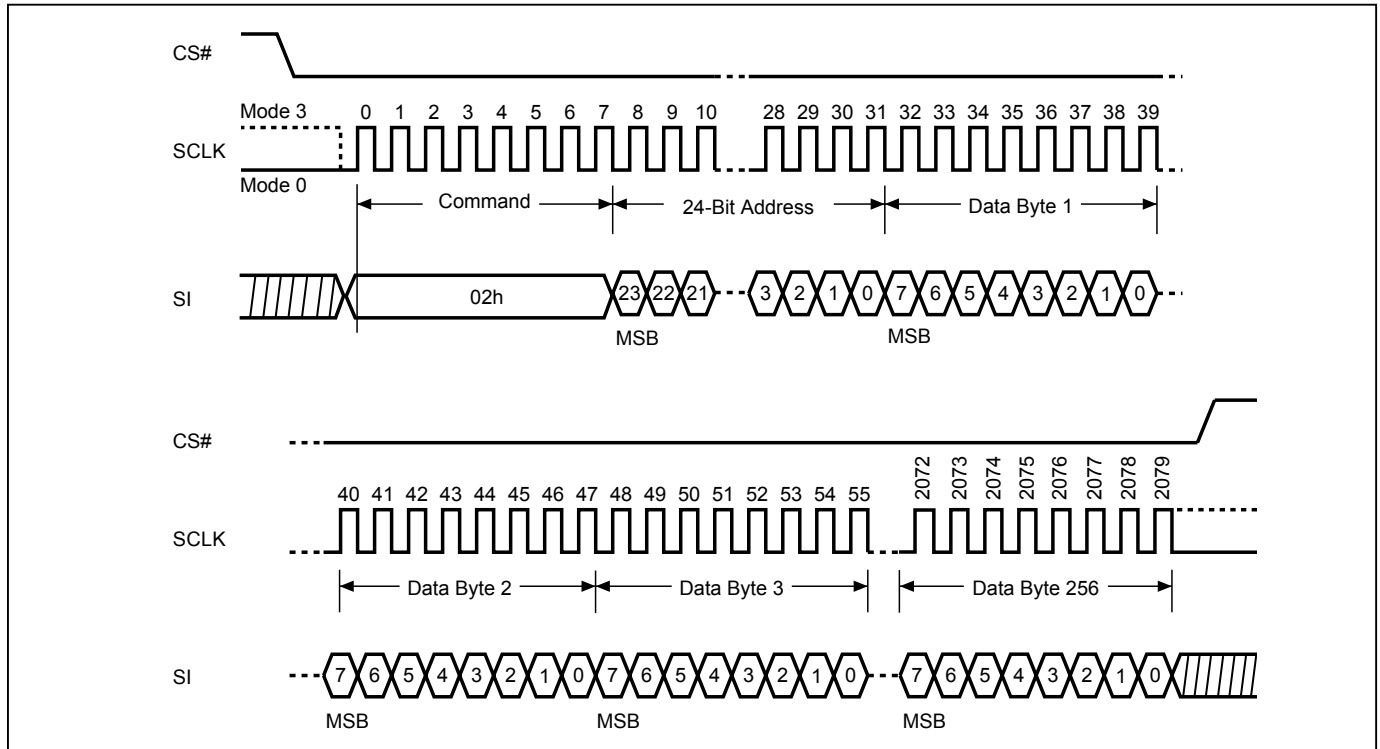
The sequence of issuing PP instruction is: CS# goes low→ sending PP instruction code→ 3-byte address on SI→ at least 1-byte on data on SI→ CS# goes high.

The CS# must be kept low during the whole Page Program cycle; The CS# must go high exactly at the byte boundary (the latest eighth bit of data being latched in), otherwise the instruction will be rejected and will not be executed.

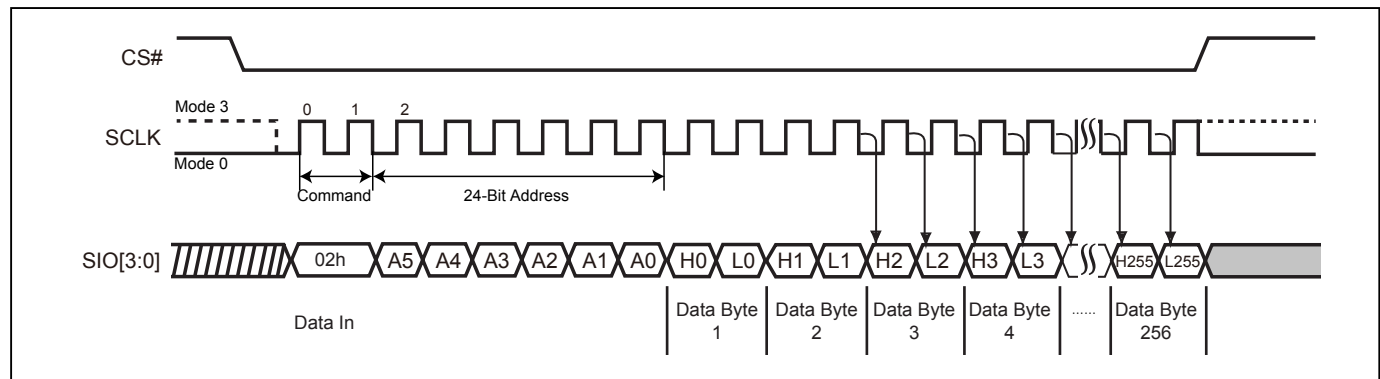
The self-timed Page Program Cycle time (tPP) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be checked during the Page Program cycle is in progress. The WIP sets 1 during the tPP timing, and sets 0 when Page Program Cycle is completed, and the Write Enable Latch (WEL) bit is reset. If the page is protected by BP3, BP2, BP1, BP0 bits, the Page Program (PP) instruction will not be executed.

Both SPI (8 clocks) and QPI (2 clocks) command cycle can accept by this instruction. The SIO[3:1] are "don't care" in SPI mode.

**Figure 45. Page Program (PP) Sequence (SPI Mode)**



**Figure 46. Page Program (PP) Sequence (QPI Mode)**

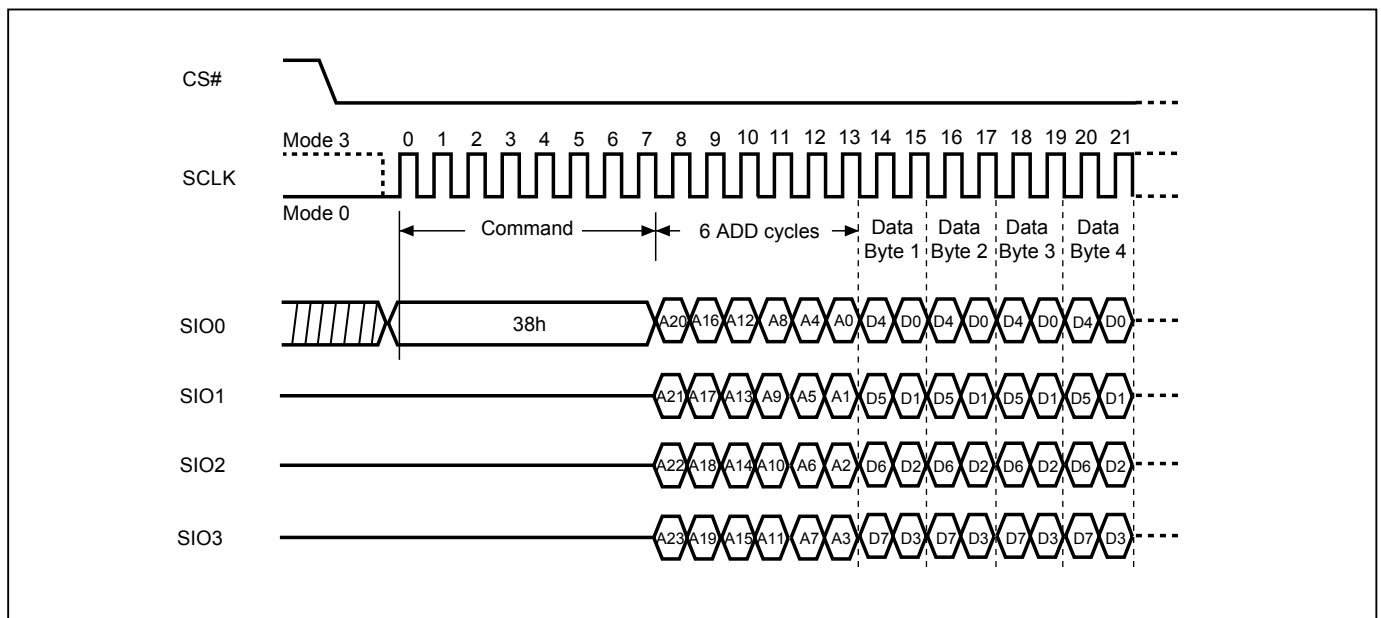


## 9-22. 4 x I/O Page Program (4PP)

The Quad Page Program (4PP) instruction is for programming the memory to be "0". A Write Enable (WREN) instruction must execute to set the Write Enable Latch (WEL) bit and Quad Enable (QE) bit must be set to "1" before sending the Quad Page Program (4PP). The Quad Page Programming takes four pins: SIO0, SIO1, SIO2, and SIO3 as address and data input, which can improve programmer performance and the effectiveness of application. The 4PP operation frequency supports as fast as Max. fSCLK. The other function descriptions are as same as standard page program.

The sequence of issuing 4PP instruction is: CS# goes low→ sending 4PP instruction code→ 3-byte address on SIO[3:0]→ at least 1-byte on data on SIO[3:0]→CS# goes high.

**Figure 47. 4 x I/O Page Program (4PP) Sequence (SPI Mode only)**



### 9-23. Deep Power-down (DP)

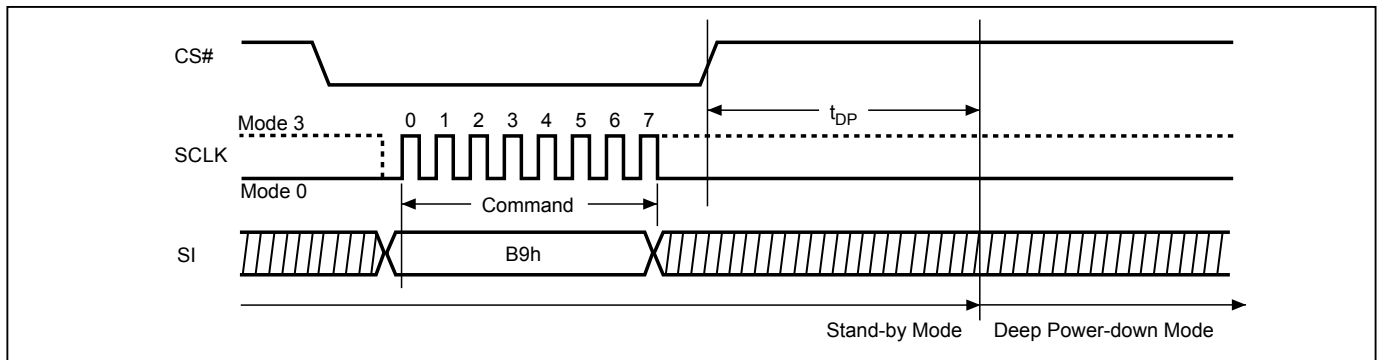
The Deep Power-down (DP) instruction places the device into a minimum power consumption state, Deep Power-down mode, in which the quiescent current is reduced from ISB1 to ISB2.

The sequence of issuing DP instruction: CS# goes low→ send DP instruction code→ CS# goes high. The CS# must go high at the byte boundary (after exactly eighth bits of the instruction code have been latched-in); otherwise the instruction will not be executed. Both SPI (8 clocks) and QPI (2 clocks) command cycle can be accepted by this instruction. SIO[3:1] are "don't care".

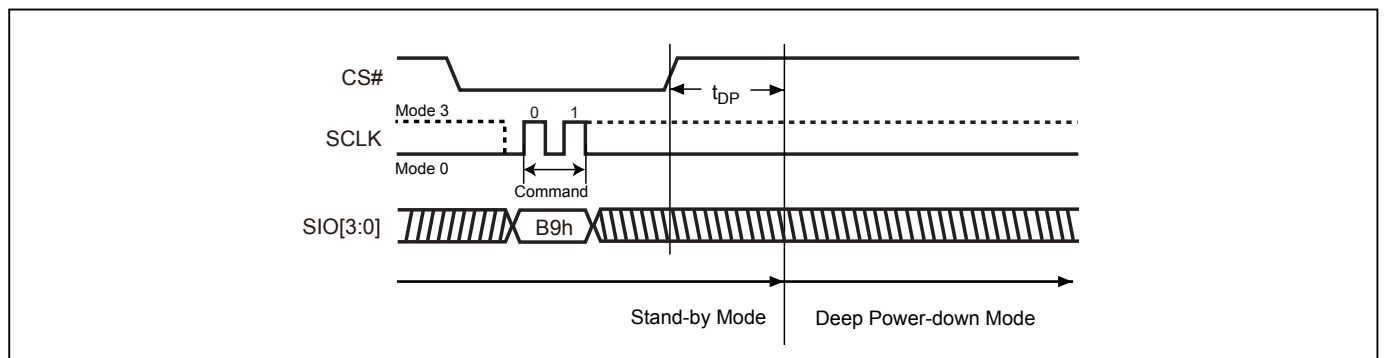
After CS# goes high there is a delay of  $t_{DP}$  before the device transitions from Stand-by mode to Deep Power-down mode and before the current reduces from ISB1 to ISB2. Once in Deep Power-down mode, all instructions will be ignored except Release from Deep Power-down (RDP).

The device exits Deep Power-down mode and returns to Stand-by mode if it receives a Release from Deep Power-down (RDP) instruction, power-cycle, or reset.

**Figure 48. Deep Power-down (DP) Sequence (SPI Mode)**



**Figure 49. Deep Power-down (DP) Sequence (QPI Mode)**



**9-24. Enter Secured OTP (ENSO)**

The ENSO instruction is for entering the additional 4K-bit secured OTP mode. The additional 4K-bit secured OTP is independent from main array, which may use to store unique serial number for system identifier. After entering the Secured OTP mode, and then follow standard read or program procedure to read out the data or update data. The Secured OTP data cannot be updated again once it is lock-down.

The sequence of issuing ENSO instruction is: CS# goes low→ sending ENSO instruction to enter Secured OTP mode→ CS# goes high.

Both SPI (8 clocks) and QPI (2 clocks) command cycle can accept by this instruction. The SIO[3:1] are "don't care" in SPI mode.

Please note that WRSR/WRSCUR commands are not acceptable during the access of secure OTP region, once security OTP is lock down, only read related commands are valid.

**9-25. Exit Secured OTP (EXSO)**

The EXSO instruction is for exiting the additional 4K-bit secured OTP mode.

The sequence of issuing EXSO instruction is: CS# goes low→ sending EXSO instruction to exit Secured OTP mode→ CS# goes high.

Both SPI (8 clocks) and QPI (2 clocks) command cycle can accept by this instruction. The SIO[3:1] are "don't care" in SPI mode.

**9-26. Read Security Register (RDSCUR)**

The RDSCUR instruction is for reading the value of Security Register bits. The Read Security Register can be read at any time (even in program/erase/write status register/write security register condition) and continuously.

The sequence of issuing RDSCUR instruction is : CS# goes low→sending RDSCUR instruction→Security Register data out on SO→ CS# goes high.

Both SPI (8 clocks) and QPI (2 clocks) command cycle can accept by this instruction. The SIO[3:1] are "don't care" in SPI mode.

The definition of the Security Register bits is as below:

**Secured OTP Indicator bit.** The Secured OTP indicator bit shows the Secured OTP area is locked by factory before ex- factory or not. When it is "0", it indicates non-factory lock; "1" indicates factory-lock.

**Lock-down Secured OTP (LDSO) bit.** By writing WRSCUR instruction, the LDSO bit may be set to "1" for customer lock-down purpose. However, once the bit is set to "1" (lock-down), the LDSO bit and the 4K-bit Secured OTP area cannot be update any more. While it is in 4K-bit secured OTP mode, main array access is not allowed.

**Table 9. Security Register Definition**

| bit7                                                                                     | bit6                                                                      | bit5                                                                             | bit4         | bit3                                                                   | bit2                                                                       | bit1                                                                           | bit0                                               |
|------------------------------------------------------------------------------------------|---------------------------------------------------------------------------|----------------------------------------------------------------------------------|--------------|------------------------------------------------------------------------|----------------------------------------------------------------------------|--------------------------------------------------------------------------------|----------------------------------------------------|
| WPSEL                                                                                    | E_FAIL                                                                    | P_FAIL                                                                           | Reserved     | ESB<br>(Erase<br>Suspend bit)                                          | PSB<br>(Program<br>Suspend bit)                                            | LDSO<br>(indicate if<br>lock-down)                                             | Secured OTP<br>indicator bit                       |
| 0=BP<br>protection<br>mode<br>1=Individual<br>Block<br>Protection<br>mode<br>(default=0) | 0=normal<br>Erase<br>succeed<br>1=indicate<br>Erase failed<br>(default=0) | 0=normal<br>Program<br>succeed<br>1=indicate<br>Program<br>failed<br>(default=0) | -            | 0=Erase<br>is not<br>suspended<br>1= Erase<br>suspended<br>(default=0) | 0=Program<br>is not<br>suspended<br>1= Program<br>suspended<br>(default=0) | 0 = not lock-<br>down<br>1 = lock-down<br>(cannot<br>program/<br>erase<br>OTP) | 0 = non-<br>factory<br>lock<br>1 = factory<br>lock |
| Non-volatile<br>bit (OTP)                                                                | Volatile bit                                                              | Volatile bit                                                                     | Volatile bit | Volatile bit                                                           | Volatile bit                                                               | Non-volatile<br>bit<br>(OTP)                                                   | Non-volatile<br>bit (OTP)                          |

## 9-27. Write Security Register (WRSCUR)

The WRSCUR instruction is for changing the values of Security Register Bits. The WREN (Write Enable) instruction is required before issuing WRSCUR instruction. The WRSCUR instruction may change the values of bit1 (LDSO bit) for customer to lock-down the 4K-bit Secured OTP area. Once the LDSO bit is set to "1", the Secured OTP area cannot be updated any more.

The sequence of issuing WRSCUR instruction is: CS# goes low → sending WRSCUR instruction → CS# goes high.

Both SPI (8 clocks) and QPI (2 clocks) command cycle can accept by this instruction. The SIO[3:1] are "don't care" in SPI mode.

The CS# must go high exactly at the boundary; otherwise, the instruction will be rejected and not executed.

## 9-28. Write Protection Selection (WPSEL)

There are two write protection methods provided on this device, (1) Block Protection (BP) mode or (2) Individual Block Protection mode. The protection modes are mutually exclusive. The WPSEL bit selects which protection mode is enabled. If WPSEL=0 (factory default), BP mode is enabled and Individual block protection mode is disabled. If WPSEL=1, Individual Block Protection mode is enabled and BP mode is disabled. The WPSEL command is used to set WPSEL=1. A WREN command must be executed to set the WEL bit before sending the WPSEL command. Please note that the WPSEL bit is an OTP bit. Once WPSEL is set to "1", it cannot be programmed back to "0".

When WPSEL = 0: Block Lock (BP) Protection mode,

The memory array is write protected by the BP3~BP0 bits.

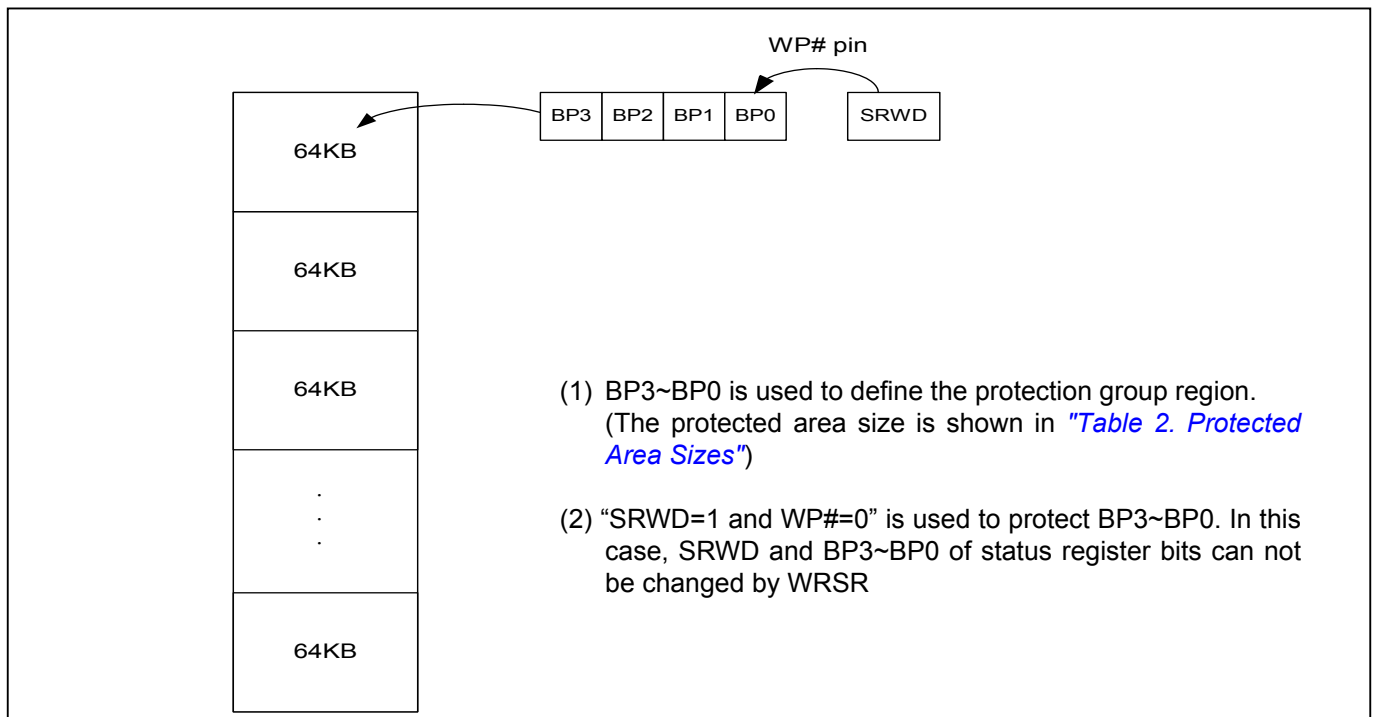
When WPSEL = 1: Individual Block Protection mode,

Blocks are individually protected by their own SRAM lock bits. On power-up, SBULK and SBLK command can set SRAM lock bit to "0" and "1". The Individual Block Protection instructions SBLK, SBULK, RDBLOCK, GBLK, and GBULK are activated. The BP3~BP0 bits of the Status Register are disabled and have no effect. Hardware protection is performed by driving WP#=0. Once WP#=0 all blocks and sectors are write protected regardless of the state of each SRAM lock bit.

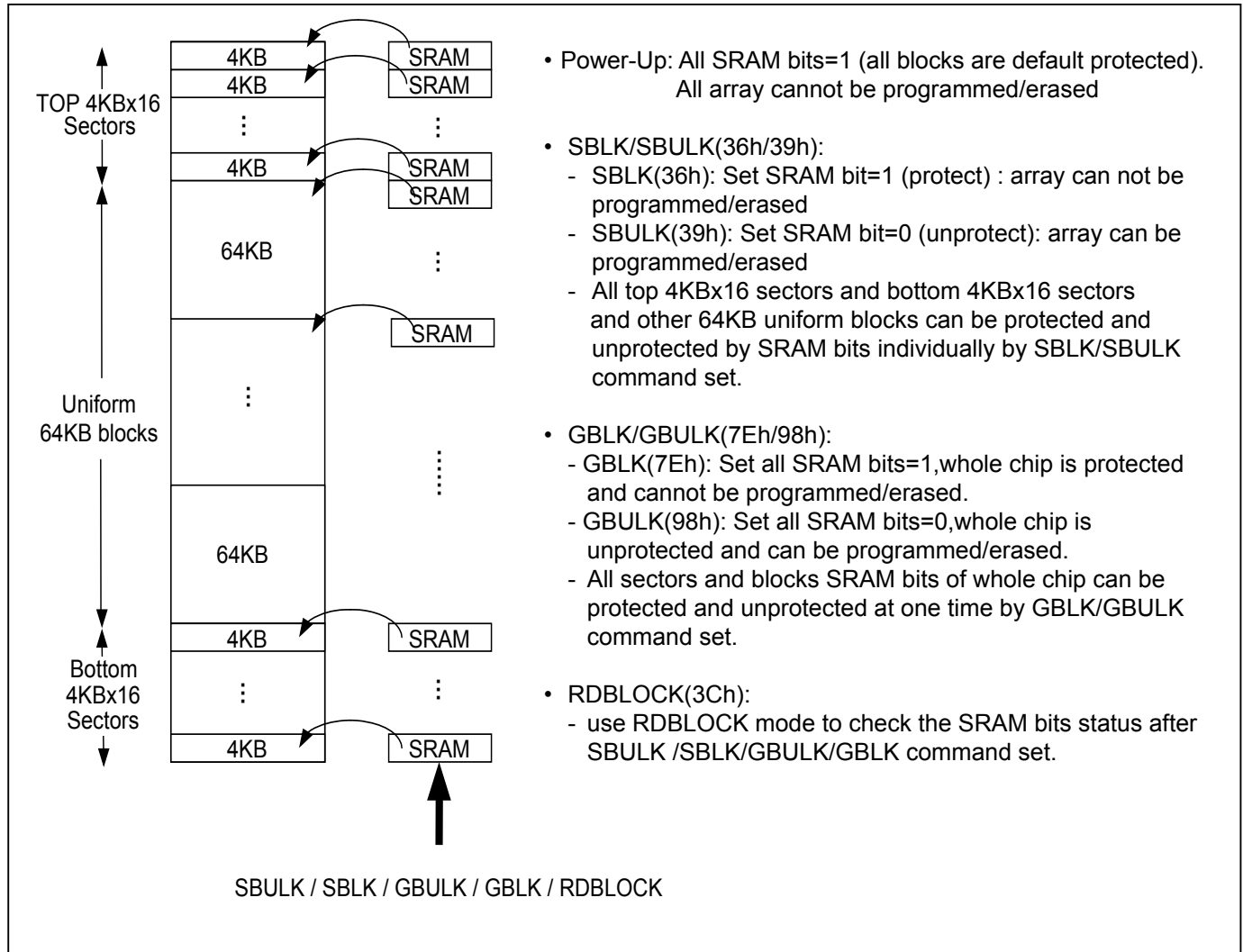
The sequence of issuing WPSEL instruction is: CS# goes low → send WPSEL instruction to enable the Individual block Protect mode → CS# goes high.

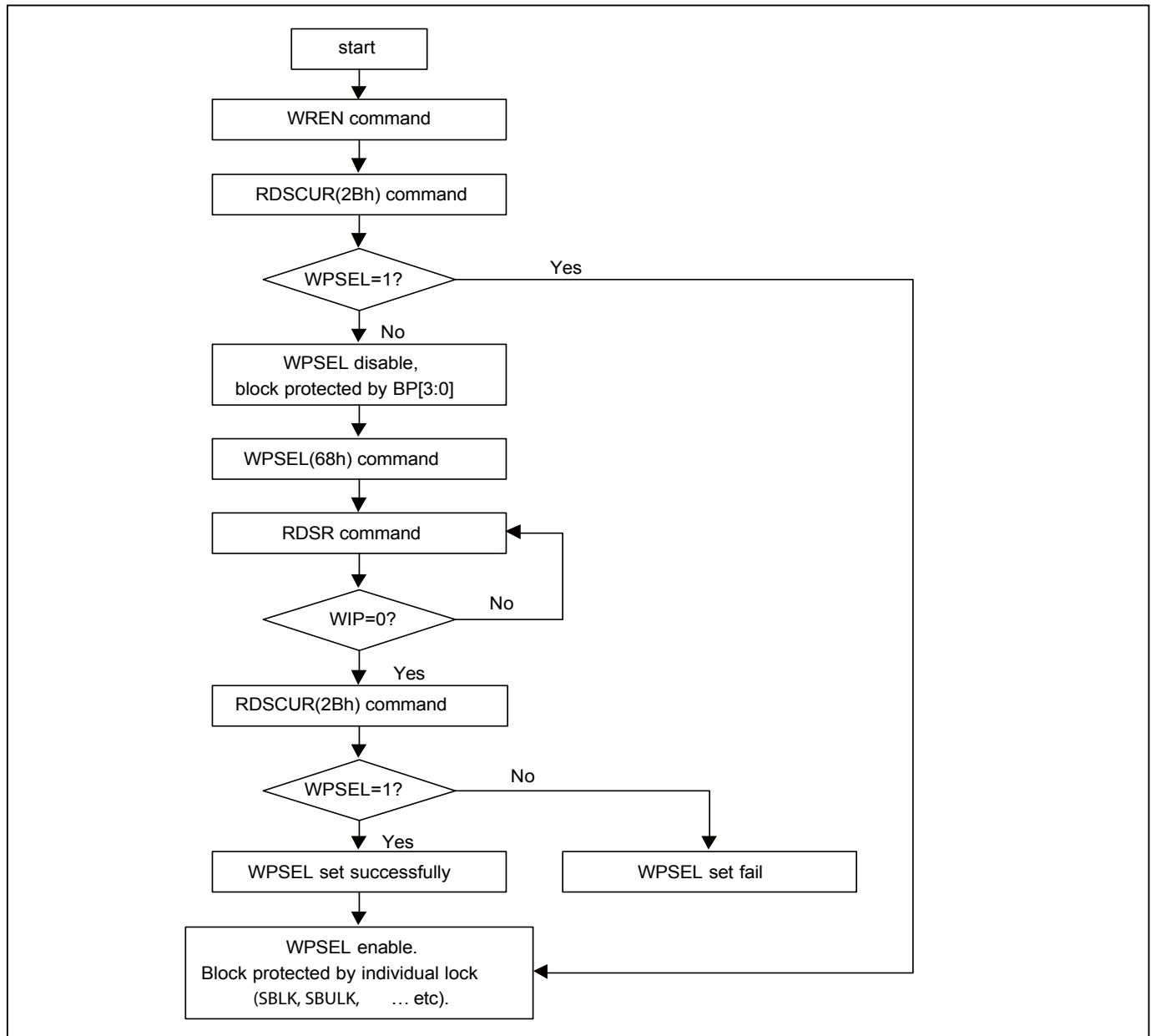
WPSEL instruction function flow is as follows:

**Figure 50. BP and SRWD if WPSEL=0**



**The individual block lock mode is effective after setting WPSEL=1**



**Figure 51. WPSEL Flow**

## 9-29. Single Block Lock/Unlock Protection (SBLK/SBULK)

These instructions are only effective after WPSEL was executed. The SBLK instruction is for write protection a specified block (or sector) of memory, using  $A_{MAX}-A16$  or ( $A_{MAX}-A12$ ) address bits to assign a 64Kbyte block (or 4K bytes sector) to be protected as read only. The SBULK instruction will cancel the block (or sector) write protection state. This feature allows user to stop protecting the entire block (or sector) through the chip unprotect command (GBULK).

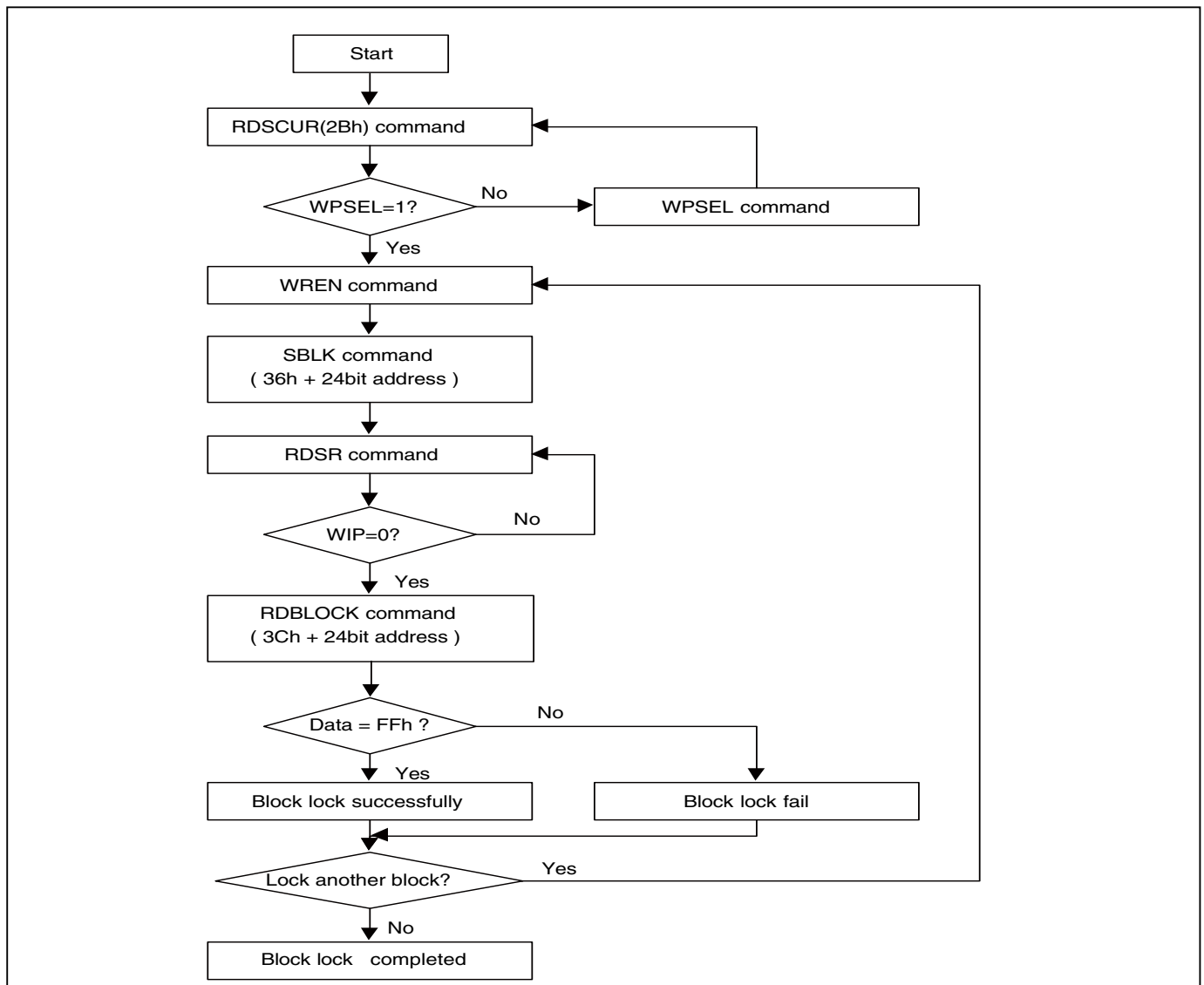
The WREN (Write Enable) instruction is required before issuing SBLK/SBULK instruction.

The sequence of issuing SBLK/SBULK instruction is: CS# goes low → send SBLK/SBULK (36h/39h) instruction → send 3-byte address assign one block (or sector) to be protected on SI pin → CS# goes high. The CS# must go high exactly at the byte boundary, otherwise the instruction will be rejected and not be executed.

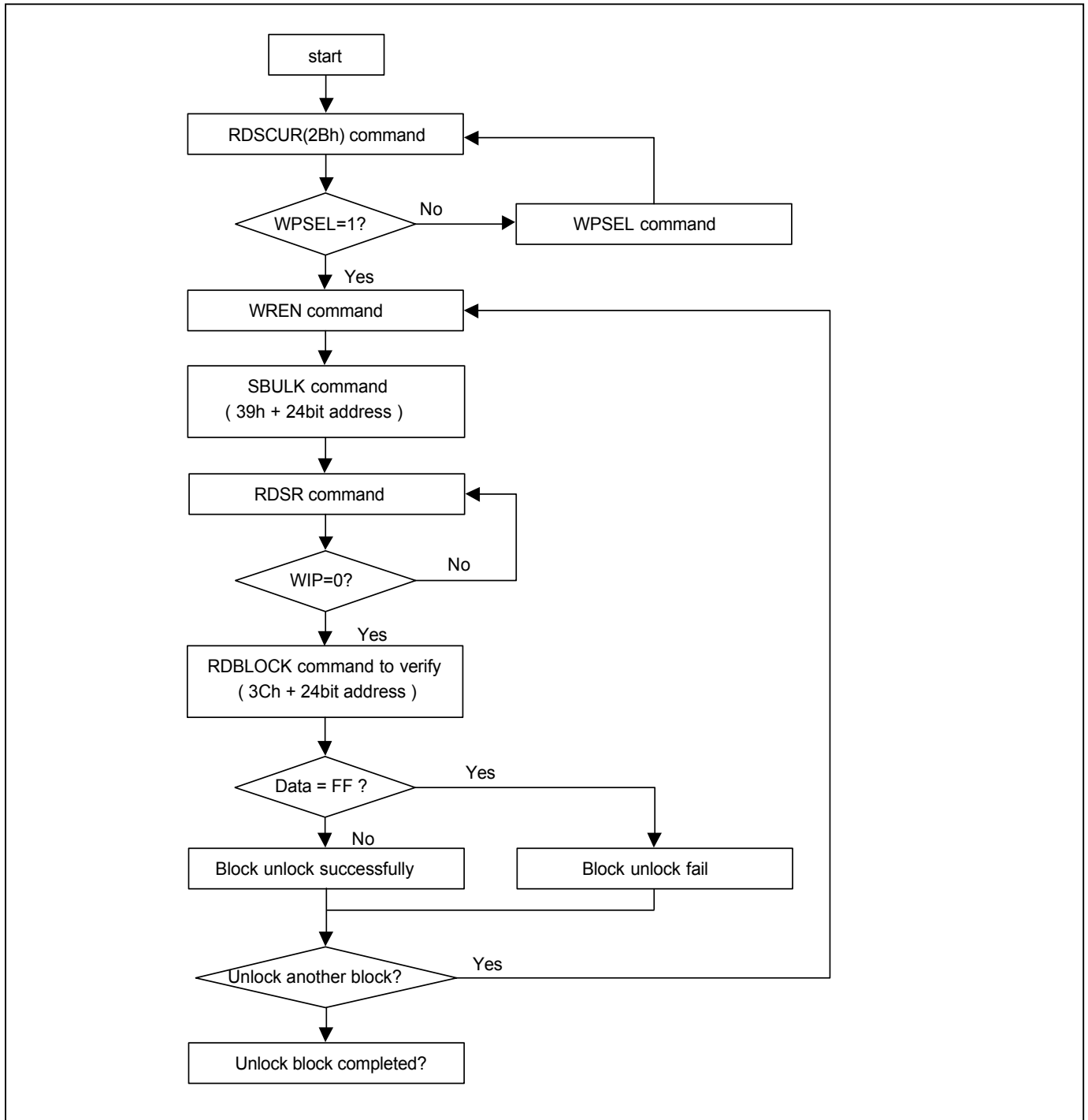
Both SPI (8 clocks) and QPI (2 clocks) command cycle can accept by this instruction. The SIO[3:1] are "don't care" in SPI mode.

SBLK/SBULK instruction function flow is as follows:

**Figure 52. Block Lock Flow**



**Figure 53. Block Unlock Flow**



**9-30. Read Block Lock Status (RDBLOCK)**

This instruction is only effective after WPSEL was executed. The RDBLOCK instruction is for reading the status of protection lock of a specified block (or sector), using  $A_{MAX}$ -A16 (or  $A_{MAX}$ -A12) address bits to assign a 64K bytes block (4K bytes sector) and read protection lock status bit which the first byte of Read-out cycle. The status bit is "1" to indicate that this block has been protected, that user can read only but cannot write/program/erase this block. The status bit is "0" to indicate that this block hasn't been protected, and user can read and write this block.

The sequence of issuing RDBLOCK instruction is: CS# goes low → send RDBLOCK (3Ch) instruction → send 3-byte address to assign one block on SI pin → read block's protection lock status bit on SO pin → CS# goes high.

Both SPI (8 clocks) and QPI (2 clocks) command cycle can accept by this instruction. The SIO[3:1] are "don't care" in SPI mode.

**9-31. Gang Block Lock/Unlock (GBLK/GBULK)**

These instructions are only effective after WPSEL was executed. The GBLK/GBULK instruction is for enable/disable the lock protection block of the whole chip.

The WREN (Write Enable) instruction is required before issuing GBLK/GBULK instruction.

The sequence of issuing GBLK/GBULK instruction is: CS# goes low → send GBLK/GBULK (7Eh/98h) instruction → CS# goes high.

Both SPI (8 clocks) and QPI (2 clocks) command cycle can accept by this instruction. The SIO[3:1] are "don't care" in SPI mode.

The CS# must go high exactly at the byte boundary, otherwise, the instruction will be rejected and not be executed.

### 9-32. Program Suspend and Erase Suspend

The Suspend instruction interrupts a Page Program, Sector Erase, or Block Erase operation to allow access to the memory array. After the program or erase operation has entered the suspended state, the memory array can be read except for the page being programmed or the sector or block being erased (*"Table 10. Readable Area of Memory While a Program or Erase Operation is Suspended"*).

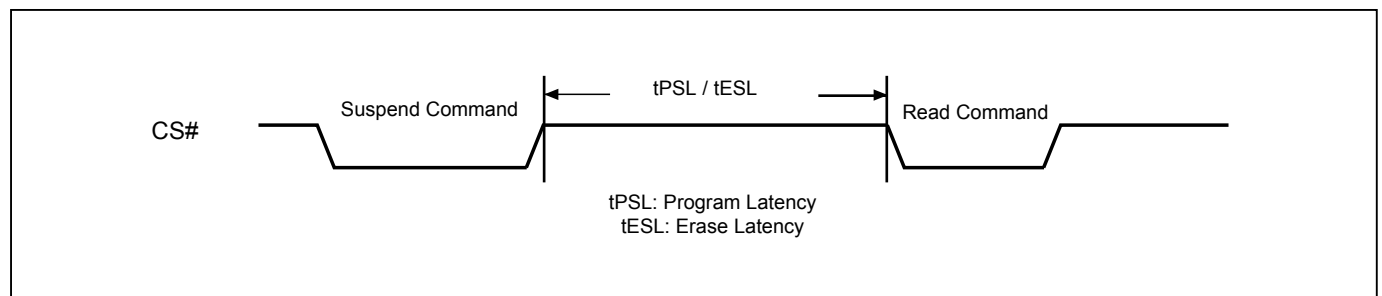
**Table 10. Readable Area of Memory While a Program or Erase Operation is Suspended**

| Suspended Operation | Readable Region of Memory Array     |
|---------------------|-------------------------------------|
| Page Program        | All but the Page being programmed   |
| Sector Erase (4KB)  | All but the 4KB Sector being erased |
| Block Erase (32KB)  | All but the 32KB Block being erased |
| Block Erase (64KB)  | All but the 64KB Block being erased |

When the Serial NOR Flash receives the Suspend instruction, there is a latency of tPSL or tESL (*"Figure 54. Suspend to Read Latency"*) before the Write Enable Latch (WEL) bit clears to "0" and the PSB or ESB sets to "1", after which the device is ready to accept one of the commands listed in *"Table 11. Acceptable Commands During Suspend after tPSL/tESL"* (e.g. FAST READ). Refer to *"Table 20. AC Characteristics"* for tPSL and tESL timings. *"Table 12. Acceptable Commands During Suspend (tPSL/tESL not required)"* lists the commands for which the tPSL and tESL latencies do not apply. For example, RDSR, RDSCUR, RSTEN, and RST can be issued at any time after the Suspend instruction.

Security Register bit 2 (PSB) and bit 3 (ESB) can be read to check the suspend status. The PSB (Program Suspend Bit) sets to "1" when a program operation is suspended. The ESB (Erase Suspend Bit) sets to "1" when an erase operation is suspended. The PSB or ESB clears to "0" when the program or erase operation is resumed.

**Figure 54. Suspend to Read Latency**



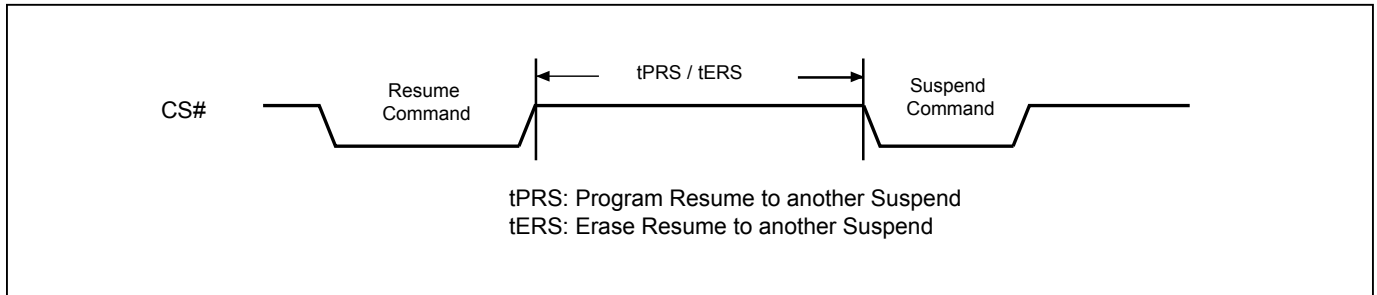
**Table 11. Acceptable Commands During Suspend after tPSL/tESL**

| Command Name | Command Code | Suspend Type    |               |
|--------------|--------------|-----------------|---------------|
|              |              | Program Suspend | Erase Suspend |
| READ         | 03h          | •               | •             |
| FAST READ    | 0Bh          | •               | •             |
| DREAD        | 3Bh          | •               | •             |
| QREAD        | 6Bh          | •               | •             |
| 2READ        | BBh          | •               | •             |
| 4READ        | EBh          | •               | •             |
| W4READ       | E7h          | •               | •             |
| RDSFDP       | 5Ah          | •               | •             |
| RDID         | 9Fh          | •               | •             |
| RDBLOCK      | 3Ch          | •               | •             |
| REMS         | 90h          | •               | •             |
| ENSO         | B1h          | •               | •             |
| EXSO         | C1h          | •               | •             |
| SBL          | C0h          | •               | •             |
| WREN         | 06h          |                 | •             |
| RESUME       | 30h          | •               | •             |
| EQIO         | 35h          | •               | •             |
| RSTQIO       | F5h          | •               | •             |
| QPIID        | AFh          | •               | •             |
| PP           | 02h          |                 | •             |
| 4PP          | 38h          |                 | •             |

**Table 12. Acceptable Commands During Suspend (tPSL/tESL not required)**

| Command Name | Command Code | Suspend Type    |               |
|--------------|--------------|-----------------|---------------|
|              |              | Program Suspend | Erase Suspend |
| WRDI         | 04h          | •               | •             |
| RDSR         | 05h          | •               | •             |
| RDSCUR       | 2Bh          | •               | •             |
| RES          | ABh          | •               | •             |
| RSTEN        | 66h          | •               | •             |
| RST          | 99h          | •               | •             |
| NOP          | 00h          | •               | •             |

**Figure 55. Resume to Suspend Latency**

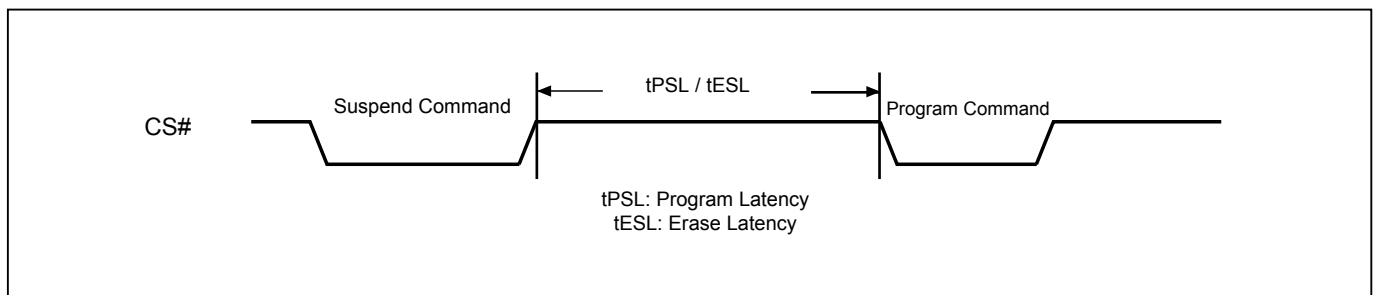


### 9-32-1. Suspend to Program

The “Erase Suspend to Program” feature allows Page Programming while an erase operation is suspended. Page Programming is permitted in any unprotected memory except within the sector of a suspended Sector Erase operation or within the block of a suspended Block Erase operation. The Write Enable (WREN) instruction must be issued before any Page Program instruction.

A Page Program operation initiated within a suspended erase cannot itself be suspended and must be allowed to finish before the suspended erase can be resumed. The Status Register can be polled to determine the status of the Page Program operation. The WEL and WIP bits of the Status Register will remain “1” while the Page Program operation is in progress and will both clear to “0” when the Page Program operation completes.

**Figure 56. Suspend to Program Latency**



### 9-33. Program Resume and Erase Resume

The Resume instruction resumes a suspended Page Program, Sector Erase, or Block Erase operation. Before issuing the Resume instruction to restart a suspended erase operation, make sure that there is no Page Program operation in progress.

Immediately after the Serial NOR Flash receives the Resume instruction, the WEL and WIP bits are set to “1” and the PSB or ESB is cleared to “0”. The program or erase operation will continue until finished (*“Figure 57. Resume to Read Latency”*) or until another Suspend instruction is received. A resume-to-suspend latency of  $t_{PRS}$  or  $t_{ERS}$  must be observed before issuing another Suspend instruction (*“Figure 55. Resume to Suspend Latency”*).

Please note that the Resume instruction will be ignored if the Serial NOR Flash is in “Performance Enhance Mode”. Make sure the Serial NOR Flash is not in “Performance Enhance Mode” before issuing the Resume instruction.

**Figure 57. Resume to Read Latency**



#### **9-34. No Operation (NOP)**

The "No Operation" command is only able to terminate the Reset Enable (RSTEN) command and will not affect any other command.

Both SPI (8 clocks) and QPI (2 clocks) command cycle can accept by this instruction. The SIO[3:1] are don't care when during SPI mode.

#### **9-35. Software Reset (Reset-Enable (RSTEN) and Reset (RST))**

The Software Reset operation combines two instructions: Reset-Enable (RSTEN) command and Reset (RST) command. It returns the device to a standby mode. All the volatile bits and settings will be cleared then, which makes the device return to the default status as power on.

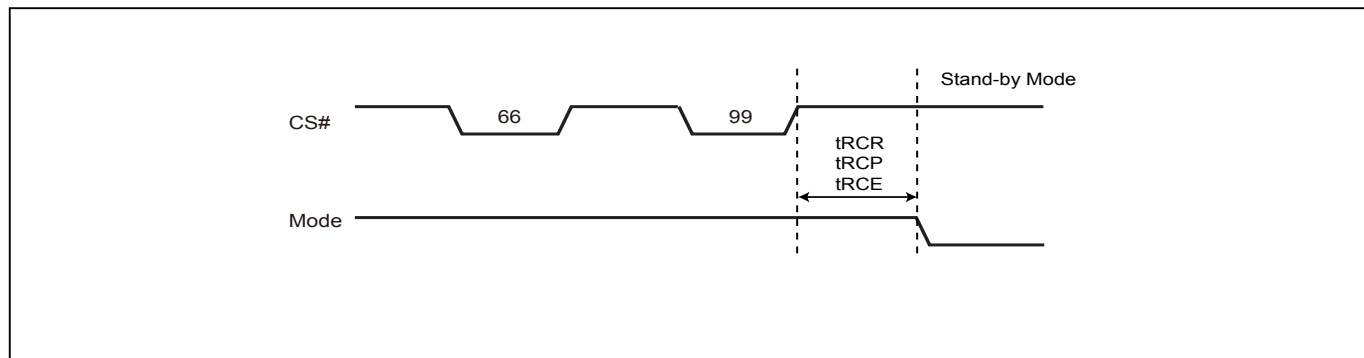
To execute Reset command (RST), the Reset-Enable (RSTEN) command must be executed first to perform the Reset operation. If there is any other command to interrupt after the Reset-Enable command, the Reset-Enable will be invalid.

Both SPI (8 clocks) and QPI (2 clocks) command cycle can accept by this instruction. The SIO[3:1] are "don't care" in SPI mode.

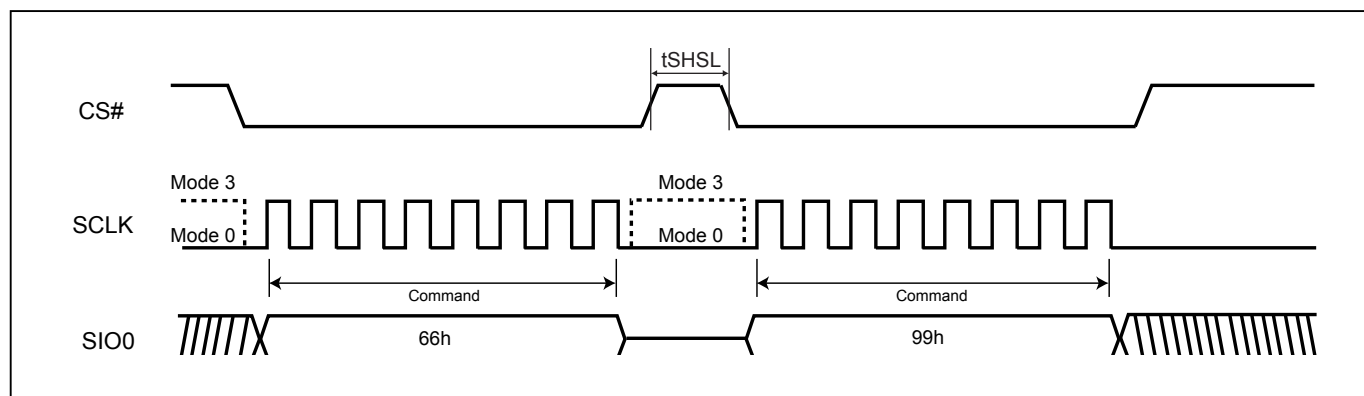
If the Reset command is executed during program or erase operation, the operation will be disabled, the data under processing could be damaged or lost.

The reset time is different depending on the last operation. Longer latency time is required to recover from a program operation than from other operations.

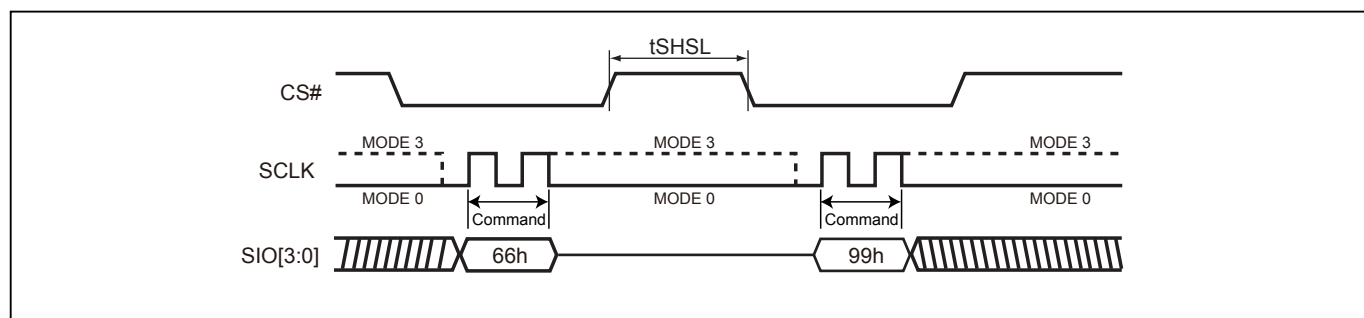
**Figure 58. Software Reset Recovery**



**Figure 59. Reset Sequence (SPI mode)**



**Figure 60. Reset Sequence (QPI mode)**



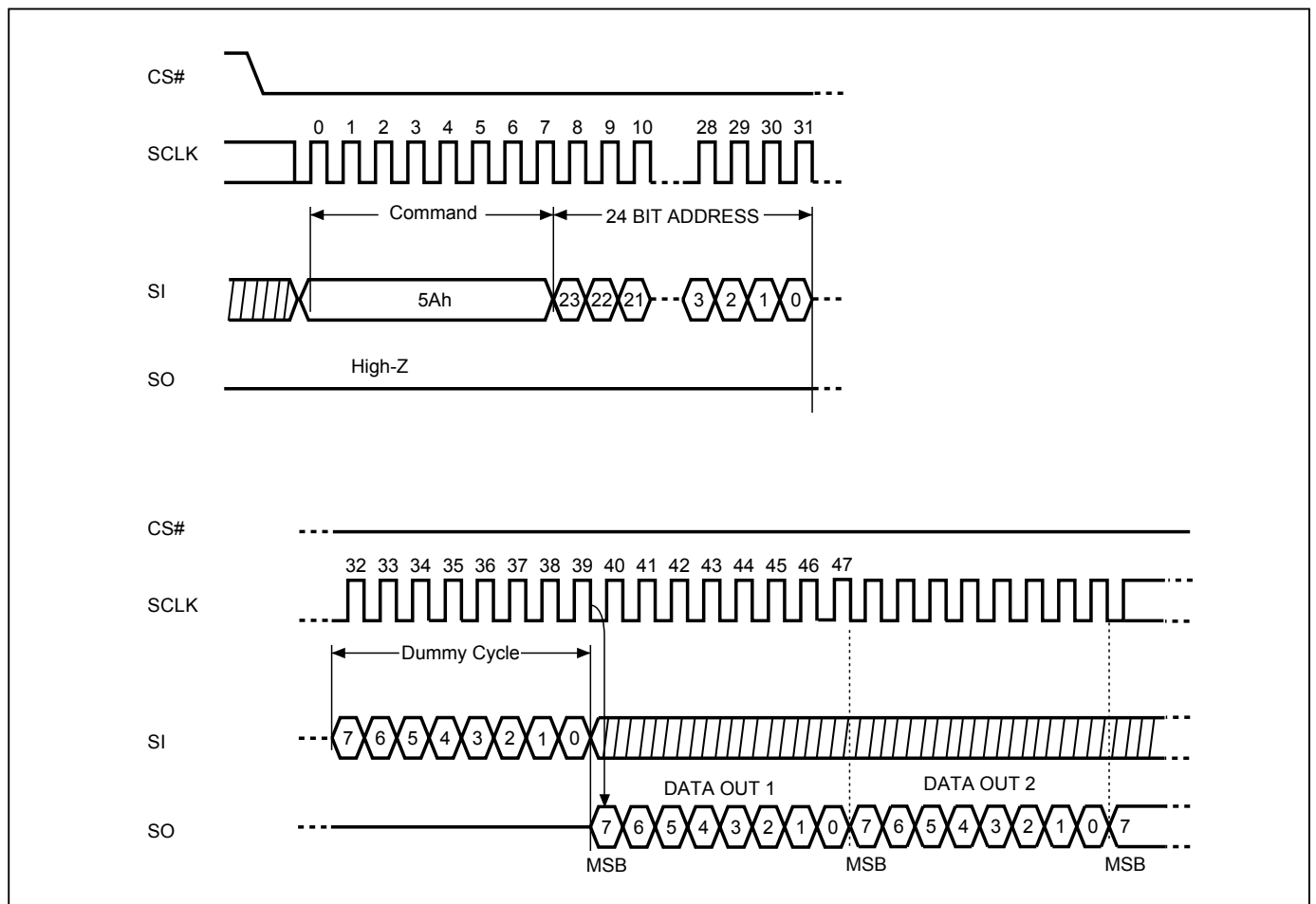
### 9-36. Read SFDP Mode (RDSFDP)

The Serial Flash Discoverable Parameter (SFDP) standard provides a consistent method of describing the functional and feature capabilities of serial flash devices in a standard set of internal parameter tables. These parameter tables can be interrogated by host system software to enable adjustments needed to accommodate divergent features from multiple vendors. The concept is similar to the one found in the Introduction of JEDEC Standard, JESD68 on CFI.

The sequence of issuing RDSFDP instruction is same as FAST\_READ: CS# goes low→send RDSFDP instruction (5Ah)→send 3 address bytes on SI pin→send 1 dummy byte on SI pin→read SFDP code on SO→to end RDSFDP operation can use CS# to high at any time during data out.

SFDP is a JEDEC Standard, JESD216.

**Figure 61. Read Serial Flash Discoverable Parameter (RDSFDP) Sequence**



**Table 13. Signature and Parameter Identification Data Values**

SFDP Table below is for MX25U3235FBAI-10G, MX25U3235FM2I-10G, MX25U3235FZNI-10G, MX25U3235FZBI-10G and MX25U3235FZCI-10G

| Description                                | Comment                                                            | Add (h)<br>(Byte) | DW Add<br>(Bit) | Data (h/b)<br>(Note1) | Data<br>(h) |
|--------------------------------------------|--------------------------------------------------------------------|-------------------|-----------------|-----------------------|-------------|
| SFDP Signature                             | Fixed: 50444653h                                                   | 00h               | 07:00           | 53h                   | 53h         |
|                                            |                                                                    | 01h               | 15:08           | 46h                   | 46h         |
|                                            |                                                                    | 02h               | 23:16           | 44h                   | 44h         |
|                                            |                                                                    | 03h               | 31:24           | 50h                   | 50h         |
| SFDP Minor Revision Number                 | Start from 00h                                                     | 04h               | 07:00           | 00h                   | 00h         |
| SFDP Major Revision Number                 | Start from 01h                                                     | 05h               | 15:08           | 01h                   | 01h         |
| Number of Parameter Headers                | This number is 0-based. Therefore, 0 indicates 1 parameter header. | 06h               | 23:16           | 01h                   | 01h         |
| Unused                                     |                                                                    | 07h               | 31:24           | FFh                   | FFh         |
| ID number (JEDEC)                          | 00h: it indicates a JEDEC specified header.                        | 08h               | 07:00           | 00h                   | 00h         |
| Parameter Table Minor Revision Number      | Start from 00h                                                     | 09h               | 15:08           | 00h                   | 00h         |
| Parameter Table Major Revision Number      | Start from 01h                                                     | 0Ah               | 23:16           | 01h                   | 01h         |
| Parameter Table Length<br>(in double word) | How many DWORDs in the Parameter table                             | 0Bh               | 31:24           | 09h                   | 09h         |
| Parameter Table Pointer (PTP)              | First address of JEDEC Flash Parameter table                       | 0Ch               | 07:00           | 30h                   | 30h         |
|                                            |                                                                    | 0Dh               | 15:08           | 00h                   | 00h         |
|                                            |                                                                    | 0Eh               | 23:16           | 00h                   | 00h         |
| Unused                                     |                                                                    | 0Fh               | 31:24           | FFh                   | FFh         |
| ID number<br>(Macronix manufacturer ID)    | it indicates Macronix manufacturer ID                              | 10h               | 07:00           | C2h                   | C2h         |
| Parameter Table Minor Revision Number      | Start from 00h                                                     | 11h               | 15:08           | 00h                   | 00h         |
| Parameter Table Major Revision Number      | Start from 01h                                                     | 12h               | 23:16           | 01h                   | 01h         |
| Parameter Table Length<br>(in double word) | How many DWORDs in the Parameter table                             | 13h               | 31:24           | 04h                   | 04h         |
| Parameter Table Pointer (PTP)              | First address of Macronix Flash Parameter table                    | 14h               | 07:00           | 60h                   | 60h         |
|                                            |                                                                    | 15h               | 15:08           | 00h                   | 00h         |
|                                            |                                                                    | 16h               | 23:16           | 00h                   | 00h         |
| Unused                                     |                                                                    | 17h               | 31:24           | FFh                   | FFh         |

**Table 14. Parameter Table (0): JEDEC Flash Parameter Tables**

SFDP Table below is for MX25U3235FBAI-10G, MX25U3235FM2I-10G, MX25U3235FZNI-10G, MX25U3235FZBI-10G and MX25U3235FZCI-10G

| Description                                                                      | Comment                                                                                                                                      | Add (h)<br>(Byte) | DW Add<br>(Bit) | Data (h/b)<br>(Note1) | Data<br>(h) |
|----------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------|-------------------|-----------------|-----------------------|-------------|
| Block/Sector Erase sizes                                                         | 00: Reserved, 01: 4KB erase,<br>10: Reserved,<br>11: not support 4KB erase                                                                   | 30h               | 01:00           | 01b                   | E5h         |
| Write Granularity                                                                | 0: 1Byte, 1: 64Byte or larger                                                                                                                |                   | 02              | 1b                    |             |
| Write Enable Instruction Required<br>for Writing to Volatile Status<br>Registers | 0: not required<br>1: required 00h to be written to the<br>status register                                                                   |                   | 03              | 0b                    |             |
| Write Enable Opcode Select for<br>Writing to Volatile Status Registers           | 0: use 50h opcode,<br>1: use 06h opcode<br>Note: If target flash status register is<br>nonvolatile, then bits 3 and 4 must<br>be set to 00b. |                   | 04              | 0b                    |             |
| Unused                                                                           | Contains 111b and can never be<br>changed                                                                                                    |                   | 07:05           | 111b                  |             |
| 4KB Erase Opcode                                                                 |                                                                                                                                              | 31h               | 15:08           | 20h                   | 20h         |
| (1-1-2) Fast Read (Note2)                                                        | 0=not support 1=support                                                                                                                      | 32h               | 16              | 1b                    | F1h         |
| Address Bytes Number used in<br>addressing flash array                           | 00: 3Byte only, 01: 3 or 4Byte,<br>10: 4Byte only, 11: Reserved                                                                              |                   | 18:17           | 00b                   |             |
| Double Transfer Rate (DTR)<br>Clocking                                           | 0=not support 1=support                                                                                                                      |                   | 19              | 0b                    |             |
| (1-2-2) Fast Read                                                                | 0=not support 1=support                                                                                                                      |                   | 20              | 1b                    |             |
| (1-4-4) Fast Read                                                                | 0=not support 1=support                                                                                                                      |                   | 21              | 1b                    |             |
| (1-1-4) Fast Read                                                                | 0=not support 1=support                                                                                                                      |                   | 22              | 1b                    |             |
| Unused                                                                           |                                                                                                                                              |                   | 23              | 1b                    |             |
| Unused                                                                           |                                                                                                                                              | 33h               | 31:24           | FFh                   | FFh         |
| Flash Memory Density                                                             |                                                                                                                                              | 37h:34h           | 31:00           | 01FF FFFFh            |             |
| (1-4-4) Fast Read Number of Wait<br>states (Note3)                               | 0 0000b: Wait states (Dummy<br>Clocks) not support                                                                                           | 38h               | 04:00           | 0 0100b               | 44h         |
| (1-4-4) Fast Read Number of<br>Mode Bits (Note4)                                 | 000b: Mode Bits not support                                                                                                                  |                   | 07:05           | 010b                  |             |
| (1-4-4) Fast Read Opcode                                                         |                                                                                                                                              | 39h               | 15:08           | EBh                   | EBh         |
| (1-1-4) Fast Read Number of Wait<br>states                                       | 0 0000b: Wait states (Dummy<br>Clocks) not support                                                                                           | 3Ah               | 20:16           | 0 1000b               | 08h         |
| (1-1-4) Fast Read Number of<br>Mode Bits                                         | 000b: Mode Bits not support                                                                                                                  |                   | 23:21           | 000b                  |             |
| (1-1-4) Fast Read Opcode                                                         |                                                                                                                                              | 3Bh               | 31:24           | 6Bh                   | 6Bh         |

SFDP Table below is for MX25U3235FBAI-10G, MX25U3235FM2I-10G, MX25U3235FZNI-10G, MX25U3235FZBI-10G and MX25U3235FZCI-10G

| Description                             | Comment                                                                                   | Add (h)<br>(Byte) | DW Add<br>(Bit) | Data (h/b)<br>(Note1) | Data<br>(h) |
|-----------------------------------------|-------------------------------------------------------------------------------------------|-------------------|-----------------|-----------------------|-------------|
| (1-1-2) Fast Read Number of Wait states | 0 0000b: Wait states (Dummy Clocks) not support                                           | 3Ch               | 04:00           | 0 1000b               | 08h         |
| (1-1-2) Fast Read Number of Mode Bits   | 000b: Mode Bits not support                                                               |                   | 07:05           | 000b                  |             |
| (1-1-2) Fast Read Opcode                |                                                                                           | 3Dh               | 15:08           | 3Bh                   | 3Bh         |
| (1-2-2) Fast Read Number of Wait states | 0 0000b: Wait states (Dummy Clocks) not support                                           | 3Eh               | 20:16           | 0 0100b               | 04h         |
| (1-2-2) Fast Read Number of Mode Bits   | 000b: Mode Bits not support                                                               |                   | 23:21           | 000b                  |             |
| (1-2-2) Fast Read Opcode                |                                                                                           | 3Fh               | 31:24           | BBh                   | BBh         |
| (2-2-2) Fast Read                       | 0=not support 1=support                                                                   | 40h               | 00              | 0b                    | FEh         |
| Unused                                  |                                                                                           |                   | 03:01           | 111b                  |             |
| (4-4-4) Fast Read                       | 0=not support 1=support                                                                   |                   | 04              | 1b                    |             |
| Unused                                  |                                                                                           |                   | 07:05           | 111b                  |             |
| Unused                                  |                                                                                           | 43h:41h           | 31:08           | FFh                   | FFh         |
| Unused                                  |                                                                                           | 45h:44h           | 15:00           | FFh                   | FFh         |
| (2-2-2) Fast Read Number of Wait states | 0 0000b: Wait states (Dummy Clocks) not support                                           | 46h               | 20:16           | 0 0000b               | 00h         |
| (2-2-2) Fast Read Number of Mode Bits   | 000b: Mode Bits not support                                                               |                   | 23:21           | 000b                  |             |
| (2-2-2) Fast Read Opcode                |                                                                                           | 47h               | 31:24           | FFh                   | FFh         |
| Unused                                  |                                                                                           | 49h:48h           | 15:00           | FFh                   | FFh         |
| (4-4-4) Fast Read Number of Wait states | 0 0000b: Wait states (Dummy Clocks) not support                                           | 4Ah               | 20:16           | 0 0100b               | 44h         |
| (4-4-4) Fast Read Number of Mode Bits   | 000b: Mode Bits not support                                                               |                   | 23:21           | 010b                  |             |
| (4-4-4) Fast Read Opcode                |                                                                                           | 4Bh               | 31:24           | EBh                   | EBh         |
| Sector Type 1 Size                      | Sector/block size = 2 <sup>N</sup> bytes (Note5)<br>0x00b: this sector type doesn't exist | 4Ch               | 07:00           | 0Ch                   | 0Ch         |
| Sector Type 1 erase Opcode              |                                                                                           | 4Dh               | 15:08           | 20h                   | 20h         |
| Sector Type 2 Size                      | Sector/block size = 2 <sup>N</sup> bytes<br>0x00b: this sector type doesn't exist         | 4Eh               | 23:16           | 0Fh                   | 0Fh         |
| Sector Type 2 erase Opcode              |                                                                                           | 4Fh               | 31:24           | 52h                   | 52h         |
| Sector Type 3 Size                      | Sector/block size = 2 <sup>N</sup> bytes<br>0x00b: this sector type doesn't exist         | 50h               | 07:00           | 10h                   | 10h         |
| Sector Type 3 erase Opcode              |                                                                                           | 51h               | 15:08           | D8h                   | D8h         |
| Sector Type 4 Size                      | Sector/block size = 2 <sup>N</sup> bytes<br>0x00b: this sector type doesn't exist         | 52h               | 23:16           | 00h                   | 00h         |
| Sector Type 4 erase Opcode              |                                                                                           | 53h               | 31:24           | FFh                   | FFh         |

**Table 15. Parameter Table (1): Macronix Flash Parameter Tables**

SFDP Table below is for MX25U3235FBAI-10G, MX25U3235FM2I-10G, MX25U3235FZNI-10G, MX25U3235FZBI-10G and MX25U3235FZCI-10G

| Description                                                          | Comment                                                                               | Add (h)<br>(Byte) | DW Add<br>(Bit) | Data (h/b)<br>(Note1) | Data<br>(h) |
|----------------------------------------------------------------------|---------------------------------------------------------------------------------------|-------------------|-----------------|-----------------------|-------------|
| Vcc Supply Maximum Voltage                                           | 2000h=2.000V<br>2700h=2.700V<br>3600h=3.600V                                          | 61h:60h           | 07:00<br>15:08  | 00h<br>20h            | 00h<br>20h  |
| Vcc Supply Minimum Voltage                                           | 1650h=1.650V<br>2250h=2.250V<br>2350h=2.350V<br>2700h=2.700V                          | 63h:62h           | 23:16<br>31:24  | 50h<br>16h            | 50h<br>16h  |
| H/W Reset# pin                                                       | 0=not support 1=support                                                               | 65h:64h           | 00              | 1b                    | F99Dh       |
| H/W Hold# pin                                                        | 0=not support 1=support                                                               |                   | 01              | 0b                    |             |
| Deep Power Down Mode                                                 | 0=not support 1=support                                                               |                   | 02              | 1b                    |             |
| S/W Reset                                                            | 0=not support 1=support                                                               |                   | 03              | 1b                    |             |
| S/W Reset Opcode                                                     | Reset Enable (66h) should be issued before Reset Opcode                               |                   | 11:04           | 1001 1001b<br>(99h)   |             |
| Program Suspend/Resume                                               | 0=not support 1=support                                                               |                   | 12              | 1b                    |             |
| Erase Suspend/Resume                                                 | 0=not support 1=support                                                               |                   | 13              | 1b                    |             |
| Unused                                                               |                                                                                       |                   | 14              | 1b                    |             |
| Wrap-Around Read mode                                                | 0=not support 1=support                                                               |                   | 15              | 1b                    |             |
| Wrap-Around Read mode Opcode                                         |                                                                                       | 66h               | 23:16           | C0h                   | C0h         |
| Wrap-Around Read data length                                         | 08h:support 8B wrap-around read<br>16h:8B&16B<br>32h:8B&16B&32B<br>64h:8B&16B&32B&64B | 67h               | 31:24           | 64h                   | 64h         |
| Individual block lock                                                | 0=not support 1=support                                                               | 6Bh:68h           | 00              | 1b                    | C8D9h       |
| Individual block lock bit<br>(Volatile/Nonvolatile)                  | 0=Volatile 1=Nonvolatile                                                              |                   | 01              | 0b                    |             |
| Individual block lock Opcode                                         |                                                                                       |                   | 09:02           | 0011 0110b<br>(36h)   |             |
| Individual block lock Volatile<br>protect bit default protect status | 0=protect 1=unprotect                                                                 |                   | 10              | 0b                    |             |
| Secured OTP                                                          | 0=not support 1=support                                                               |                   | 11              | 1b                    |             |
| Read Lock                                                            | 0=not support 1=support                                                               |                   | 12              | 0b                    |             |
| Permanent Lock                                                       | 0=not support 1=support                                                               |                   | 13              | 0b                    |             |
| Unused                                                               |                                                                                       |                   | 15:14           | 11b                   |             |
| Unused                                                               |                                                                                       |                   | 31:16           | FFh                   | FFh         |
| Unused                                                               |                                                                                       | 6Fh:6Ch           | 31:00           | FFh                   | FFh         |

Note 1: h/b is hexadecimal or binary.

Note 2: **(x-y-z)** means I/O mode nomenclature used to indicate the number of active pins used for the opcode (x), address (y), and data (z). At the present time, the only valid Read SFDP instruction modes are: (1-1-1), (2-2-2), and (4-4-4)

Note 3: **Wait States** is required dummy clock cycles after the address bits or optional mode bits.

Note 4: **Mode Bits** is optional control bits that follow the address bits. These bits are driven by the system controller if they are specified. (eg, read performance enhance toggling bits)

Note 5: 4KB=2<sup>0Ch</sup>, 32KB=2<sup>0Fh</sup>, 64KB=2<sup>10h</sup>

Note 6: All unused and undefined area data is blank FFh for SFDP Tables that are defined in Parameter Identification Header. All other areas beyond defined SFDP Table are reserved by Macronix.

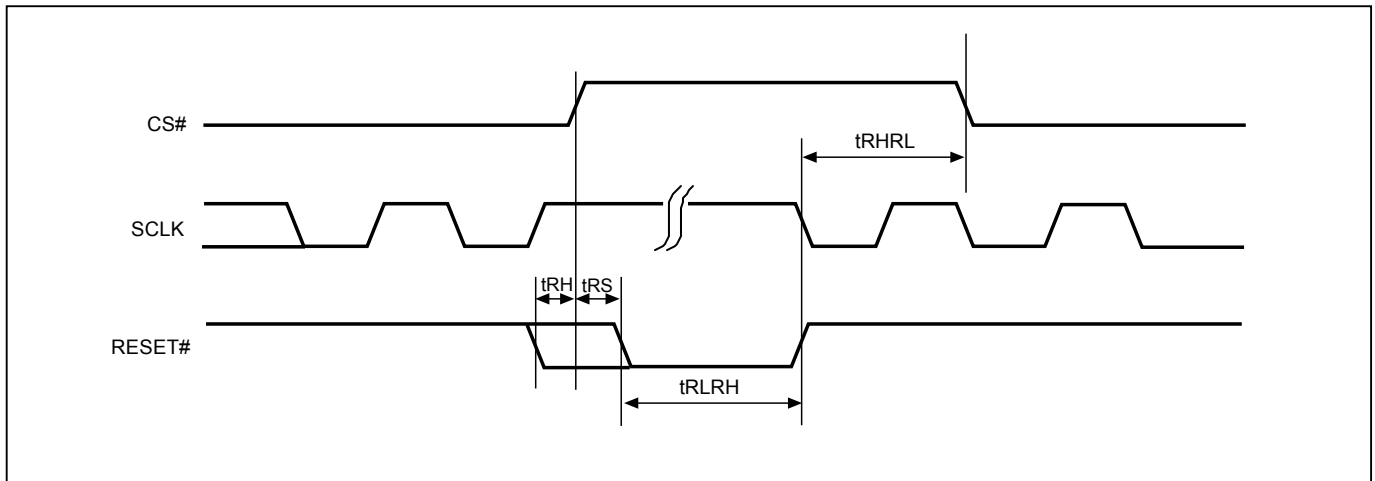
## 10. RESET

Driving the RESET# pin low for a period of tRLRH or longer will reset the device. After reset cycle, the device is at the following states:

- Standby mode
- All the volatile bits such as WEL/WIP/SRAM lock bit will return to the default status as power on.

If the device is under programming or erasing, driving the RESET# pin low will also terminate the operation and data could be lost. During the resetting cycle, the SO data becomes high impedance and the current will be reduced to minimum.

**Figure 62. RESET Timing**



**Table 16. Reset Timing**

| Symbol | Alt. | Parameter                                         | Min. | Typ. | Max. | Unit |
|--------|------|---------------------------------------------------|------|------|------|------|
| tRLRH  |      | Reset Pulse Width                                 | 1    |      |      | us   |
| tRS    |      | Reset Setup Time                                  | 15   |      |      | ns   |
| tRH    |      | Reset Hold Time                                   | 15   |      |      | ns   |
| tRHRL  |      | Reset Recovery Time (During instruction decoding) |      |      | 20   | us   |
|        | tRCR | Read                                              |      |      | 20   | us   |
|        | tRCE | Erase                                             |      |      | 12   | ms   |
|        | tRCP | Program                                           |      |      | 20   | us   |
|        |      | Reset Recovery Time (for WRSR operation)          |      |      | 20   | us   |

## 11. POWER-ON STATE

The device is at the following states after power-up:

- Standby mode (please note it is not deep power-down mode)
- Write Enable Latch (WEL) bit is reset

The device must not be selected during power-up and power-down stage until the VCC reaches the following levels:

- VCC minimum at power-up stage and then after a delay of tVSL
- GND at power-down

Please note that a pull-up resistor on CS# may ensure a safe and proper power-up/down level.

An internal power-on reset (POR) circuit may protect the device from data corruption and inadvertent data change during power up state. When VCC is lower than VWI (POR threshold voltage value), the internal logic is reset and the flash device has no response to any command.

For further protection on the device, if the VCC does not reach the VCC minimum level, the correct operation is not guaranteed. The write, erase, and program command should be sent after the below time delay:

- tVSL after VCC reached VCC minimum level

The device can accept read command after VCC reached VCC minimum and a time delay of tVSL.

Please refer to the *"Figure 70. Power-up Timing"*.

### Note:

- To stabilize the VCC level, the VCC rail decoupled by a suitable capacitor close to package pins is recommended. (generally around 0.1uF)
- At power-down stage, the VCC drops below VWI level, all operations are disabled and device has no response to any command. The data corruption might occur during this stage if a write, program, erase cycle is in progress.

## 12. ELECTRICAL SPECIFICATIONS

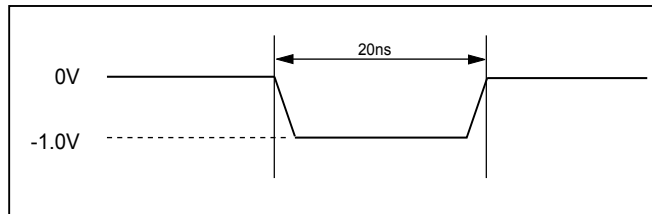
**Table 17. Absolute Maximum Ratings**

| Rating                        |                  | Value             |
|-------------------------------|------------------|-------------------|
| Ambient Operating Temperature | Industrial grade | -40°C to 85°C     |
| Storage Temperature           |                  | -65°C to 150°C    |
| Applied Input Voltage         |                  | -0.5V to VCC+0.5V |
| Applied Output Voltage        |                  | -0.5V to VCC+0.5V |
| VCC to Ground Potential       |                  | -0.5V to 2.5V     |

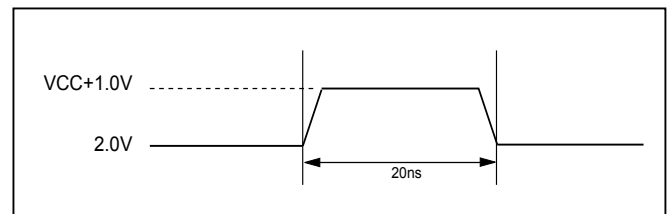
**NOTICE:**

1. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is stress rating only and functional operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended period may affect reliability.
2. Specifications contained within the following tables are subject to change.
3. During voltage transitions, all pins may overshoot to VCC+1.0V or -1.0V for period up to 20ns.

**Figure 63. Maximum Negative Overshoot Waveform**



**Figure 64. Maximum Positive Overshoot Waveform**

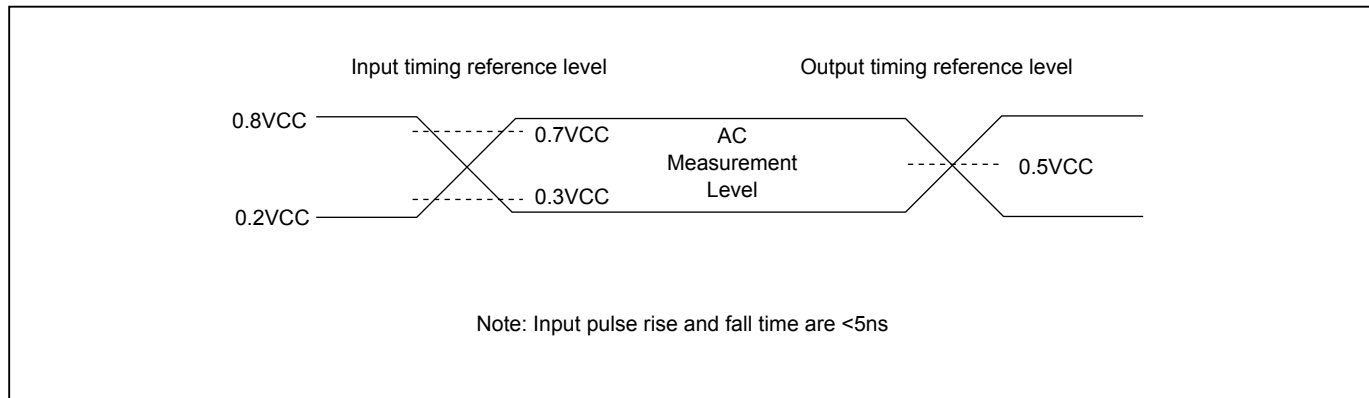


**Table 18. Capacitance**

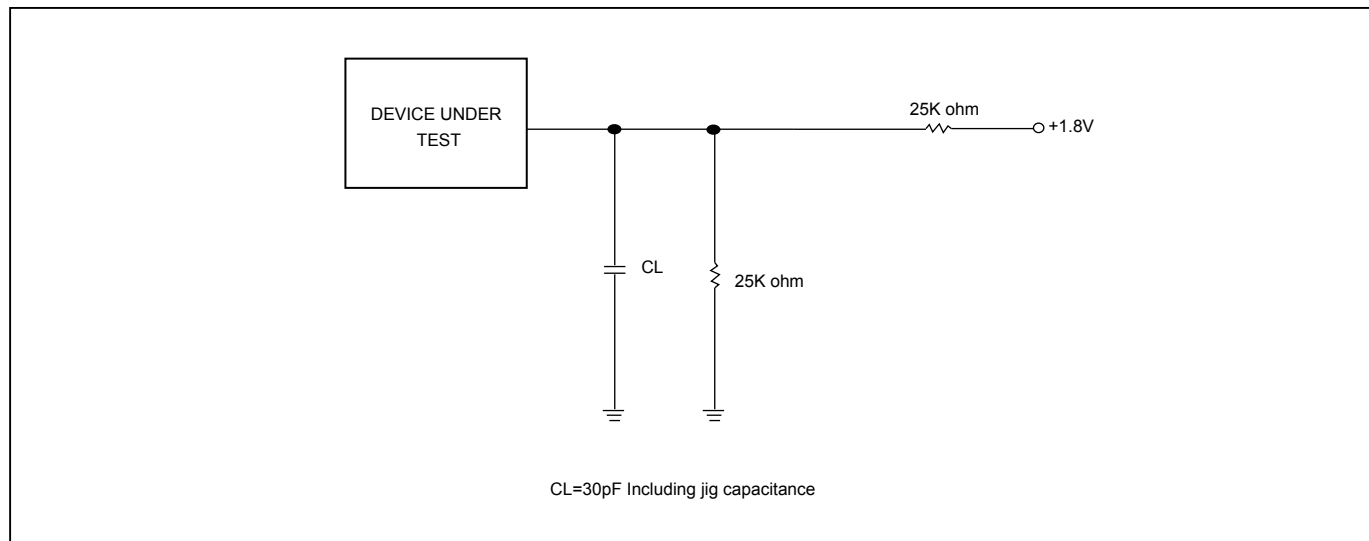
TA = 25°C, f = 1.0 MHz

| Symbol | Parameter          | Min. | Typ. | Max. | Unit | Conditions |
|--------|--------------------|------|------|------|------|------------|
| CIN    | Input Capacitance  |      |      | 6    | pF   | VIN = 0V   |
| COU    | Output Capacitance |      |      | 8    | pF   | VOU = 0V   |

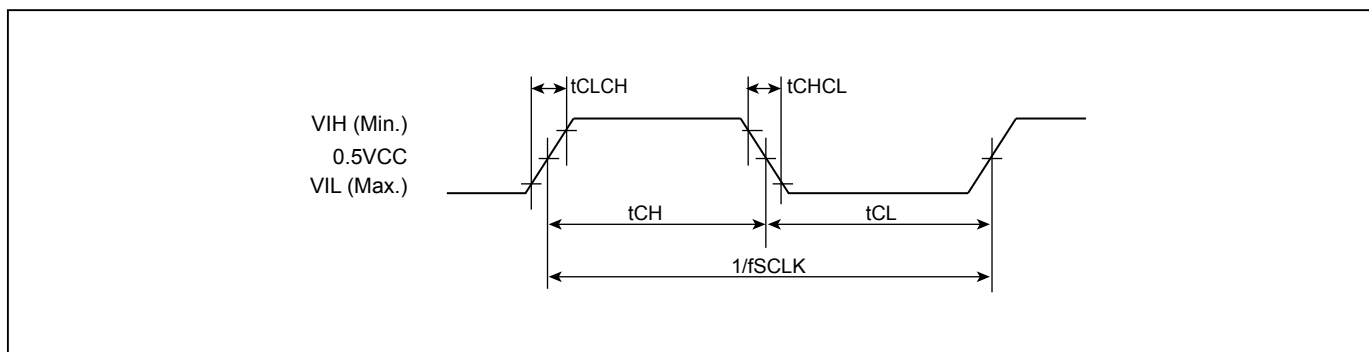
**Figure 65. Input Test Waveforms and Measurement Level**



**Figure 66. Output Loading**



**Figure 67. SCLK TIMING DEFINITION**



**Table 19. DC Characteristics**

Temperature = -40°C to 85°C, VCC = 1.65V - 2.0V

| Symbol | Parameter                                               | Notes | Min.    | Typ. | Max.    | Units | Test Conditions                                            |
|--------|---------------------------------------------------------|-------|---------|------|---------|-------|------------------------------------------------------------|
| ILI    | Input Load Current                                      | 1     |         |      | ±2      | uA    | VCC = VCC Max,<br>VIN = VCC or GND                         |
| ILO    | Output Leakage Current                                  | 1     |         |      | ±2      | uA    | VCC = VCC Max,<br>VOU = VCC or GND                         |
| ISB1   | VCC Standby Current                                     | 1     |         | 10   | 50      | uA    | VIN = VCC or GND,<br>CS# = VCC                             |
| ISB2   | Deep Power-down Current                                 |       |         | 1.5  | 15      | uA    | VIN = VCC or GND,<br>CS# = VCC                             |
| ICC1   | VCC Read                                                | 1     |         |      | 20      | mA    | f=104MHz, (4 x I/O read)<br>SCLK=0.1VCC/0.9VCC,<br>SO=Open |
|        |                                                         |       |         |      | 15      | mA    | f=84MHz,<br>SCLK=0.1VCC/0.9VCC,<br>SO=Open                 |
| ICC2   | VCC Program Current (PP)                                | 1     |         | 20   | 25      | mA    | Program in Progress,<br>CS# = VCC                          |
| ICC3   | VCC Write Status Register (WRSR) Current                |       |         | 10   | 20      | mA    | Program status register in progress, CS#=VCC               |
| ICC4   | VCC Sector/Block (32K, 64K) Erase Current (SE/BE/BE32K) | 1     |         | 18   | 25      | mA    | Erase in Progress,<br>CS#=VCC                              |
| ICC5   | VCC Chip Erase Current (CE)                             | 1     |         | 20   | 25      | mA    | Erase in Progress,<br>CS#=VCC                              |
| VIL    | Input Low Voltage                                       |       | -0.5    |      | 0.2VCC  | V     |                                                            |
| VIH    | Input High Voltage                                      |       | 0.8VCC  |      | VCC+0.4 | V     |                                                            |
| VOL    | Output Low Voltage                                      |       |         |      | 0.2     | V     | IOL = 100uA                                                |
| VOH    | Output High Voltage                                     |       | VCC-0.2 |      |         | V     | IOH = -100uA                                               |

**Notes:**

1. Typical values at VCC = 1.8V, T = 25°C. These currents are valid for all product versions (package and speeds).
2. Typical value is calculated by simulation.

**Table 20. AC Characteristics**

Temperature = -40°C to 85°C, VCC = 1.65V - 2.0V

| Symbol                | Alt. | Parameter                                                                                                                                | Min. | Typ. <sup>(2)</sup>                | Max.   | Unit |
|-----------------------|------|------------------------------------------------------------------------------------------------------------------------------------------|------|------------------------------------|--------|------|
| fSCLK                 | fC   | Clock Frequency for the following instructions:<br>FAST_READ, RDSFDP, 4PP, PP, SE, BE, CE, DP,<br>RES, RDP, WREN, WRDI, RDID, RDSR, WRSR | D.C. |                                    | 104    | MHz  |
| fRCLK                 | fR   | Clock Frequency for READ instructions <sup>(6)</sup>                                                                                     |      |                                    | 54     | MHz  |
| fTCLK                 | fT   | Clock Frequency for 2READ instructions                                                                                                   |      |                                    | 84     | MHz  |
|                       | fQ   | Clock Frequency for 4READ instructions <sup>(5)</sup>                                                                                    |      |                                    | 84/104 | MHz  |
| tCH <sup>(1)</sup>    | tCLH | Clock High Time                                                                                                                          |      |                                    |        |      |
|                       |      | Normal Read (fRCLK)                                                                                                                      | 9    |                                    |        | ns   |
|                       |      | Others (fSCLK)                                                                                                                           | 4.5  |                                    |        | ns   |
| tCL <sup>(1)</sup>    | tCLL | Clock Low Time                                                                                                                           |      |                                    |        |      |
|                       |      | Normal Read (fRCLK)                                                                                                                      | 9    |                                    |        | ns   |
|                       |      | Others (fSCLK)                                                                                                                           | 4.5  |                                    |        | ns   |
| tCLCH <sup>(12)</sup> |      | Clock Rise Time (peak to peak)                                                                                                           | 0.1  |                                    |        | V/ns |
| tCHCL <sup>(12)</sup> |      | Clock Fall Time (peak to peak)                                                                                                           | 0.1  |                                    |        | V/ns |
| tSLCH                 | tCSS | CS# Active Setup Time (relative to SCLK)                                                                                                 | 5    |                                    |        | ns   |
| tCHSL                 |      | CS# Not Active Hold Time (relative to SCLK)                                                                                              | 5    |                                    |        | ns   |
| tDVCH                 | tDSU | Data In Setup Time                                                                                                                       | 2    |                                    |        | ns   |
| tCHDX                 | tDH  | Data In Hold Time                                                                                                                        | 3    |                                    |        | ns   |
| tCHSH                 |      | CS# Active Hold Time (relative to SCLK)                                                                                                  | 2    |                                    |        | ns   |
| tSHCH                 |      | CS# Not Active Setup Time (relative to SCLK)                                                                                             | 3    |                                    |        | ns   |
| tSHSL <sup>(12)</sup> | tCSH | CS# Deselect Time                                                                                                                        |      |                                    |        |      |
|                       |      | From Read to next Read                                                                                                                   | 5    |                                    |        | ns   |
|                       |      | From Write/Erase/Program<br>to Read Status Register                                                                                      | 30   |                                    |        | ns   |
| tSHQZ <sup>(12)</sup> | tDIS | Output Disable Time                                                                                                                      |      |                                    | 8      | ns   |
| tCLQV                 | tV   | Clock Low to Output Valid                                                                                                                |      |                                    | 8      | ns   |
|                       |      | Loading: 30pF                                                                                                                            |      |                                    | 6      | ns   |
|                       |      | Loading: 30pF/15pF                                                                                                                       |      |                                    |        |      |
|                       |      | Loading: 15pF                                                                                                                            |      |                                    |        |      |
| tCLQX                 | tHO  | Output Hold Time                                                                                                                         | 0    |                                    |        | ns   |
| tWHS <sup>(3)</sup>   |      | Write Protect Setup Time                                                                                                                 | 10   |                                    |        | ns   |
| tSHWL <sup>(3)</sup>  |      | Write Protect Hold Time                                                                                                                  | 10   |                                    |        | ns   |
| tDP <sup>(12)</sup>   |      | CS# High to Deep Power-down Mode                                                                                                         |      |                                    | 10     | us   |
| tRES1 <sup>(12)</sup> |      | CS# High to Standby Mode without Electronic Signature<br>Read                                                                            |      |                                    | 30     | us   |
| tRES2 <sup>(12)</sup> |      | CS# High to Standby Mode with Electronic Signature<br>Read                                                                               |      |                                    | 30     | us   |
| tRCR                  |      | Recovery Time from Read                                                                                                                  |      |                                    | 20     | us   |
| tRCP                  |      | Recovery Time from Program                                                                                                               |      |                                    | 20     | us   |
| tRCE                  |      | Recovery Time from Erase                                                                                                                 |      |                                    | 12     | ms   |
| tW                    |      | Write Status Register Cycle Time                                                                                                         |      |                                    | 40     | ms   |
| tBP                   |      | Byte-Program                                                                                                                             |      | 12                                 | 30     | us   |
| tPP                   |      | Page Program Cycle Time                                                                                                                  |      | 0.5                                | 3      | ms   |
| tPP <sup>(7)</sup>    |      | Page Program Cycle Time (n bytes)                                                                                                        |      | 0.008+<br>(nx0.004) <sup>(8)</sup> | 3      | ms   |
| tSE                   |      | Sector Erase Cycle Time                                                                                                                  |      | 35                                 | 200    | ms   |
| tBE32                 |      | Block Erase (32KB) Cycle Time                                                                                                            |      | 0.2                                | 1      | s    |
| tBE                   |      | Block Erase (64KB) Cycle Time                                                                                                            |      | 0.35                               | 2      | s    |
| tCE                   |      | Chip Erase Cycle Time                                                                                                                    |      | 25                                 | 50     | s    |
| tESL <sup>(9)</sup>   |      | Erase Suspend Latency                                                                                                                    |      |                                    | 20     | us   |
| tPSL <sup>(9)</sup>   |      | Program Suspend Latency                                                                                                                  |      |                                    | 20     | us   |
| tPRS <sup>(10)</sup>  |      | Latency between Program Resume and next Suspend                                                                                          | 0.3  | 100                                |        | us   |
| tERS <sup>(11)</sup>  |      | Latency between Erase Resume and next Suspend                                                                                            | 0.3  | 400                                |        | us   |

**Notes:**

1.  $t_{CH} + t_{CL}$  must be greater than or equal to  $1/\text{Frequency}$ .
2. Typical values given for  $T_A=25^{\circ}\text{C}$ . Not 100% tested.
3. Only applicable as a constraint for a WRSR instruction when SRWD is set at 1.
4. Test condition is shown as *"Figure 65. Input Test Waveforms and Measurement Level"*, *"Figure 66. Output Loading"*.
5. When dummy cycle=4 (In both QPI & SPI mode), maximum clock rate=84MHz; when dummy cycle=6 (In both QPI & SPI mode), maximum clock rate=104MHz.
6. The maximum clock rate=33MHz when reading secured OTP area.
7. While programming consecutive bytes, Page Program instruction provides optimized timings by selecting to program the whole 256 bytes or only a few bytes between 1~256 bytes.
8. "n"=how many bytes to program. In the formula, while  $n=1$ , byte program time=12us.
9. Latency time is required for Erase/Program Suspend until WIP bit is "0".
10. For tPRS, minimum timing must be observed before issuing the next program suspend command. However, a period equal to or longer than the typical timing is required in order for the program operation to make progress. (The flash memory can accept another suspend command just after 0.3us from suspend resume. However, if the timing is less than 100us from Program Suspend Resume, the content of flash memory might not be changed before the suspend command has been issued.) Not 100% tested.
11. For tERS, minimum timing must be observed before issuing the next erase suspend command. However, a period equal to or longer than the typical timing is required in order for the erase operation to make progress. (The flash memory can accept another suspend command just after 0.3us from suspend resume. However, if the timing is less than 400us from Erase Suspend Resume, the content of flash memory might not be changed before the suspend command has been issued.) Not 100% tested.
12. The value guaranteed by characterization, not 100% tested in production.

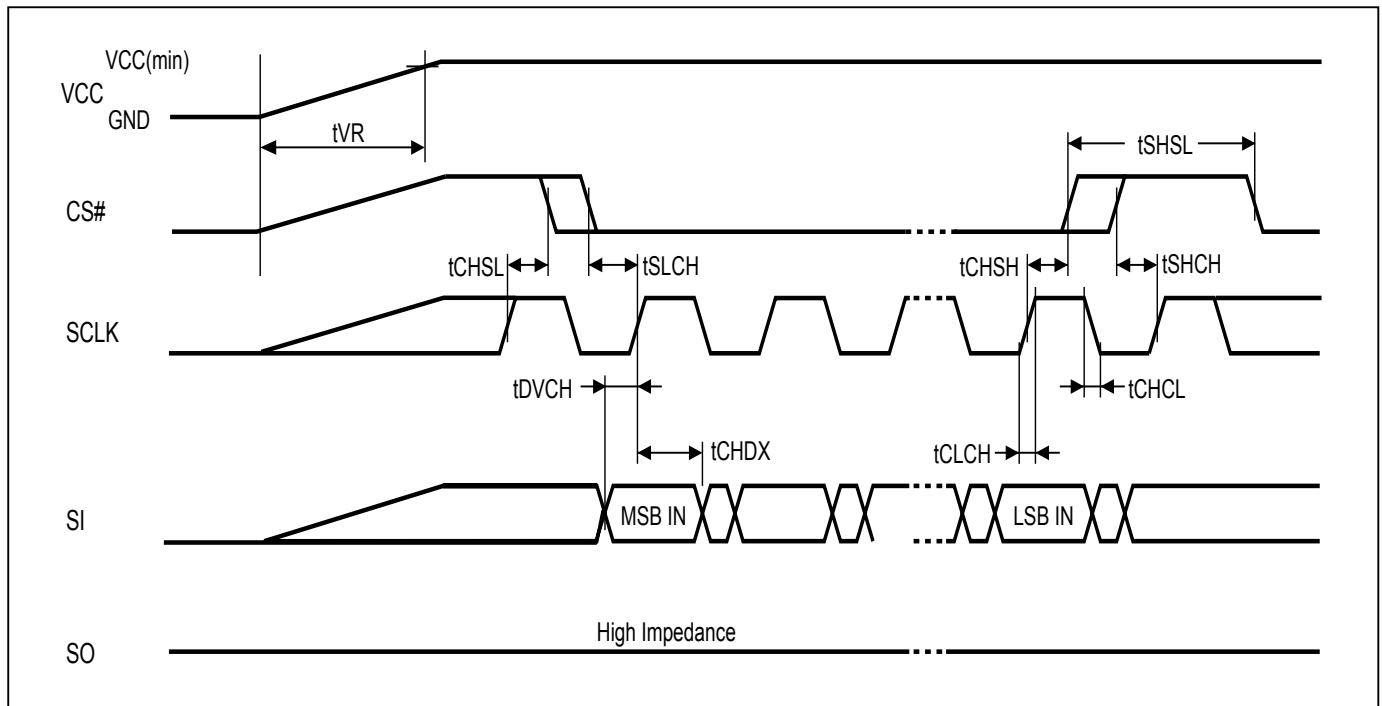
### 13. OPERATING CONDITIONS

#### At Device Power-Up and Power-Down

AC timing illustrated in "Figure 68. AC Timing at Device Power-Up" and "Figure 69. Power-Down Sequence" are for the supply voltages and the control signals at device power-up and power-down. If the timing in the figures is ignored, the device will not operate correctly.

During power-up and power-down, CS# needs to follow the voltage applied on VCC to keep the device not to be selected. The CS# can be driven low when VCC reach Vcc(min.) and wait a period of tVSL.

**Figure 68. AC Timing at Device Power-Up**



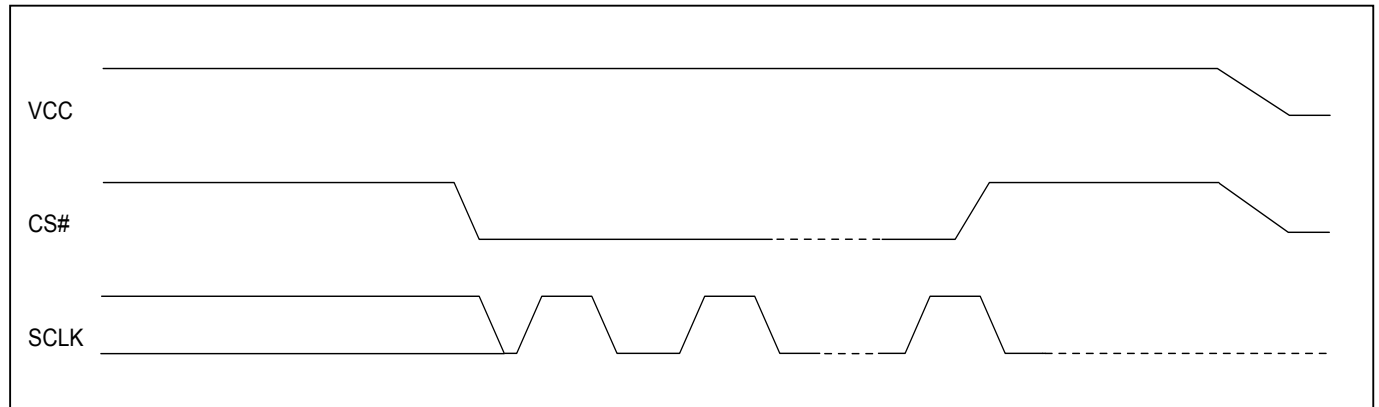
| Symbol | Parameter     | Notes | Min. | Max.   | Unit |
|--------|---------------|-------|------|--------|------|
| tVR    | VCC Rise Time | 1     |      | 500000 | us/V |

#### Notes:

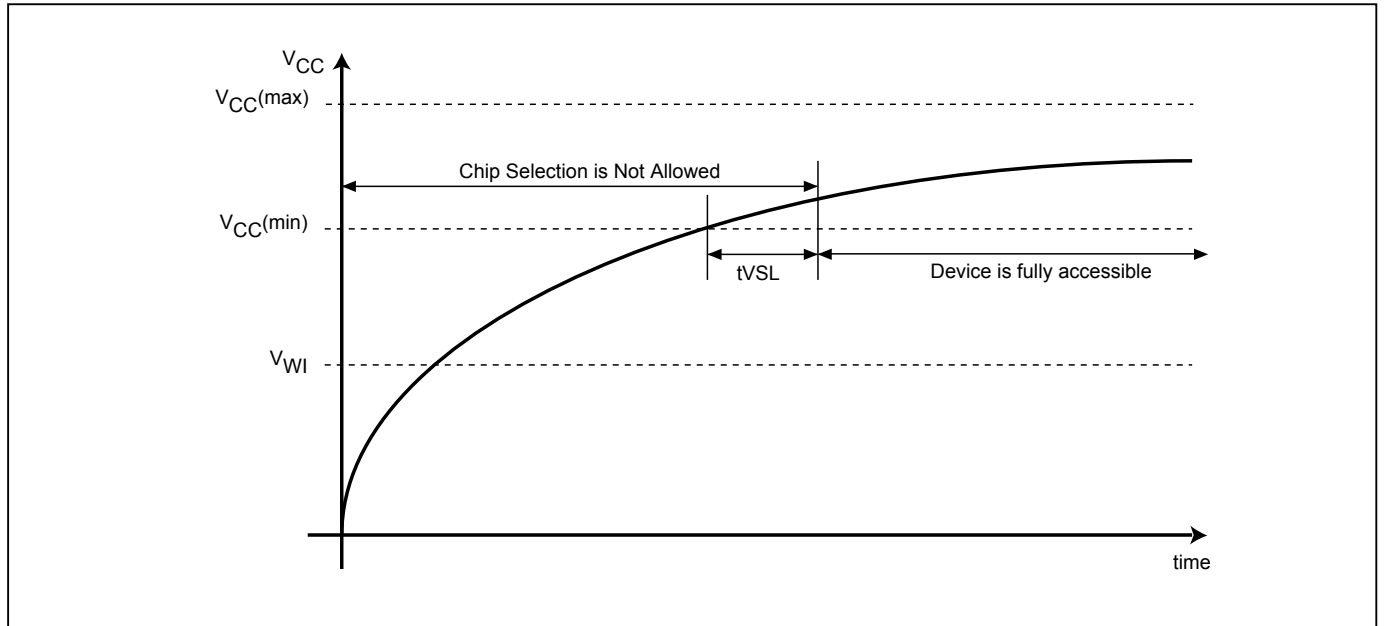
1. Sampled, not 100% tested.
2. For AC spec tCHSL, tSLCH, tDVCH, tCHDX, tSHSL, tCHSH, tSHCH, tCHCL, tCLCH in the figure, please refer to "Table 20. AC Characteristics".

**Figure 69. Power-Down Sequence**

During power-down, CS# needs to follow the voltage drop on VCC to avoid mis-operation.



**Figure 70. Power-up Timing**



Note: VCC (max.) is 2.0V and VCC (min.) is 1.65V.

**Table 21. Power-Up Timing and VWI Threshold**

| Symbol              | Parameter                           | Min. | Max. | Unit |
|---------------------|-------------------------------------|------|------|------|
| tVSL <sup>(1)</sup> | VCC(min) to CS# low (VCC Rise Time) | 800  |      | us   |
| VWI <sup>(1)</sup>  | Write Inhibit Voltage               | 1.0  | 1.4  | V    |

**Note:** 1. These parameters are characterized only.

### 13-1. Initial Delivery State

The device is delivered with the memory array erased: all bits are set to 1 (each byte contains FFh). The Status Register contains 00h (all Status Register bits are 0).

**14. ERASE AND PROGRAMMING PERFORMANCE**

| PARAMETER                                    | Min. | Typ. <sup>(1)</sup> | Max. <sup>(2)</sup> | Unit   |
|----------------------------------------------|------|---------------------|---------------------|--------|
| Write Status Register Cycle Time             |      |                     | 40                  | ms     |
| Sector Erase Cycle Time (4KB)                |      | 35                  | 200                 | ms     |
| Block Erase Cycle Time (32KB)                |      | 0.2                 | 1                   | s      |
| Block Erase Cycle Time (64KB)                |      | 0.35                | 2                   | s      |
| Chip Erase Cycle Time                        |      | 25                  | 50                  | s      |
| Byte Program Time (via page program command) |      | 12 <sup>(5)</sup>   | 30                  | us     |
| Page Program Time                            |      | 0.5 <sup>(5)</sup>  | 3                   | ms     |
| Erase/Program Cycle                          |      | 100,000             |                     | cycles |

**Note:**

1. Typical erase assumes the following conditions: 25°C, 1.8V, and all zero pattern.
2. Under worst conditions of 85°C and 1.65V.
3. System-level overhead is the time required to execute the first-bus-cycle sequence for the programming command.
4. The maximum chip programming time is evaluated under the worst conditions of 0°C, VCC=1.8V, and 100K cycle with 90% confidence level.
5. Typical program assumes the following conditions: 25°C, 1.8V, and checkerboard pattern.

**15. LATCH-UP CHARACTERISTICS**

|                                                                               | Min.   | Max.       |
|-------------------------------------------------------------------------------|--------|------------|
| Input Voltage with respect to GND on all power pins, SI, CS#                  | -1.0V  | 2 VCCmax   |
| Input Voltage with respect to GND on SO                                       | -1.0V  | VCC + 1.0V |
| Current                                                                       | -100mA | +100mA     |
| Includes all pins except VCC. Test conditions: VCC = 1.8V, one pin at a time. |        |            |

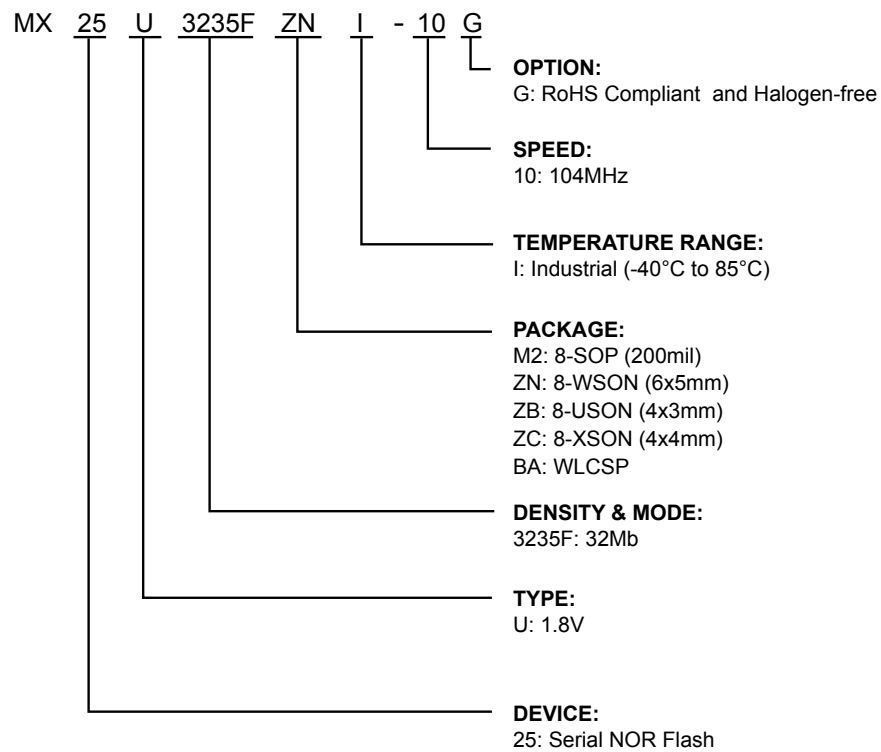


## 16. ORDERING INFORMATION

Please contact Macronix regional sales for the latest product selection and available form factors.

| PART NO.          | CLOCK (MHz) | TEMPERATURE   | PACKAGE        | Remark |
|-------------------|-------------|---------------|----------------|--------|
| MX25U3235FM2I-10G | 104         | -40°C to 85°C | 8-SOP (200mil) |        |
| MX25U3235FZNI-10G | 104         | -40°C to 85°C | 8-WSON (6x5mm) |        |
| MX25U3235FZBI-10G | 104         | -40°C to 85°C | 8-USON (4x3mm) |        |
| MX25U3235FZCI-10G | 104         | -40°C to 85°C | 8-XSON (4x4mm) |        |
| MX25U3235FBAI-10G | 104         | -40°C to 85°C | 12-Ball WLCSP  |        |

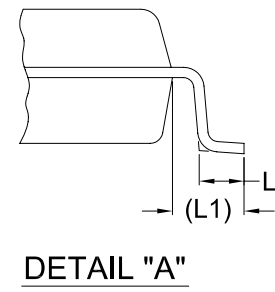
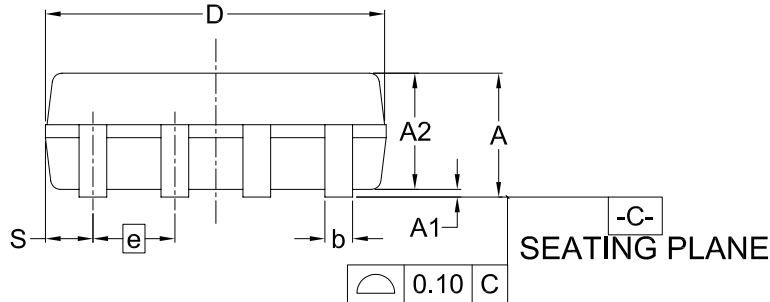
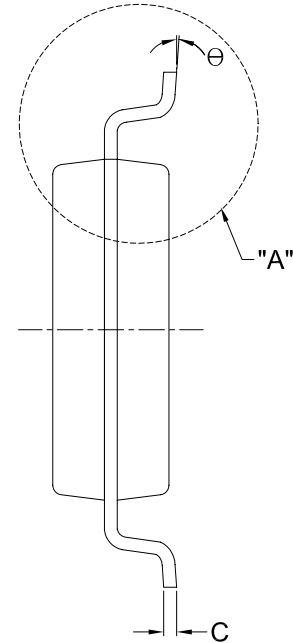
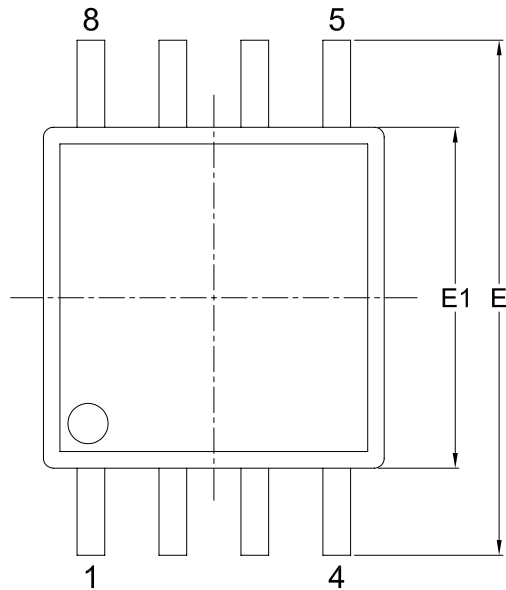
### 17. PART NAME DESCRIPTION



## 18. PACKAGE INFORMATION

### 18-1. 8-pin SOP (200mil)

Doc. Title: Package Outline for SOP 8L 200MIL (official name - 209MIL)

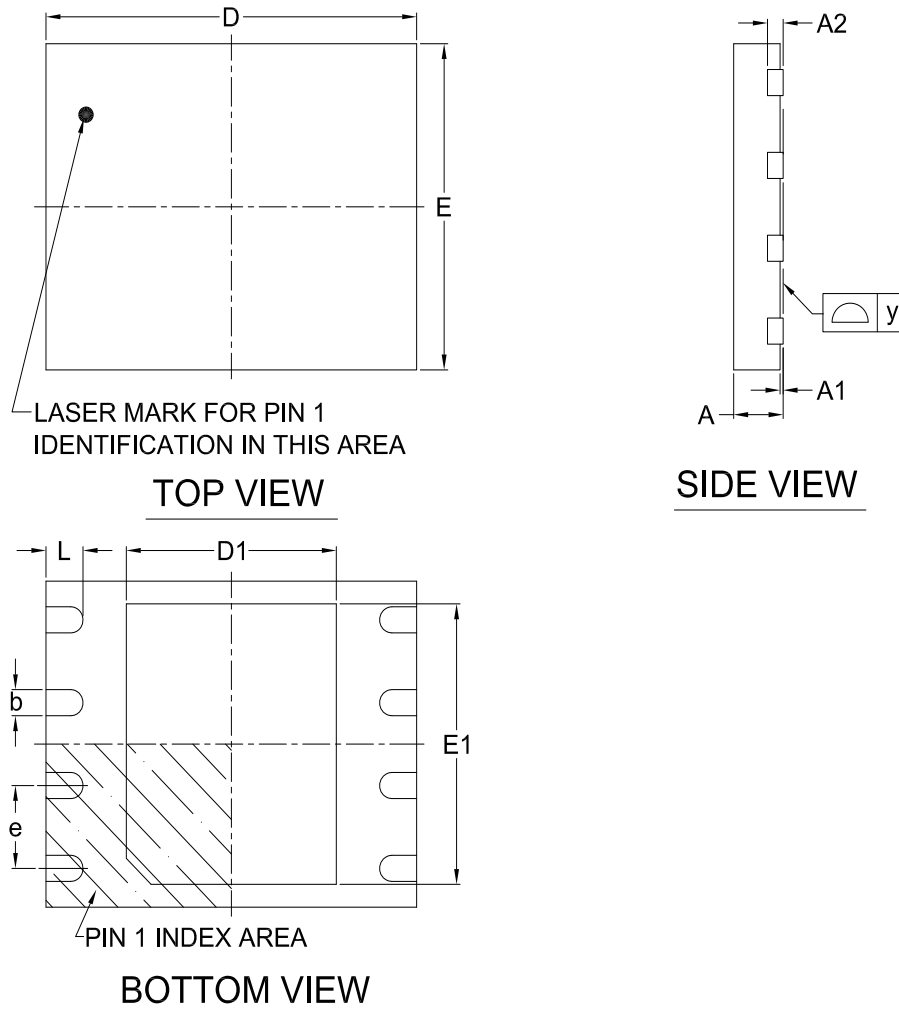


Dimensions (inch dimensions are derived from the original mm dimensions)

| SYMBOL |      | A     | A1    | A2    | b     | C     | D     | E     | E1    | e     | L     | L1    | S     | $\theta$ |
|--------|------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|----------|
| UNIT   |      |       |       |       |       |       |       |       |       |       |       |       |       |          |
| mm     | Min. | 1.75  | 0.05  | 1.70  | 0.36  | 0.19  | 5.13  | 7.70  | 5.18  | —     | 0.50  | 1.21  | 0.62  | 0°       |
|        | Nom. | 1.95  | 0.15  | 1.80  | 0.41  | 0.20  | 5.23  | 7.90  | 5.28  | 1.27  | 0.65  | 1.31  | 0.74  | 5°       |
|        | Max. | 2.16  | 0.20  | 1.91  | 0.51  | 0.25  | 5.33  | 8.10  | 5.38  | —     | 0.80  | 1.41  | 0.88  | 8°       |
| Inch   | Min. | 0.069 | 0.002 | 0.067 | 0.014 | 0.007 | 0.202 | 0.303 | 0.204 | —     | 0.020 | 0.048 | 0.024 | 0°       |
|        | Nom. | 0.077 | 0.006 | 0.071 | 0.016 | 0.008 | 0.206 | 0.311 | 0.208 | 0.050 | 0.026 | 0.052 | 0.029 | 5°       |
|        | Max. | 0.085 | 0.008 | 0.075 | 0.020 | 0.010 | 0.210 | 0.319 | 0.212 | —     | 0.031 | 0.056 | 0.035 | 8°       |

## 18-2. 8-land WSON (6x5mm)

Doc. Title: Package Outline for WSON 8L (6x5x0.8MM, LEAD PITCH 1.27MM)



Note:

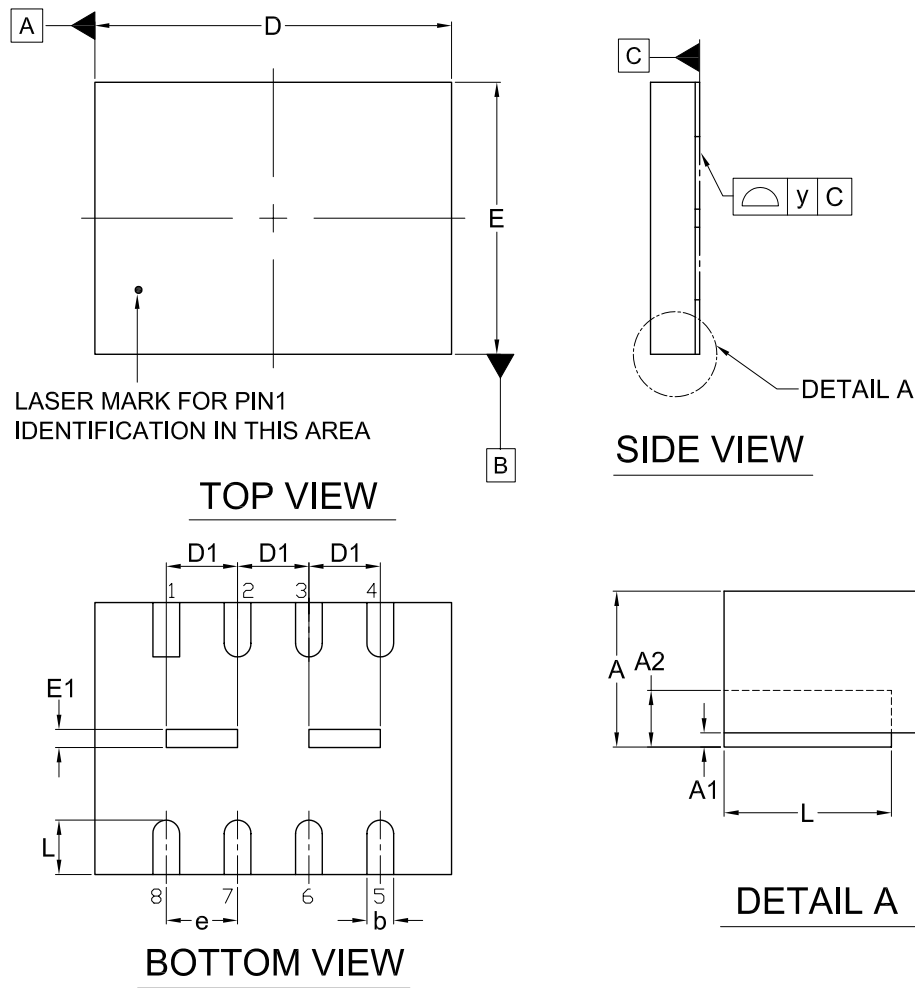
This package has an exposed metal pad underneath the package. It is recommended to leave the metal pad floating or to connect it to the same ground as the GND pin of the package. Do not connect the metal pad to any other voltage or signal line on the PCB. Avoid placing vias or traces underneath the metal pad. Connection of this metal pad to any other voltage or signal line can result in shorts and/or electrical malfunction of the device.

Dimensions (inch dimensions are derived from the original mm dimensions)

| SYMBOL |      | A     | A1    | A2    | b     | D     | D1    | E     | E1    | L     | e    | y     |
|--------|------|-------|-------|-------|-------|-------|-------|-------|-------|-------|------|-------|
| UNIT   |      |       |       |       |       |       |       |       |       |       |      |       |
| mm     | Min. | 0.70  | ---   | ---   | 0.35  | 5.90  | 3.30  | 4.90  | 3.90  | 0.50  | ---  | 0.00  |
|        | Nom. | ---   | ---   | 0.20  | 0.40  | 6.00  | 3.40  | 5.00  | 4.00  | 0.60  | 1.27 | ---   |
|        | Max. | 0.80  | 0.05  | ---   | 0.48  | 6.10  | 3.50  | 5.10  | 4.10  | 0.75  | ---  | 0.05  |
| Inch   | Min. | 0.028 | ---   | ---   | 0.014 | 0.232 | 0.129 | 0.193 | 0.154 | 0.020 | ---  | 0.00  |
|        | Nom. | ---   | ---   | 0.008 | 0.016 | 0.236 | 0.134 | 0.197 | 0.157 | 0.024 | 0.05 | ---   |
|        | Max. | 0.032 | 0.002 | ---   | 0.019 | 0.240 | 0.138 | 0.201 | 0.161 | 0.030 | ---  | 0.002 |

### 18-3. 8-land USON (4x3mm)

Package Outline for USON 8L (4x3x0.60MM, LEAD PITCH 0.8MM)



Note:

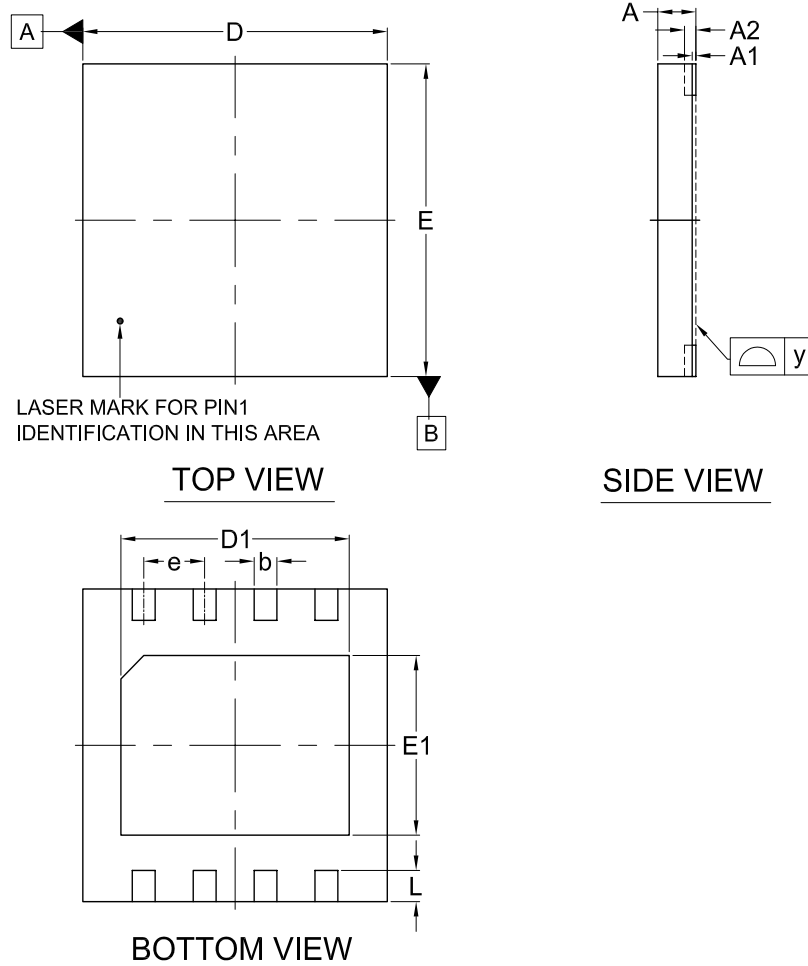
This package has an exposed metal pad underneath the package. It is recommended to leave the metal pad floating or to connect it to the same ground as the GND pin of the package. Do not connect the metal pad to any other voltage or signal line on the PCB. Avoid placing vias or traces underneath the metal pad. Connection of this metal pad to any other voltage or signal line can result in shorts and/or electrical malfunction of the device.

Dimensions (inch dimensions are derived from the original mm dimensions)

| SYMBOL |      | A     | A1    | A2    | b     | D     | D1    | E     | E1    | L     | e     | y     |
|--------|------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|
| UNIT   |      |       |       |       |       |       |       |       |       |       |       |       |
| mm     | Min. | 0.50  | ---   | ---   | 0.25  | 3.90  | 0.70  | 2.90  | 0.10  | 0.55  | ---   | 0.00  |
|        | Nom. | 0.55  | 0.02  | 0.15  | 0.30  | 4.00  | 0.80  | 3.00  | 0.20  | 0.60  | 0.80  | ---   |
|        | Max. | 0.60  | 0.05  | ---   | 0.35  | 4.10  | 0.90  | 3.10  | 0.30  | 0.65  | ---   | 0.08  |
| Inch   | Min. | 0.020 | ---   | ---   | 0.010 | 0.154 | 0.028 | 0.114 | 0.004 | 0.022 | ---   | 0.00  |
|        | Nom. | 0.022 | 0.001 | 0.006 | 0.011 | 0.158 | 0.032 | 0.118 | 0.008 | 0.024 | 0.031 | ---   |
|        | Max. | 0.024 | 0.002 | ---   | 0.014 | 0.161 | 0.035 | 0.122 | 0.012 | 0.026 | ---   | 0.003 |

**18-4. 8-land XSON(4x4mm)**

**Doc. Title: Package Outline for XSON 8L (4x4x0.5MM, LEAD PITCH 0.8MM)**



Note:

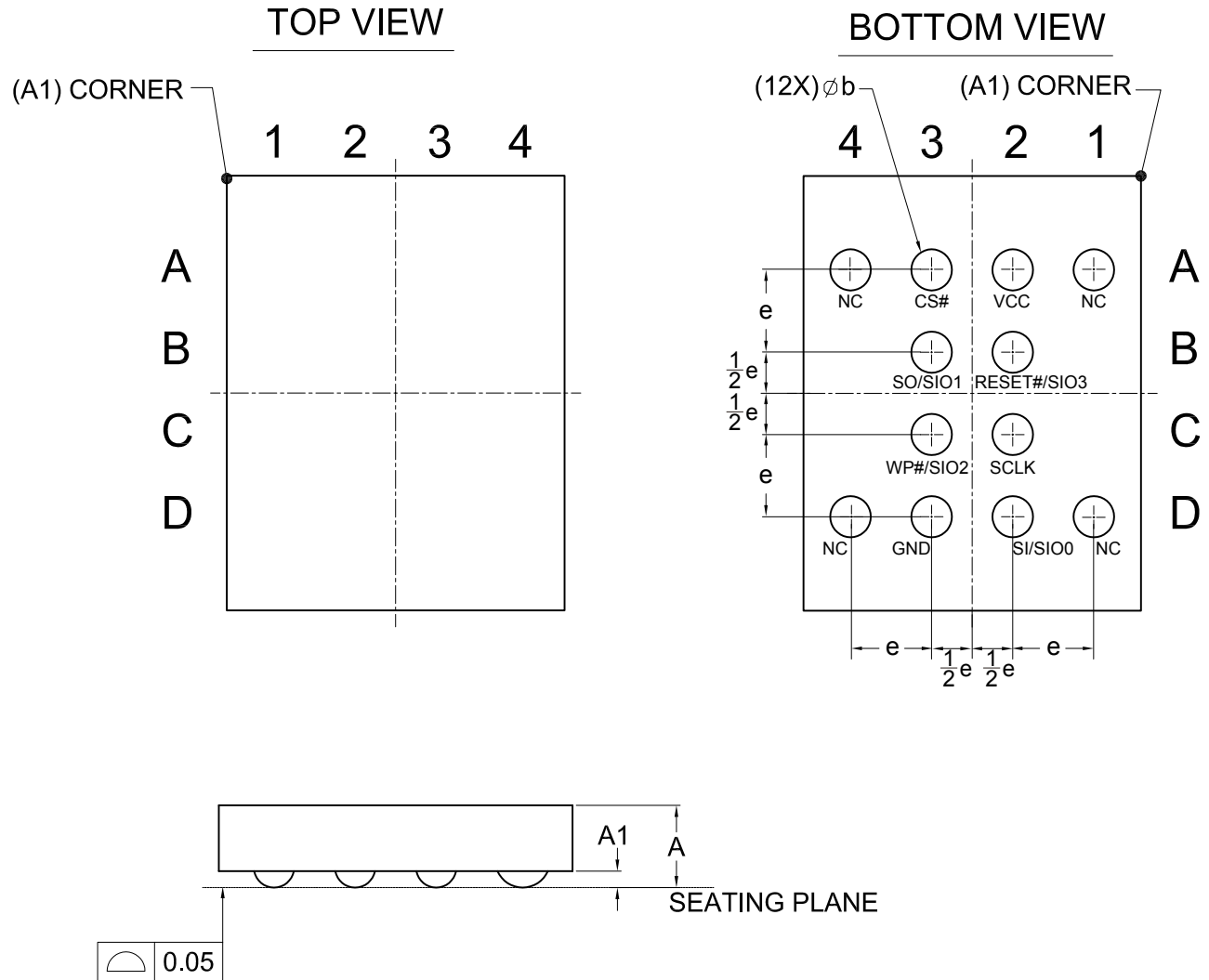
This package has an exposed metal pad underneath the package. It is recommended to leave the metal pad floating or to connect it to the same ground as the GND pin of the package. Do not connect the metal pad to any other voltage or signal line on the PCB. Avoid placing vias or traces underneath the metal pad. Connection of this metal pad to any other voltage or signal line can result in shorts and/or electrical malfunction of the device.

Dimensions (inch dimensions are derived from the original mm dimensions)

| SYMBOL<br>UNIT |      | A     | A1    | A2    | b     | D     | D1    | E     | E1    | L     | e     | y     |
|----------------|------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|
| mm             | Min. | 0.40  | —     | —     | 0.25  | 3.90  | 2.90  | 3.90  | 2.20  | 0.35  | —     | 0.00  |
|                | Nom. | 0.45  | 0.02  | 0.15  | 0.30  | 4.00  | 3.00  | 4.00  | 2.30  | 0.40  | 0.80  | —     |
|                | Max. | 0.50  | 0.05  | —     | 0.35  | 4.10  | 3.10  | 4.10  | 2.40  | 0.45  | —     | 0.08  |
| Inch           | Min. | 0.016 | —     | —     | 0.010 | 0.154 | 0.114 | 0.154 | 0.087 | 0.014 | —     | 0.00  |
|                | Nom. | 0.018 | 0.001 | 0.006 | 0.012 | 0.157 | 0.118 | 0.157 | 0.091 | 0.016 | 0.031 | —     |
|                | Max. | 0.020 | 0.002 | —     | 0.014 | 0.161 | 0.122 | 0.161 | 0.094 | 0.018 | —     | 0.003 |

### 18-5. 12-ball WLCSP

**Title: Package Outline for 12BALL WLCSP (BALL PITCH 0.5MM, BALL DIAMETER 0.25MM)**



Dimensions (inch dimensions are derived from the original mm dimensions)

| SYMBOL<br>UNIT |      | A     | A1     | b     | e         |
|----------------|------|-------|--------|-------|-----------|
| mm             | Min. | 0.38  | 0.105  | 0.22  | ---       |
|                | Nom. | 0.43  | 0.135  | 0.25  | 0.50 BSC  |
|                | Max. | 0.48  | 0.165  | 0.28  | ---       |
| Inch           | Min. | 0.015 | 0.0041 | 0.009 | ---       |
|                | Nom. | 0.017 | 0.0053 | 0.010 | 0.020 BSC |
|                | Max. | 0.019 | 0.0065 | 0.011 | ---       |

**Please contact local Macronix sales channel for complete package dimensions.**

## 19. REVISION HISTORY

| Revision No. | Description                                                                                           | Page                           | Date        |
|--------------|-------------------------------------------------------------------------------------------------------|--------------------------------|-------------|
| 0.01         | 1. Modified Chip Erase Cycle Time                                                                     | P78,83                         | AUG/25/2011 |
|              | 2. Modified tVSL(min.) from 500us to 800us                                                            | P82                            |             |
| 0.02         | 1. Changed title from "Advanced Information" to "Preliminary"                                         | P4                             | OCT/06/2011 |
|              | 2. Modified Write Protection Selection (WPSEL) description                                            | P59,60                         |             |
|              | 3. Modified Power-up Timing                                                                           | P84                            |             |
| 1.0          | 1. Modified tVSL(min.) in Power-Up Timing Table                                                       | P84                            | FEB/03/2012 |
|              | 2. Modified value of tWHSL, tSHWL, tCHDX, tCHSH, tSHCH, tSHSL and ISB1(max.) in CHARACTERISTICS Table | P79,80                         |             |
|              | 3. Added Reset# description for write/erase execution                                                 | P33,49,50~53,58,75             |             |
| 1.1          | 1. Modified Data Retention value                                                                      | P4                             | JUN/19/2013 |
|              | 2. Remove MX25U6435F                                                                                  | All                            |             |
|              | 3. Modified tVSL value                                                                                | P83                            |             |
| 1.2          | 1. Added DREAD/QREAD function                                                                         | P7,14,17,39, 41                | APR/17/2014 |
|              | 2. Updated DREAD(1-1-2) / QREAD(1-1-4) in SFDP Table                                                  | P72,73                         |             |
|              | 3. Modified accepted commands after Erase Suspend                                                     | P66                            |             |
|              | 4. Modified VCC to Ground Potential                                                                   | P78                            |             |
|              | 5. Updated Erase time, Consumption current and Page Program                                           | P4                             |             |
|              | 6. Updated ISB1, ISB2, ICC3 and ICC4 in DC Table                                                      | P80                            |             |
|              | 7. Updated tPP, tSE, tBE32 and tBE in AC Table                                                        | P81                            |             |
|              | 8. Updated Erase time and Page Program time                                                           | P86                            |             |
|              | 9. Added 8-XSON (4x4mm) package                                                                       | P5,8,87,88,92                  |             |
|              | 10. Added WLCSP, 8-USON (4x3mm) package as Advanced Information                                       | P5,8,87,88,91,93               |             |
| 1.3          | 1. Updated the ordering information of MX25U3235FBAI-10G                                              | P89                            | APR/02/2015 |
|              | 2. Updated suspend/resume parameters and descriptions.                                                | P66-69, 83-84                  |             |
|              | 3. Updated SFDP note 6.                                                                               | P77                            |             |
|              | 4. Modified BLOCK DIAGRAM.                                                                            | P9                             |             |
| 1.4          | 1. Removed the "Advanced Information" remark of 8-USON (4x3mm) package.                               | P88                            | SEP/25/2015 |
|              | 2. Content modification.                                                                              | P20, 26, 31, 41, 56            |             |
|              | 3. Removed Performance Enhance Mode Reset                                                             |                                |             |
|              | 4. Revised notes of <i>"Table 20. AC Characteristics"</i> .                                           | P82                            |             |
| 1.5          | 1. Modified Max. fRSCLK.                                                                              | P82                            | MAY/31/2016 |
|              | 2. Content modification.                                                                              | P12, 17, 20, 53, 57, 59, 82-83 |             |
|              | 3. Updated tVR values.                                                                                | P84                            |             |
|              | 4. Added a statement for product ordering information.                                                | P88                            |             |
| 1.6          | 1. Added the note for the internal pull up status of RESET#/SIO3 and WP#/SIO2.                        | P8                             | JUL/12/2017 |
|              | 2. Updated notes of <i>"Table 20. AC Characteristics"</i> .                                           | P82-83                         |             |
|              | 3. Added <i>"Figure 67. SCLK TIMING DEFINITION"</i> .                                                 | P80                            |             |
|              | 4. Content modification.                                                                              | P16, 24, 31, 42                |             |
|              | 5. Format modification.                                                                               | P90-93                         |             |

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